TAS2770 具有扬声器 I/V 感应 20W 数字输入单声道 D 类音频放大器

1 特性

- 高性能单声道 D 类放大器
  - 1% THD+N 时的功率为 20W（4Ω，16V）
  - 1% THD+N 时的功率为 15.4W（4Ω，12.6V）
- 1W 时的 THD+N 为 0.03%（4Ω，VBAT = 12.6V）
- 8.4V Vbat 时的 A 加权空闲通道噪声为 32μVrms
- 20Hz 至 20kHz 内具有 90dB PSRR、200mV$_{PP}$ 纹波
- 1W（4Ω，VBAT = 12.6V）下的效率为 82.5%
- < 1μA HW 关断 VBAT 电流
- 42mW / 63mW 空闲损耗 (8.4V / 12.6V)
- 扬声器电压和电流感测
- 使用 I/V 扬声器感测进行实时诊断
  - 过流
  - 短路（电源短路、接地短路和终端至终端短路）
  - 过热
- VBAT 跟踪峰值电压限制器提供欠压保护
- 44.1kHz 至 192kHz 采样速率
- 灵活的用户界面
  - I^{2}S/TDM：8 通道（32 位/96kHz）
  - I^{2}C：8 个可选择地址
- 无 MCLK 运行
- 低噗声和嘀哒声
- 电源
  - VBAT：4.5V 至 16V
  - AVDD：1.8V
- 扩频频谱低 EMI 模式
- 热保护和过流保护

2 应用

- 笔记本电脑
- 蓝牙扬声器
- 家庭自动化
- 智能扬声器/物联网

3 说明

TAS2770 是一款经优化后可高效驱动小型扬声器的单声道数字输入 D 类音频放大器。凭借出色的输出功率、保护功能和封装，TAS2770 成为智能扬声器、蓝牙扬声器、家庭自动化设备、笔记本电脑和平板电脑的理想选择。

该 D 类放大器能够在 16V 电压下向 4Ω 的负载提供 20W 的连续功率，在 16V 电压下向 8Ω 的负载提供 15W 的连续功率，两种情况下的 THD 都为 1%。4.5V 至 16V 的宽输入电压范围和高输出功率使该放大器具有出色的通用性，能够与电池电源或线路供电系统配合使用。

欠压保护器跟踪峰值电压，并自动将增益限制为可用电压。该硬件实现的功能降低了放大器对系统电源的需求，从而防止音频中断和系统关断。

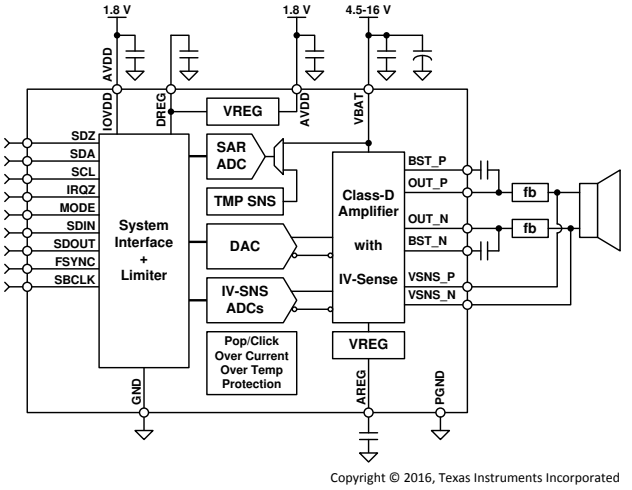
TAS2770 可用作常规放大器或与基于主机的扬声器保护算法配合使用。集成的扬声器电压和电流感应功能可通过 I2S 返回路径将扬声器状况实时反馈到保护算法。

最多有 8 个器件可以通过任意一个 I^{2}S/TDM + I^{2}C 共享一个公共总线。

TAS2770 器件采用 26 引脚、0.4mm 间距 QFN 封装，实现紧凑的 PCB 空间。

器件信息

器件型号	封装	封装尺寸（标称值）
TAS2770	QFN	4mm × 3.5mm
TAS2770	DSBGA	2mm × 2.52mm
SNP002770	QFN	4mm x 3.5mm
SNP002770	DSBGA	2mm × 2.52mm
TAS5770LC0	DSBGA	2mm × 2.52mm



功能方框图

本文档旨在为方便起见，提供有关 TI 产品中文版本的信息，以确认产品的概要。有关适用的官方英文版本的最新信息，请访问 www.ti.com，其内容始终优先。TI 不保证翻译的准确性和有效性。在实际设计之前，请务必参考最新版本的英文版本。

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4 Revision History

注：以前版本的页码可能与当前版本的页码不同

Changes from Revision D (August 2022) to Revision E (April 2023)	Page
• Updated 表 8-70	45
• Updated 图 8-64	74

Changes from Revision C (October 2020) to Revision D (August 2022)	Page
• 向数据表添加了 TAS5770LC0 器件	1

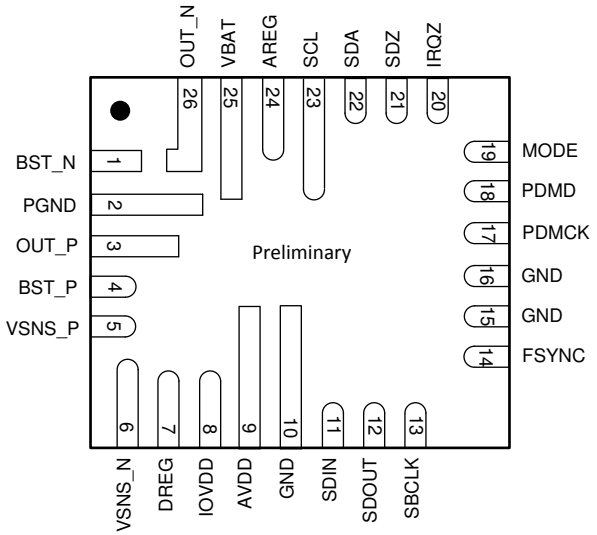
Changes from Revision B (October 2018) to Revision C (October 2020)	Page
• 更改了首页中的信息	1
• Changed VBAT Max in 节 6.3 from 16 V to 18 V	5
• Changed REV_ID	75

Changes from Revision A (December 2017) to Revision B (October 2018)	Page
• Changed From: Efficiency (%) To: VDD PSRR (dB) in 图 6-15	14
• Changed From: Efficiency (%) To: VBAT PSRR (dB) in 图 6-16	14

Changes from Revision * (October 2017) to Revision A (December 2017)	Page
• 将 TAS2770 发布为“量产数据”	1

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5 Pin Configuration and Functions



Drawing is Preliminary.

图 5-1. QFN Package 26-Pin RJQ Top View

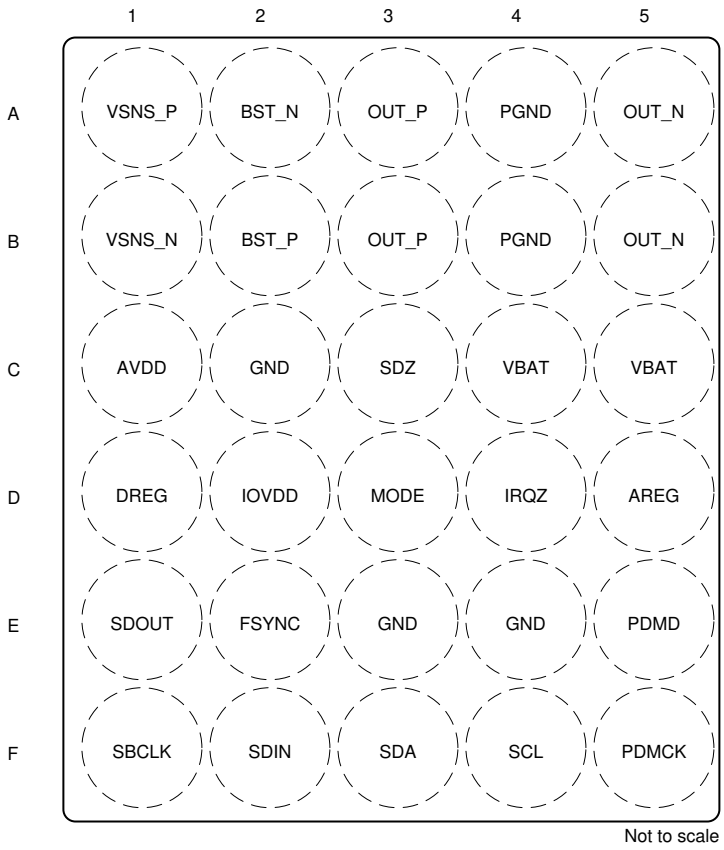


图 5-2. WCSP 30-Ball Top View

表 5-1. Pin Functions

PIN			I/O	DESCRIPTION
DSBGA	QFN	NAME		
D5	24	AREG	O	Gate drive voltage regulator output. Decouple with cap to GND. Do not connect to external load.
C1	9	AVDD	P	Analog power input. Connect to 1.8V supply and decouple to GND with cap.
A2	1	BST_N	I	Class-D negative bootstrap. Connect a cap between BST_N and OUT_N.
B2	4	BST_P	I	Class-D positive bootstrap. Connect a cap between BST_P and OUT_P.
D1	7	DREG	O	Digital core voltage regulator output. Bypass to GND with a cap. Do not connect to external load.
E2	14	FSYNC	I	TDM Frame Sync.
C2, E3, E4	10, 15, 16	GND	P	Analog GND. Connect to PCB GND Plane.
D2	8	IOVDD	P	Digital IO Supply. Connect to the same 1.8 V supply that powers AVDD and decouple with a cap to GND.
D4	20	IRQZ	O	Open drain, actve low interrupt pin. Pull up to IOVDD with resistor if optional internal pull up is not used.
D3	19	MODE	I	Mode detect pin. This pin can detect a short to IOVDD or GND, a 470 Ω connection to IOVDD or GND, a 2.2 kΩ connection to IOVDD or GND, a 10 kΩ connection to IOVDD or GND and a 47 kΩ connection to IOVDD. Minimize capacitive loading on this pin and do not connect to any other load.
A5, B5	26	OUT_N	O	Class-D negative output.
A3, B3	3	OUT_P	O	Class-D positive output.
F5	17	PDMCK	IO	PDM Clock.
E5	18	PDMD	I	PDM Digital Input.
A4, B4	2	PGND	P	Class-D GND. Connect to PCB GND Plane.
F1	13	SBCLK	I	TDM Serial Bit Clock in TDM/I^2C Mode.
F4	23	SCL	I	I^2C Clock Pin. Pull up to IOVDD with a resistor.
F3	22	SDA	IO	I^2C Data Pin. Pull up to IOVDD with a resistor.
F2	11	SDIN	I	TDM Serial Data Input.
E1	12	SDOUT	IO	TDM Serial Data Output in TDM/I^2C Mode.
C3	21	SDZ	I	Active low hardware shutdown.
C4, C5	25	VBAT	P	Class-D power supply input. Connect to VBAT supply and decouple with a cap.
B1	6	VSNS_N	I	Voltage Sense negative input. Connect to Class-D negative output after Ferrite bead filter.
A1	5	VSNS_P	I	Voltage Sense positive input. Connect to Class-D positive output after Ferrite bead filter.

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6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) (1)

		MIN	MAX	UNIT
Supply Voltage	AVDD	–0.3	2	V
	IOVDD	–0.3	2	V
	VBAT	–0.3	18	V
Input voltage(2)	Digital IOs referenced to IOVDD supply	–0.3	2.3	V
Operating free-air temperature, T_A ; Device is functional and reliable, some performance characteristics may be degraded.		–40	85	°C
Performance free-air temperature, T_P ; All performance characteristics are met.		–20	70	°C
Operating junction temperature, T_J		–40	150	°C
Storage temperature, T_{stg}		–65	150	°C

(1) Stresses beyond those listed under *Absolute Maximum Ratings* can cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Procedures*. Exposure to absolute-maximum-rated conditions for extended periods can affect device reliability.
(2) All digital inputs and IOs are failsafe.

6.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001(1)	±2500	V
		Charged-device model (CDM), per JEDEC specification JESD22-C101(2)	±1500	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
AVDD	Supply voltage	1.65	1.8	1.95	V
IOVDD	Supply voltage	1.65	1.8	1.95	V
VBAT	Supply voltage	4.5		16	V
V_{IH}	High-level digital input voltage		IOVDD		V
V_{IL}	Low-level digital input voltage		0		V
R_{SPK}	Minimum speaker impedance	3.2			Ω
L_{SPK}	Minimum speaker inductance	10			µH

6.4 Thermal Information

THERMAL METRIC(1)		TAS2770 QFN (RJQ) 26 PINS	UNIT
$R_{\theta JA}$	Junction-to-ambient thermal resistance	57.0	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	0.3	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	8.5	°C/W
ψ_{JT}	Junction-to-top characterization parameter	0.2	°C/W
ψ_{JB}	Junction-to-board characterization parameter	8.7	°C/W

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THERMAL METRIC(1)		TAS2770 QFN (RJQ) 26 PINS	UNIT
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	NA	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report.

6.5 Electrical Characteristics

T_A = 25 °C, VBAT = 12.6 V, AVDD = IOVDD = 1.8 V, R_L = 4 Ω + 33 µH, f_{in} = 1 kHz, SSM, f_s = 48 kHz, Gain = 21 dBV, SDZ = 1, Measured filter free using 节 7 (unless otherwise noted).

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
DIGITAL INPUT and OUTPUT						
V_{IH}	High-level digital input logic voltage threshold	All digital pins except SDA and SCL; IOVDD = 1.8 V.	0.65 × IOVDD			V
V_{IL}	Low-level digital input logic voltage threshold	All digital pins except SDA and SCL; IOVDD = 1.8 V.			0.35 × IOVDD	V
$V_{IH(I2C)}$	High-level digital input logic voltage threshold	SDA and SCL; IOVDD = 1.8 V.	0.7 x IOVDD			V
$V_{IL(I2C)}$	Low-level digital input logic voltage threshold	SDA and SCL; IOVDD = 1.8 V.			0.3 x IOVDD	V
V_{OH}	High-level digital output voltage	All digital pins except SDA, SCL and IRQZ; IOVDD = 1.8 V; I_{OH} = 2 mA.	IOVDD – 0.45 V			V
V_{OL}	Low-level digital output voltage	All digital pins except SDA, SCL and IRQZ; IOVDD = 1.8 V; I_{OL} = – 2 mA.			0.45	V
$V_{OL(I2C)}$	Low-level digital output voltage	SDA and SCL; IOVDD = 1.8 V; $I_{OL(I2C)}$ = – 2 mA.			0.2 x IOVDD	V
$V_{OL(IRQZ)}$	Low-level digital output voltage for IRQZ open drain Output	IRQZ; IOVDD = 1.8 V; $I_{OL(IRQZ)}$ = – 2 mA.			0.45	V
I_{IH}	Input logic-high leakage for digital inputs	All digital pins; Input = IOVDD.	– 5	0.1	5	µA
I_{IL}	Input logic-low leakage for digital inputs	All digital pins; Input = GND.	– 5	0.1	5	µA
C_{IN}	Input capacitance for digital inputs	All digital pins		5		pF
R_{PD}	Pull down resistance for digital input/IO pins when asserted on	SDOUT, SDIN, FSYNC, SBCLK, PDMD, PDMCK		18		kΩ
TDM SERIAL AUDIO PORT						
	PCM Sample Rates & FSYNC Input Frequency	Single Speed, I²S/TDM Operation		48		kHz
		Double Speed, I²S/TDM Operation		96		
		Quadruple Speed, I²S/TDM Operation		192		
	SBCLK Input Frequency	I²S/TDM Operation	2.54		27.1	MHz
	SBCLK Maximum Input Jitter	RMS Jitter below 40 kHz that can be tolerated without performance degradation		1		ns
		RMS Jitter above 40 kHz that can be tolerated without performance degradation		10		
	SBCLK Cycles per FSYNC in I²S and TDM Modes	Values: 64, 96, 128, 192, 256, 384 and 512	64		512	Cycles
PDM AUDIO PORT						
	PDM clock input frequency	Single Rate PDM		3.072		MHz
		Double Rate PDM		6.144		

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T_A = 25 °C, VBAT = 12.6 V, AVDD = IOVDD = 1.8 V, R_L = 4 Ω + 33 µH, f_{in} = 1 kHz, SSM, f_s = 48 kHz, Gain = 21 dBV, SDZ = 1, Measured filter free using 节 7 (unless otherwise noted).

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
	PDM sensor clock rate to PCM sample rate oversampling ratios	Single Speed PCM. Values: 64X and 128X.	64		128	
		Double Speed PCM. Values: 32X and 64X.	32		64	
		Quadruple Speed PCM. Values: 16X and 32X.	16		32	
PROTECTION CIRCUITRY						
	Thermal shutdown temperature			140		°C
	Thermal shutdown retry			1.5		s
	VBAT undervoltage lockout threshold (UVLO)	UVLO is asserted		4		V
	VBAT overvoltage lockout threshold (OVLO)	OVLO is asserted		18		V
AMPLIFIER PERFORMANCE						
P_{OUT}	Maximum Continuous Output Power 0.1% THD+N	R_L = 8 Ω + 33 µH, THD+N = 0.1 %, f_{in} = 1 kHz, VBAT = 8.4 V		3.7		W
		R_L = 4 Ω + 33 µH, THD+N = 0.1 %, f_{in} = 1 kHz, VBAT = 8.4 V		6.6		
		R_L = 8 Ω + 33 µH, THD+N = 0.1 %, f_{in} = 1 kHz, VBAT = 12.6 V		8.5		
		R_L = 4 Ω + 33 µH, THD+N = 0.1 %, f_{in} = 1 kHz, VBAT = 12.6 V		14.2		
	Maximum Continuous Output Power 1% THD+N	R_L = 8 Ω + 33 µH, THD+N = 1 %, f_{in} = 1 kHz, VBAT = 8.4 V		4		
		R_L = 4 Ω + 33 µH, THD+N = 1 %, f_{in} = 1 kHz, VBAT = 8.4 V		7.1		
		R_L = 8 Ω + 33 µH, THD+N = 1 %, f_{in} = 1 kHz, VBAT = 12.6 V		9.1		
		R_L = 4 Ω + 33 µH, THD+N = 1 %, f_{in} = 1 kHz, VBAT = 12.6 V		15.4		
	System efficiency at P_{OUT} = 1 W	R_L = 8 Ω + 33 µH, f_{in} = 1 kHz, VBAT = 8.4 V		89 %		
		R_L = 4 Ω + 33 µH, f_{in} = 1 kHz, VBAT = 8.4 V		84 %		
		R_L = 8 Ω + 33 µH, f_{in} = 1 kHz, VBAT = 12.6 V		87.5 %		
		R_L = 4 Ω + 33 µH, f_{in} = 1 kHz, VBAT = 12.6 V		82.7 %		
	System efficiency at 0.1% THD+N power level	R_L = 8 Ω + 33 µH, P_{OUT} = 3. 7W, f_{in} = 1 kHz, VBAT = 8.4 V		92 %		
		R_L = 4 Ω + 33 µH, P_{OUT} = 6.6 W, f_{in} = 1 kHz, VBAT = 8.4 V		87 %		
		R_L = 8 Ω + 33 µH, P_{OUT} = 8.5 W, f_{in} = 1 kHz, VBAT = 12.6 V		92 %		
		R_L = 4 Ω + 33 µH, P_{OUT} = 14.2 W, f_{in} = 1 kHz, VBAT = 12.6 V		86 %		

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T_A = 25 °C, VBAT = 12.6 V, AVDD = IOVDD = 1.8 V, R_L = 4 Ω + 33 µH, f_{in} = 1 kHz, SSM, f_s = 48 kHz, Gain = 21 dBV, SDZ = 1, Measured filter free using 节 7 (unless otherwise noted).

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
THD+N	Total harmonic distortion + noise	P_{OUT} = 1 W, R_L = 8 Ω + 33 µH, f_{in} = 20 Hz - 20 kHz, VBAT = 8.4 V		0.01 %		
		P_{OUT} = 1 W, R_L = 4 Ω + 33 µH, f_{in} = 20 Hz - 20 kHz, VBAT = 8.4 V		0.01 %		
		P_{OUT} = 1 W, R_L = 8 Ω + 33 µH, f_{in} = 20 Hz - 20 kHz, VBAT = 12.6 V		0.01 %		
		P_{OUT} = 1 W, R_L = 4 Ω + 33 µH, f_{in} = 20 Hz - 20 kHz, VBAT = 12.6 V		0.01 %		
V_N	Idle channel noise	A-Weighted, 20 Hz - 20 kHz, DAC Modulator Running		31		µV
		V_{BAT} = 8.4 V		32		µV
		V_{BAT} = 12.6 V		36		µV
F_{PWM}	Class-D PWM switching frequency	Average frequency in Spread Spectrum Mode, CLASSD_SYNC=0		384		kHz
		Fixed Frequency Mode, CLASSD_SYNC=0	345.6	384	422.4	
		Fixed Frequency Mode, CLASSD_SYNC=1, f_s = 44.1, 88.2, 174.6 kHz		44.1·8		
		Fixed Frequency Mode, CLASSD_SYNC=1, f_s = 48, 96, 192 kHz		48·8		
V_{OS}	Output offset voltage		-1		1	mV
DNR	Dynamic range	A-Weighted, -60 dBFS Method		108		dB
SNR	Signal to noise ratio	A-Weighted, Referenced to 1 % THD+N Output Level		108		dB
K_{CP}	Click and pop performance	Into and out of Mute, Shutdown, Power Up, Power Down and audio clocks starting and stopping. A-weighted		5		mV
	Programmable output level range		12.5		21	dBV
	Programmable output level step size			0.5		dB
AV_{ERROR}	Amplifier gain error	P_{OUT}=1W		±0.1		dB
A_{RIPPLE}	Frequency response passband ripple	20 Hz - 20 kHz		±0.1		dB
	Mute attenuation	Device in Shutdown or Muted in Normal Operation		110		dB
	Output short circuit limit	VBAT = 12.6 V, Output to Output, Output to GND or Output to VBAT Short		6		A
$R_{DS(ON)FET}$	Power stage on-resistance (high-side + low-side + sense resistor)	T_A = 25 °C		510		mΩ
	VBAT power-supply rejection ratio	VBAT = 12.6 V + 200 mV_{pp}, f_{ripple} = 217 Hz		105		dB
		VBAT = 12.6 V + 200 mV_{pp}, f_{ripple} = 20 kHz		86		
	AVDD power-supply rejection ratio	AVDD = 1.8 V + 200 mV_{pp}, f_{ripple} = 217 Hz		95		dB
		AVDD = 1.8 V + 200 mV_{pp}, f_{ripple} = 20 kHz		88		
	Turn on time from release of SW shutdown	No Volume Ramping		1.2		ms
		Volume Ramping		5.3		

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T_A = 25 °C, VBAT = 12.6 V, AVDD = IOVDD = 1.8 V, R_L = 4 Ω + 33 µH, f_{in} = 1 kHz, SSM, f_s = 48 kHz, Gain = 21 dBV, SDZ = 1, Measured filter free using 节 7 (unless otherwise noted).

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
	Turn off time from assertion of SW shutdown to amp Hi-Z	No Volume Ramping		0.3		ms
		Volume Ramping		4.7		
PCM PLAYBACK CHARACTERISTICS						
	Playback latency from latched input sample to speaker terminals	Single Speed, I²S/TDM		3.5		samples
		Double Speed, I²S/TDM		3.5		
		Quadruple Speed, I²S/TDM		3.5		
	Playback – 0.1 dB bandwidth	Single Speed, I²S/TDM			23.06	kHz
		Double Speed, I²S/TDM			21.79	
		Quadruple Speed, I²S/TDM			21.69	
	Playback – 3 dB bandwidth	Single Speed, I²S/TDM			24	kHz
		Double Speed, I²S/TDM			23	
		Quadruple Speed, I²S/TDM			27.26	
PDM PLAYBACK CHARACTERISTICS						
	Playback latency from latched data bit to speaker terminals	Single Rate PDM, PDMD input		7.07		µs
		Double Rate PDM, PDMD input		5.02		
	Playback – 0.1 dB bandwidth	Single Rate PDM, PDMD input		41.5		kHz
		Double Rate PDM, PDMD input		88		
	Playback – 3 dB bandwidth	Single Rate PDM, PDMD input		77.5		kHz
		Double Rate PDM, PDMD input		143		
SPEAKER CURRENT SENSE						
DNR	Dynamic range	Un-Weighted, Relative to 0 dBFS		69		dB
THD+N	Total harmonic distortion + noise	R_L = 8 Ω + 33 µH, f_{in} = 1 kHz, P_{OUT} = 5 W		– 60		dB
		R_L = 4 Ω + 33 µH, f_{in} = 1 kHz, P_{OUT} = 7.5 W		– 60		
	Full-scale input current			3.75		A
	Current-sense accuracy	R_L = 8 Ω + 33 µH, I_{OUT} = 354 mA_{RMS} (P_{OUT} = 1 W)		±1 %		
	Current-sense gain error over temperature	– 20°C to 70°C, P_{OUT} = 1 W		±0.75%		
	Current-sense gain error over output power	50 mW to 0.1 % THD+N level, f_{in} = 1 kHz, 4 Ω, using a 40Hz-34dB pilot tone		±0.75%		
	Current-sense frequency response	Max deviation above and below passband gain		±0.2		dB
SPEAKER VOLTAGE SENSE						
DNR	Dynamic range	Un-Weighted, Relative 0 dBFS		69		dB
THD+N	Total harmonic distortion + noise	R_L = 8 Ω + 33 µH, f_{in} = 1 kHz, P_{OUT} = 5 W		– 60		dB
		R_L = 4 Ω + 33 µH, f_{in} = 1 kHz, P_{OUT} = 7.5 W		– 60		
	Full-scale input voltage			14		V_{PK}
	Voltage-sense accuracy	R_L = 8 Ω + 33 µH, I_{OUT} = 354 mA_{RMS} (P_{OUT} = 1 W)		±1%		
	Voltage-sense gain error over temperature	– 20°C to 70°C, P_{OUT} = 1 W		±0.75%		

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T_A = 25 °C, VBAT = 12.6 V, AVDD = IOVDD = 1.8 V, R_L = 4 Ω + 33 µH, f_{in} = 1 kHz, SSM, f_s = 48 kHz, Gain = 21 dBV, SDZ = 1, Measured filter free using 节 7 (unless otherwise noted).

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Voltage-sense gain error over output power	50 mW to 0.1 % THD+N level, f_{in} = 1 kHz, 4 Ω, using a 40Hz-34dB pilot tone		±0.75%		
Voltage-sense frequency response	Max deviation above and below passband gain		±0.2		dB
SPEAKER VOLTAGE/CURRENT SENSE RATIO					
Gain ratio error over output power	50 mW to 0.1 % THD+N level, f_{in} = 1 kHz, 4 Ω, using a 40Hz-34dB pilot tone		±0.75%		
Gain ratio error over temperature	–20°C to 70°C		±0.5%		
TYPICAL CURRENT CONSUMPTION					
Current consumption in hardware shutdown	SDZ = 0, VBAT		0.1		µA
	SDZ = 0, AVDD		1		
	SDZ = 0, IOVDD		0.1		
Current consumption in software shutdown	All Clocks Stopped, VBAT		10		µA
	All Clocks Stopped, AVDD		10		
	All Clocks Stopped, IOVDD		1		
Current consumption during active operation with IV sense disabled	f_s = 48 kHz, VBAT		3.1		mA
	f_s = 48 kHz, AVDD		10		
	f_s = 48 kHz, IOVDD		0.1		
Current consumption during active operation with IV sense enabled	f_s = 48 kHz, VBAT		3.1		mA
	f_s = 48 kHz, AVDD		12.5		
	f_s = 48 kHz, IOVDD		0.1		
PEAK VOLTAGE LIMITER					
Limiter maximum threshold		2		14.7	V
Limiter minimum threshold		2		14.7	V
Limiter inflection point		2		14.7	V
Limiter VBAT tracking slope		1		4	V/V
Limiter max attenuation		1		16.5	dB
Limiter latency	Time from VBAT dipping below threshold to initial gain reduction			23	µs
Limiter attack rate		5		640	µs/step
Limiter attack step size		0.25		2	dB/step
Limiter hold time		0		1000	ms
Limiter release rate		10		1500	ms/step
Limiter release step size		0.25		2	dB/step
BROWN OUT PREVENTION LIMITER					
Brownout prevention threshold		4.5		10.875	V
Brownout prevention threshold step size			25		mV
Brownout prevention threshold tolerance	Measured at VBAT of 5V and 10V		±25		mV
Brownout prevention latency	Time from VBAT dipping below threshold to initial gain reduction			20	µs
Brownout prevention attack rate		5		640	µs/step
Brownout prevention attack step size		0.5		2	dB/step
Brownout prevention hold time		0		1000	ms

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T_A = 25 °C, VBAT = 12.6 V, AVDD = IOVDD = 1.8 V, R_L = 4 Ω + 33 µH, f_{in} = 1 kHz, SSM, f_s = 48 kHz, Gain = 21 dBV, SDZ = 1, Measured filter free using 节 7 (unless otherwise noted).

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Brownout prevention release rate		10		1500	ms/step
Brownout prevention release step size		0.25		2	dB/step

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6.6 I²C Timing Requirements

T_A = 25 °C, AVDD = IOVDD = 1.8 V (unless otherwise noted)

		MIN	NOM	MAX	UNIT
Standard-Mode					
f_{SCL}	SCL clock frequency	0		100	kHz
$t_{HD;STA}$	Hold time (repeated) START condition. After this period, the first clock pulse is generated.	4			µs
t_{LOW}	LOW period of the SCL clock	4.7			µs
t_{HIGH}	HIGH period of the SCL clock	4			µs
$t_{SU;STA}$	Setup time for a repeated START condition	4.7			µs
$t_{HD;DAT}$	Data hold time: For I²C bus devices	0		3.45	µs
$t_{SU;DAT}$	Data set-up time	250			ns
t_r	SDA and SCL rise time			1000	ns
t_f	SDA and SCL fall time			300	ns
$t_{SU;STO}$	Set-up time for STOP condition	4			µs
t_{BUF}	Bus free time between a STOP and START condition	4.7			µs
C_b	Capacitive load for each bus line			400	pF
Fast-Mode					
f_{SCL}	SCL clock frequency	0		400	kHz
$t_{HD;STA}$	Hold time (repeated) START condition. After this period, the first clock pulse is generated.	0.6			µs
t_{LOW}	LOW period of the SCL clock	1.3			µs
t_{HIGH}	HIGH period of the SCL clock	0.6			µs
$t_{SU;STA}$	Setup time for a repeated START condition	40.6			µs
$t_{HD;DAT}$	Data hold time: For I²C bus devices	0		0.9	µs
$t_{SU;DAT}$	Data set-up time	100			ns
t_r	SDA and SCL rise time	20 + 0.1 × Cb		300	ns
t_f	SDA and SCL fall time	20 + 0.1 × Cb		300	ns
$t_{SU;STO}$	Set-up time for STOP condition	0.26			µs
t_{BUF}	Bus free time between a STOP and START condition	1.3			µs
C_b	Capacitive load for each bus line			400	pF
Fast-Mode Plus					
f_{SCL}	SCL clock frequency	0		1000	kHz
$t_{HD;STA}$	Hold time (repeated) START condition. After this period, the first clock pulse is generated.	0.26			µs
t_{LOW}	LOW period of the SCL clock	0.5			µs
t_{HIGH}	HIGH period of the SCL clock	0.26			µs
$t_{SU;STA}$	Setup time for a repeated START condition	0.26			µs
$t_{HD;DAT}$	Data hold time: For I²C bus devices	0			µs
$t_{SU;DAT}$	Data set-up time	50			ns
t_r	SDA and SCL Rise Time			120	ns
t_f	SDA and SCL Fall Time			120	ns
$t_{SU;STO}$	Set-up time for STOP condition				µs
t_{BUF}	Bus free time between a STOP and START condition	0.5			µs

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T_A = 25 °C, AVDD = IOVDD = 1.8 V (unless otherwise noted)

		MIN	NOM	MAX	UNIT
C_b	Capacitive load for each bus line			550	pF

6.7 TDM Port Timing Requirements

T_A = 25 °C, AVDD = IOVDD = 1.8 V, 20 pF load on all outputs (unless otherwise noted)

			MIN	NOM	MAX	UNIT
t_H(SBCLK)	SBCLK high period		40			ns
t_L(SBCLK)	SBCLK low period		40			ns
t_{SU}(FSYNC)	FSYNC setup time		8			ns
t_{HLD}(FSYNC)	FSYNC hold time		8			ns
t_{SU}(FSYNC)	SDIN setup time		8			ns
t_{HLD}(SDIN)	SDIN hold time		8			ns
t_d(DO-FSYNC)	FSYNC to SDOUT delay (tx_offset = 0 only)	50% of FSYNC to 50% of SDOUT			35	ns
t_d(DO-SBCLK)	SBCLK to SDOUT delay	50% of FSYNC to 50% of SDOUT			35	ns
t_r(SBCLK)	SBCLK rise time	10 % - 90 % Rise Time			8	ns
t_f(SBCLK)	SBCLK fall time	90 % - 10 % Fall Time			8	ns

6.8 PDM Port Timing Requirements

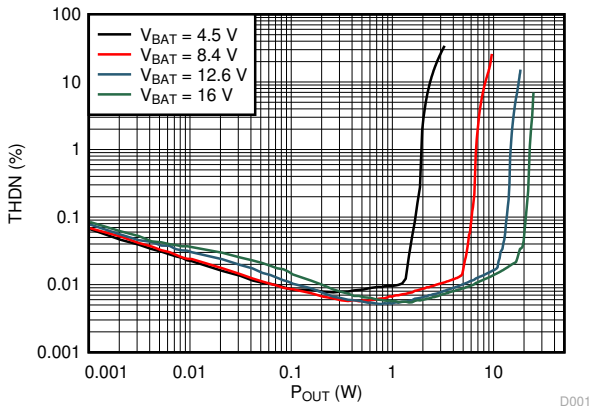
T_A = 25 °C, AVDD = IOVDD = 1.8 V, 20 pF load on all outputs (unless otherwise noted)

			MIN	NOM	MAX	UNIT
t_{SU}(PDM)	PDM IN setup time		20			ns
t_{HLD}(PDM)	PDM IN hold time		3			ns
t_r(PDM)	PDM IN rise time	10 % - 90 % Rise Time			4	ns
t_f(PDM)	PDM IN fall time	90 % - 10 % Fall Time			4	ns

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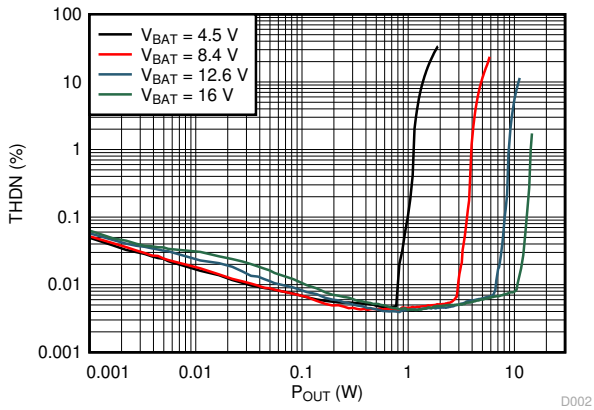
6.9 Typical Characteristics

At T_A = 25°C, f_{SPK_AMP} = 384 kHz, input signal is 1 kHz Sine, unless otherwise noted. Filter used for Load Resistance is 30 µH, unless otherwise noted.



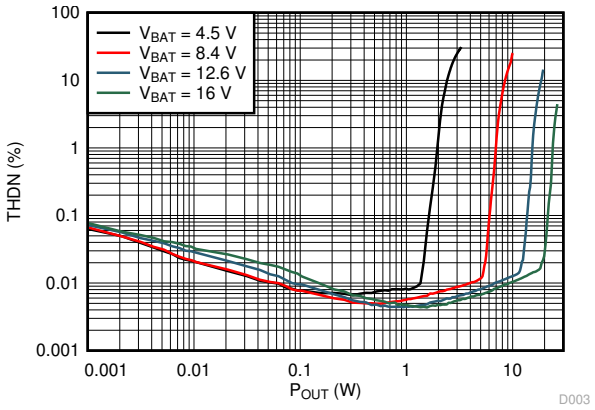
RL = 4 Ω F_{IN} = 1 kHz

图 6-1. THD+N vs Output Power



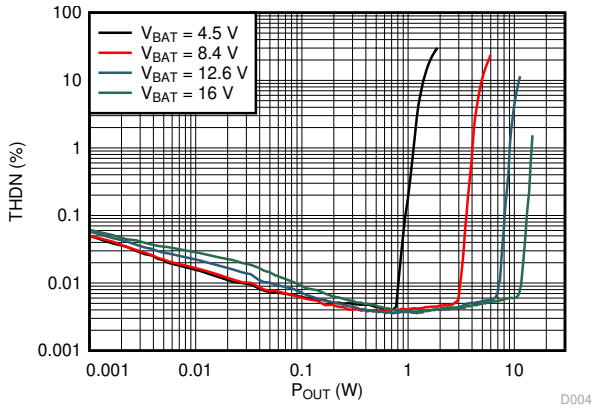
RL = 8 Ω F_S = 1 kHz F_{IN} = 1 kHz

图 6-2. THD+N vs Output Power



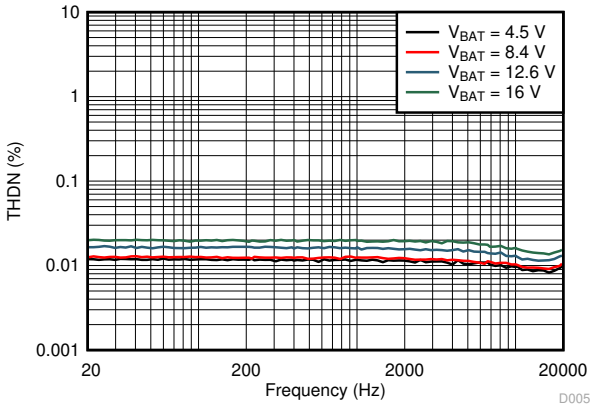
RL = 4 Ω F_{IN} = 6.667 kHz

图 6-3. THD+N vs Output Power



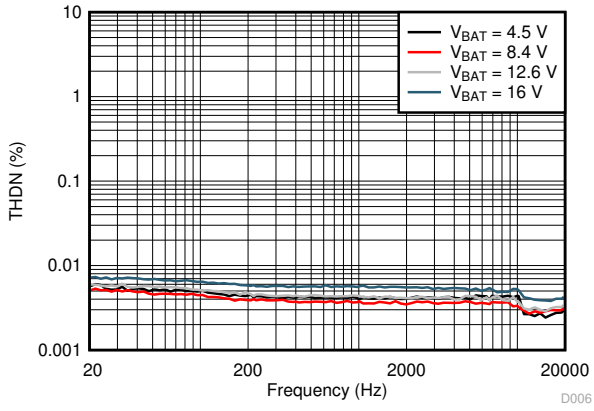
RL = 8 Ω F_{IN} = 6.667 kHz

图 6-4. THD+N vs Output Power



F_{IN} = 20 Hz – 20 kHz P_{OUT} = 0.1 W RL = 4 Ω + 30 µH

图 6-5. THD+N vs Frequency



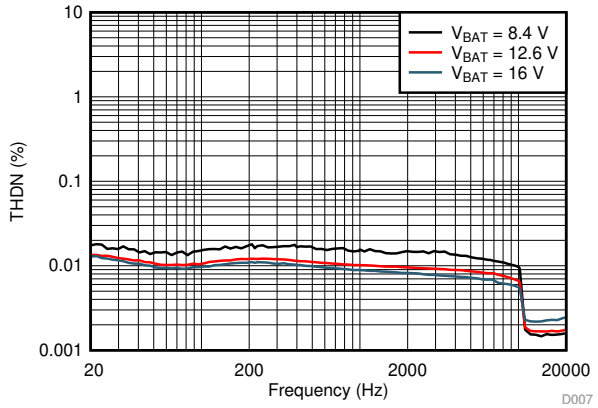
F_{IN} = 20 Hz – 20 kHz P_{OUT} = 1 W RL = 4 Ω + 30 µH

图 6-6. THD+N vs Frequency

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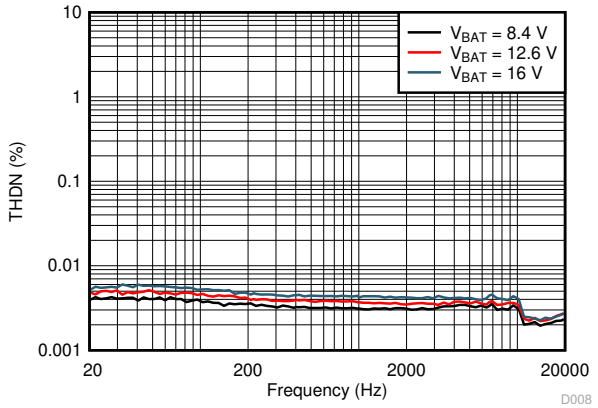
6.9 Typical Characteristics (continued)

At T_A = 25°C, f_{SPK_AMP} = 384 kHz, input signal is 1 kHz Sine, unless otherwise noted. Filter used for Load Resistance is 30 µH, unless otherwise noted.



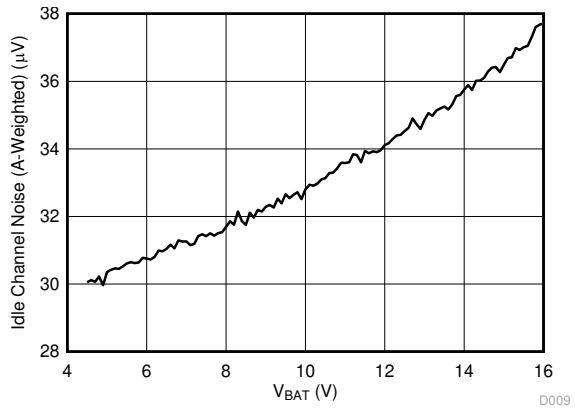
F_{IN} = 20 Hz – 20 kHz P_{OUT} = 5 W RL = 4 Ω + 30 µH

图 6-7. THD+N vs Frequency



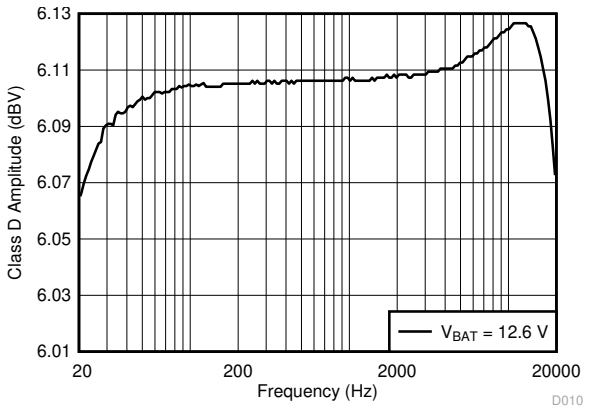
F_{IN} = 20 Hz – 20 kHz P_{OUT} = 1 W RL = 8 Ω + 30 µH

图 6-8. THD+N vs Frequency



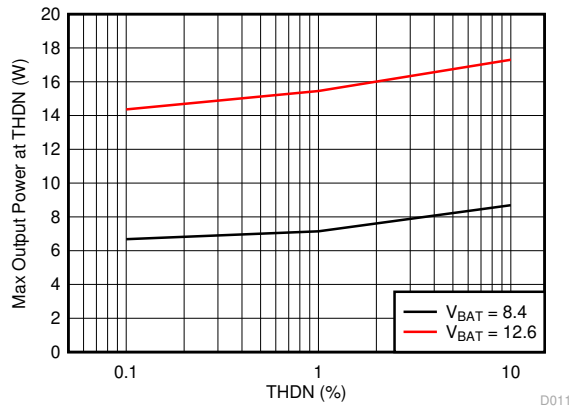
VBAT = 4.5 V – 16 V

图 6-9. Idle Channel Noise (A-Weighted) vs V_{BAT}



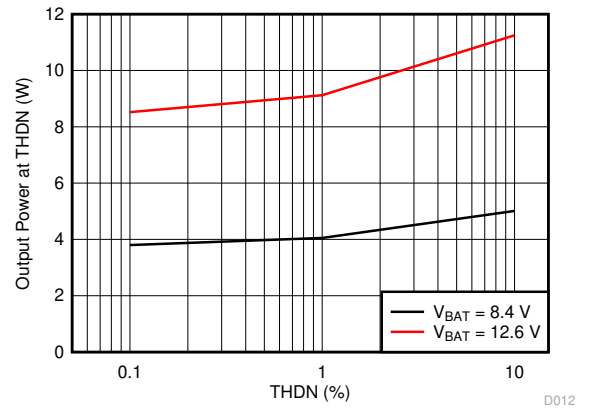
F_S = 48 kHz P_{OUT} = 1 W

图 6-10. Amplitude vs Frequency



RL = 4 Ω

图 6-11. Max Output Power vs THD+N

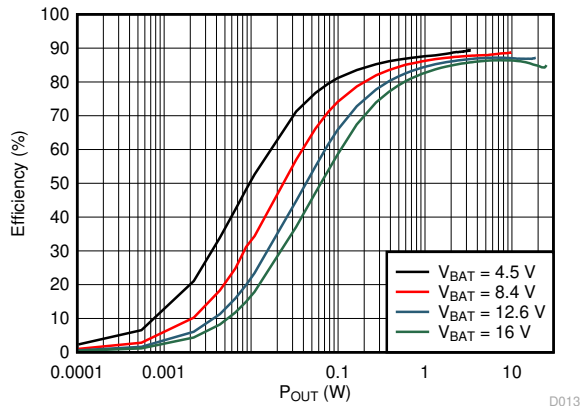


RL = 8 Ω

图 6-12. Max Output Power vs THD+N

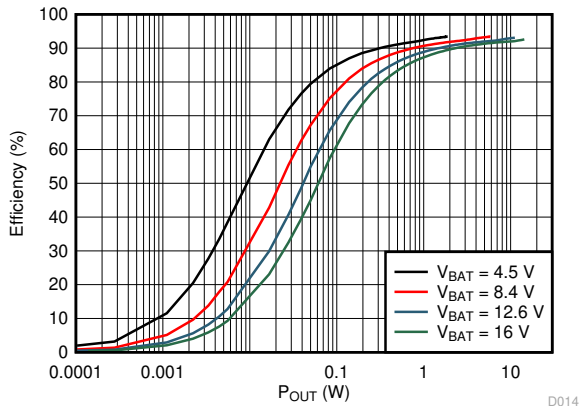
6.9 Typical Characteristics (continued)

At T_A = 25°C, f_{SPK_AMP} = 384 kHz, input signal is 1 kHz Sine, unless otherwise noted. Filter used for Load Resistance is 30 µH, unless otherwise noted.



RL = 4 Ω F_{IN} = 1 kHz

图 6-13. Efficiency vs Output Power



RL = 8 Ω F_{IN} = 1 kHz

图 6-14. Efficiency vs Output Power

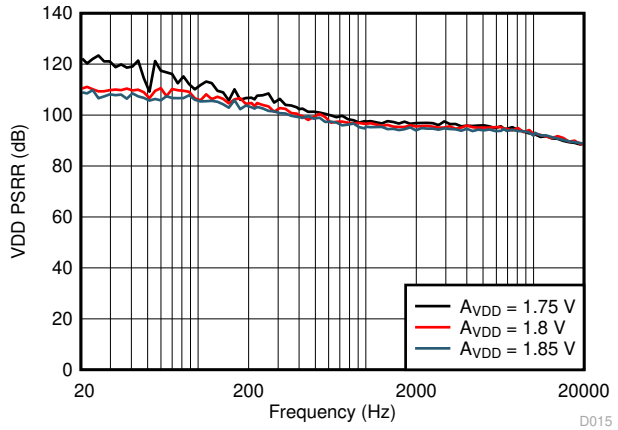


图 6-15. VDD PSRR vs Frequency

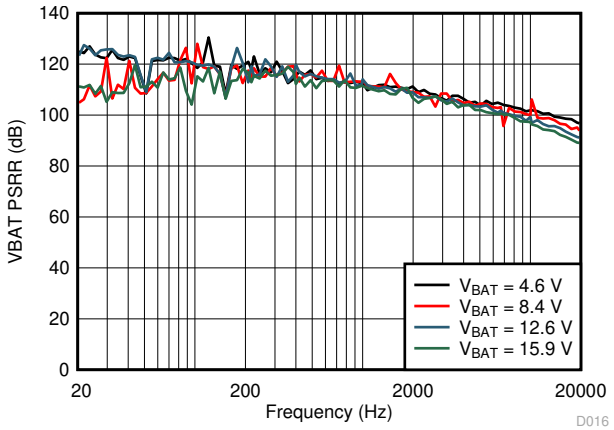
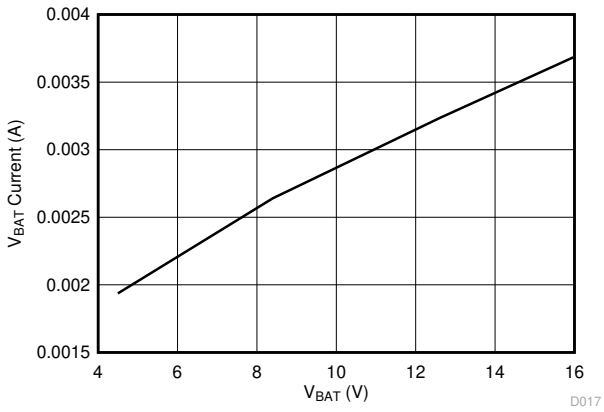
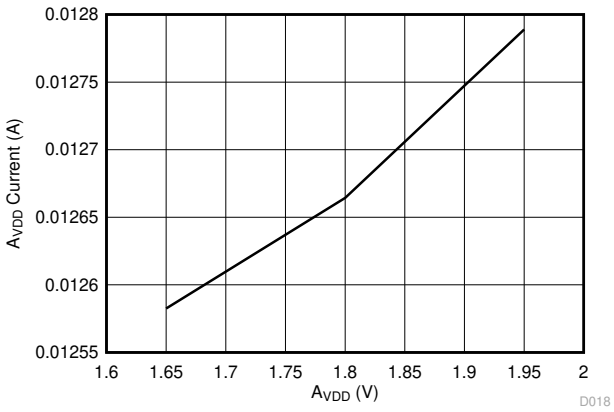


图 6-16. VBAT PSRR vs Frequency



V_{BAT} = 4.5 V – 16 V

图 6-17. V_{BAT} Idle Current vs V_{BAT}



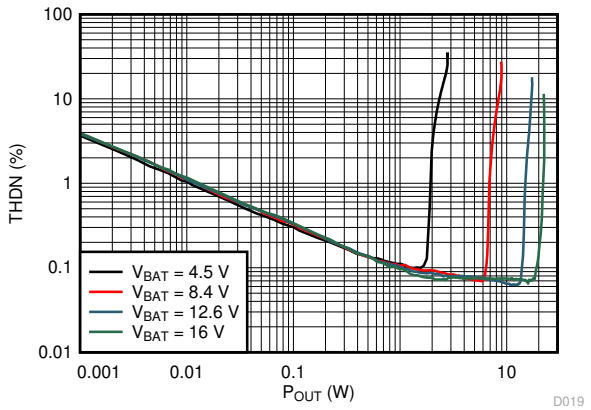
A. A_{VDD} = 1.65 V – 1.95 V IV Sense Enabled

图 6-18. A_{VDD} Idle Current vs A_{VDD}

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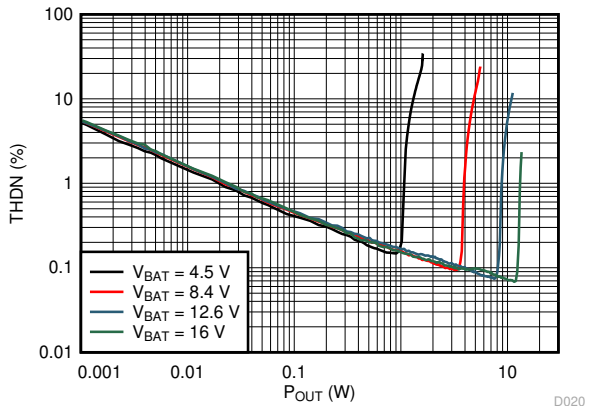
6.9 Typical Characteristics (continued)

At T_A = 25°C, f_{SPK_AMP} = 384 kHz, input signal is 1 kHz Sine, unless otherwise noted. Filter used for Load Resistance is 30 µH, unless otherwise noted.



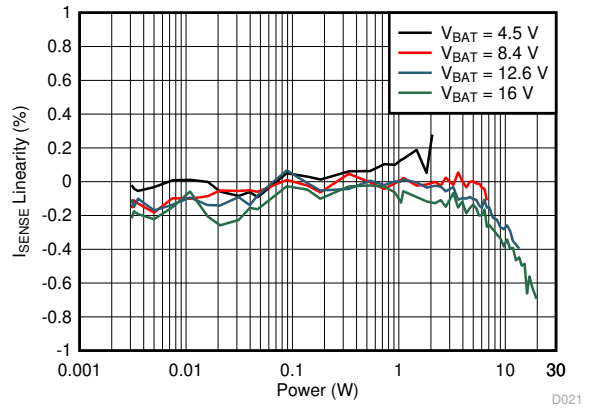
RL = 4 Ω F_{IN} = 1 kHz

图 6-19. I_{SENSE} THD+N vs Output Power



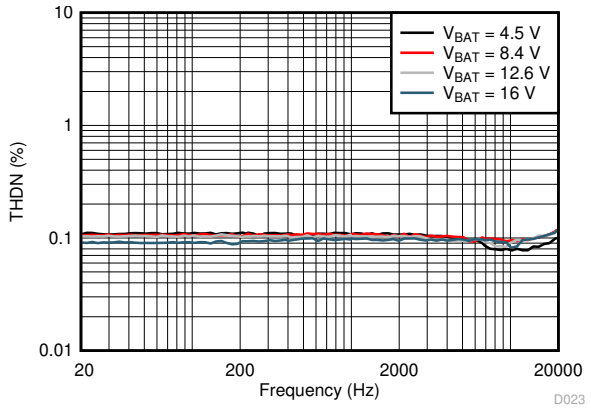
RL = 8 Ω F_{IN} = 1 kHz

图 6-20. I_{SENSE} THD+N vs Output Power



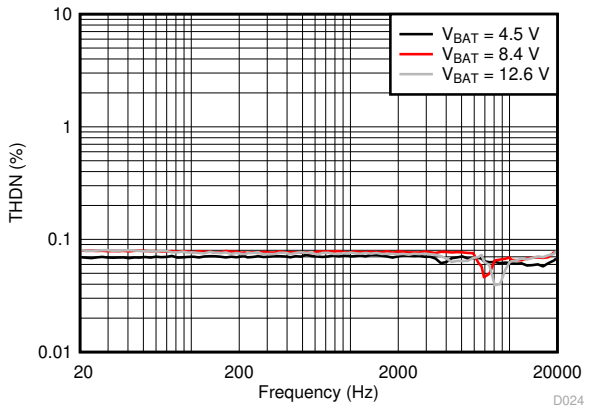
RL = 4 Ω Pilot tone = 40 Hz, 34 dB

图 6-21. I_{SENSE} Gain Linearity vs Output Power



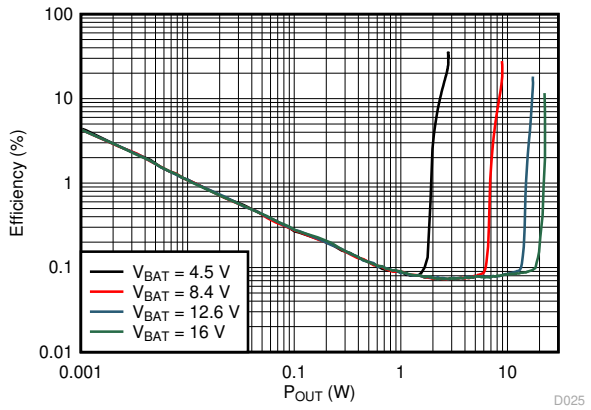
F_{IN} = 20 Hz – 20 kHz P_{OUT} = 1 W

图 6-22. I_{SENSE} THD+N vs Frequency



F_{IN} = 20 Hz – 20 kHz P_{OUT} = 1 W

图 6-23. I_{SENSE} THD+N vs Frequency

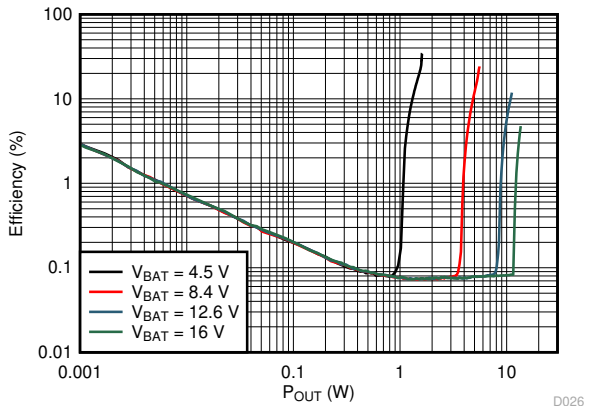


RL = 4 Ω

图 6-24. V_{SENSE} THD+N vs Output Power

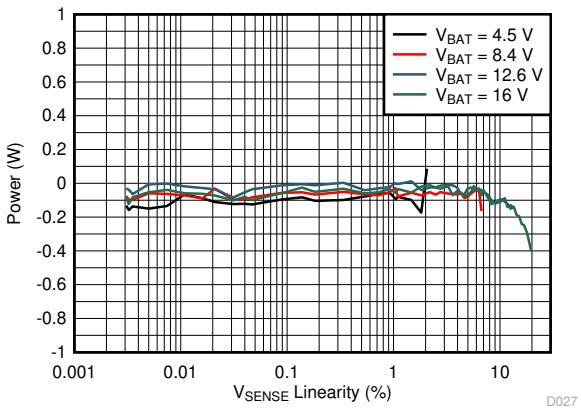
6.9 Typical Characteristics (continued)

At T_A = 25°C, f_{SPK_AMP} = 384 kHz, input signal is 1 kHz Sine, unless otherwise noted. Filter used for Load Resistance is 30 µH, unless otherwise noted.



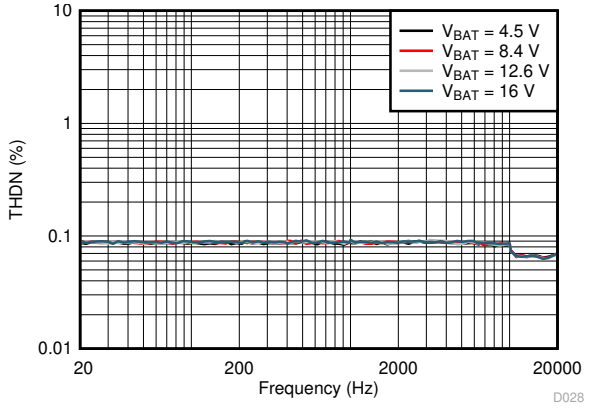
RL = 8 Ω

图 6-25. V_{SENSE} THD+N vs Output Power



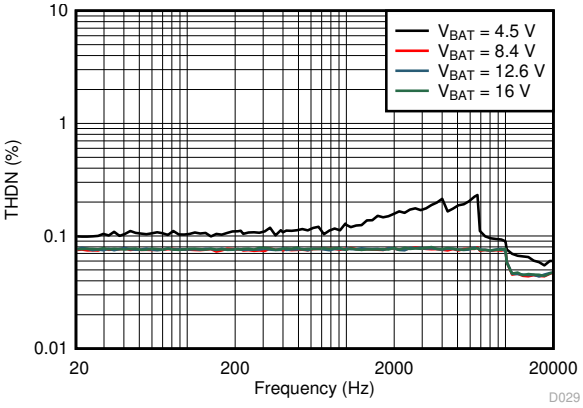
RL = 4 Ω Pilot tone = 40 Hz, 34 dB

图 6-26. Output Power vs V_{SENSE} Linearity



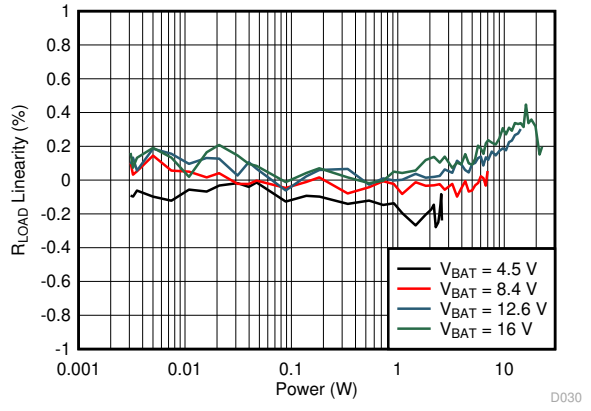
FIN = 20 Hz – 20 kHz POUT = 1 W

图 6-27. V_{SENSE} THD+N vs Frequency



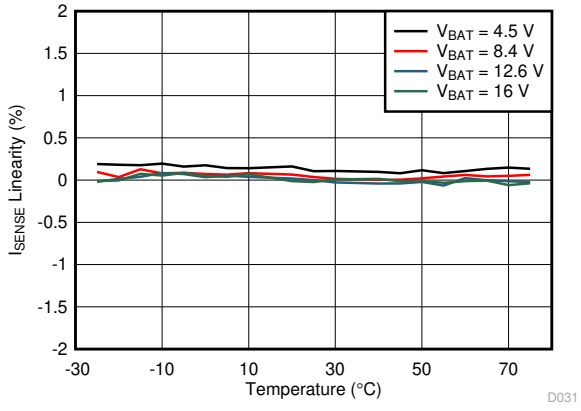
FIN = 20 Hz – 20 kHz POUT = 1 W

图 6-28. V_{SENSE} THD+N vs Frequency



RL = 4 Ω + 30 µH Pilot tone = 40 Hz, 34 dB

图 6-29. V/I_{SENSE} Gain Linearity vs Output Power



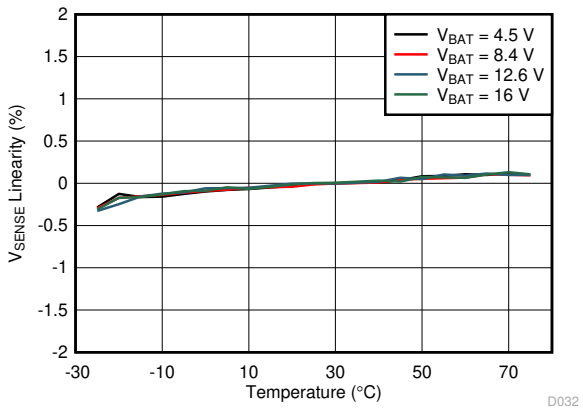
TA = –20°C – 70°C Pilot tone = 40 Hz, 34 dB

图 6-30. I_{SENSE} Gain Deviation vs Temperature

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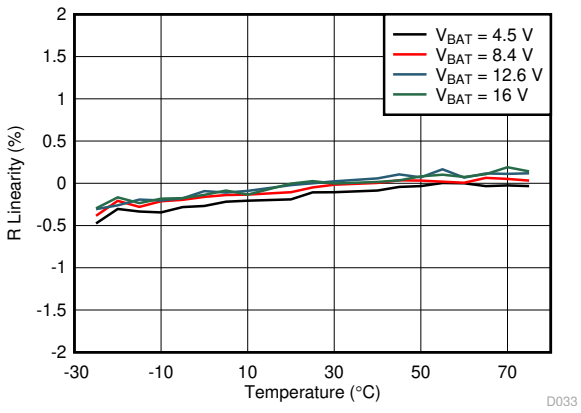
6.9 Typical Characteristics (continued)

At T_A = 25°C, f_{SPK_AMP} = 384 kHz, input signal is 1 kHz Sine, unless otherwise noted. Filter used for Load Resistance is 30 µH, unless otherwise noted.



T_A = –20°C – 70°C Pilot tone = 40 Hz, 34 dB

图 6-31. V_{SENSE} Gain Deviation vs Temperature



T_A = –20°C – 70°C Pilot tone = 40 Hz, 34 dB

图 6-32. V/I_{SENSE} Gain Deviation vs Temperature

7 Parameter Measurement Information

All typical characteristics for the devices are measured using the Bench EVM and an Audio Precision SYS-2722 Audio Analyzer. A PSIA interface is used to allow the I²S interface to be driven directly into the SYS-2722. Speaker output terminals are connected to the Audio-Precision analyzer analog inputs through a differential-to-single ended(D2S) filter as shown below. The D2S filter contains a 1st order Passive pole at 120 kHz. The D2S filter ensures the TAS2770 high performance class-D amplifier sees a fully differential matched loading at its outputs. This prevents measurement errors due to loading effects of AUX-0025 filter on the class-D outputs.

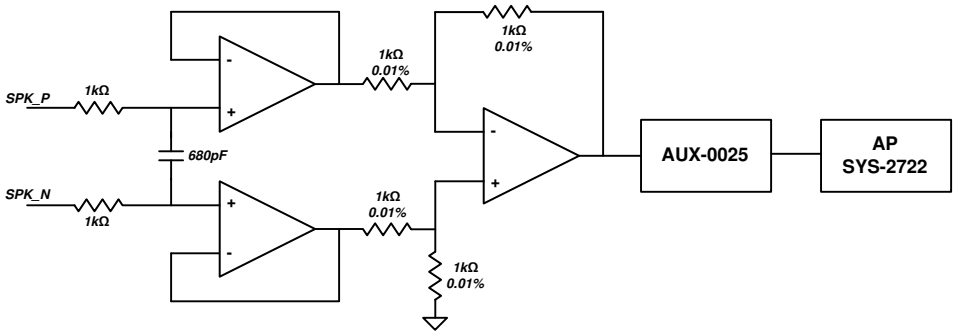


图 7-1. Differential To Single Ended (D2S) Filter

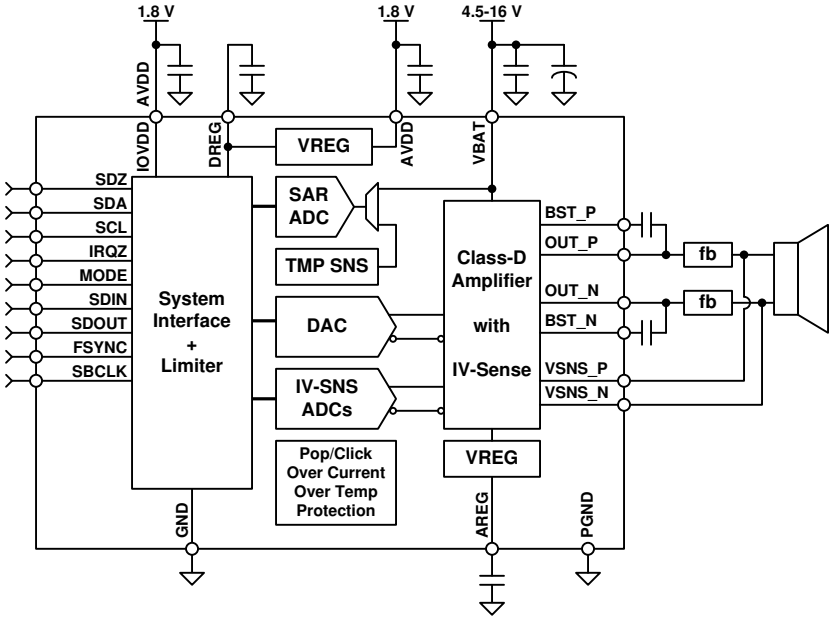
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8 Detailed Description

8.1 Overview

The TAS2770 is a mono digital input Class-D amplifier optimized for mobile applications where efficient battery operation and small solution size are crucial. It integrates speaker voltage and current sensing and battery tracking limiting with brown out prevention. The device can operate in either TDM/I^{2}C mode. Both modes support two PDM inputs that can be used for low latency playback or sensor aggregation.

8.2 Functional Block Diagram



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8.3 Feature Description

8.3.1 Device Mode and Address Selection

The TAS2770 can operate in two distinct operational modes, each with eight selectable device addresses. In TDM/I^{2}C Mode, audio input and output are provided through the FSYNC, SBCLK, SDIN and SDOUT pins using formats including I^{2}S, Left Justified and TDM. Configuration and status are provided through the SDA and SCL pins using the I^{2}C protocol.

The PDM input can be used for a low latency playback path or as a sensor input.

表 8-1 below illustrates how to configure the device for TDM/I^{2}C Mode. I^{2}C slave addresses are shown left shifted by one bit with the R/W bit set to 0 (i.e. {ADDR[6:0],1b0}). 5% or better tolerance resistors should be used for setting the mode configuration.

表 8-1. TDM/I^{2}C Mode Address Selection

MODE PIN	I2C SLAVE ADDRESS	
	TAS5770LC0	TAS2770
Short to GND	0x62	0x82
470 Ω to GND	0x64	0x84
470 Ω to IOVDD	0x66	0x86
2.2 KΩ to GND	0x68	0x88
2.2 KΩ to IOVDD	0x6A	0x8A
10 KΩ to GND	0x6C	0x8C
10 KΩ to IOVDD	0x6E	0x8E

表 8-1. TDM/I²C Mode Address Selection (continued)

MODE PIN	I2C SLAVE ADDRESS	
	TAS5770LC0	TAS2770
47 KΩ to IOVDD	0x70	0x90

8.3.2 General I²C Operation

The I²C bus employs two signals, SDA (data) and SCL (clock), to communicate between integrated circuits in a system using serial data transmission. The address and data 8-bit bytes are transferred most-significant bit (MSB) first. In addition, each byte transferred on the bus is acknowledged by the receiving device with an acknowledge bit. Each transfer operation begins with the master device driving a start condition on the bus and ends with the master device driving a stop condition on the bus. The bus uses transitions on the data terminal (SDA) while the clock is at logic high to indicate start and stop conditions. A high-to-low transition on SDA indicates a start, and a low-to-high transition indicates a stop. Normal data-bit transitions must occur within the low time of the clock period. shows a typical sequence.

The master generates the 7-bit slave address and the read/write (R/W) bit to open communication with another device and then waits for an acknowledge condition. The device holds SDA low during the acknowledge clock period to indicate acknowledgment. When this occurs, the master transmits the next byte of the sequence. Each device is addressed by a unique 7-bit slave address plus R/W bit (1 byte). All compatible devices share the same signals via a bi-directional bus using a wired-AND connection.

Use external pull-up resistors for the SDA and SCL signals to set the logic-high level for the bus. Use pull-up resistors between 2 kΩ and 4.7 kΩ. Do not allow the SDA and SCL voltages to exceed the device supply voltage, IOVDD.

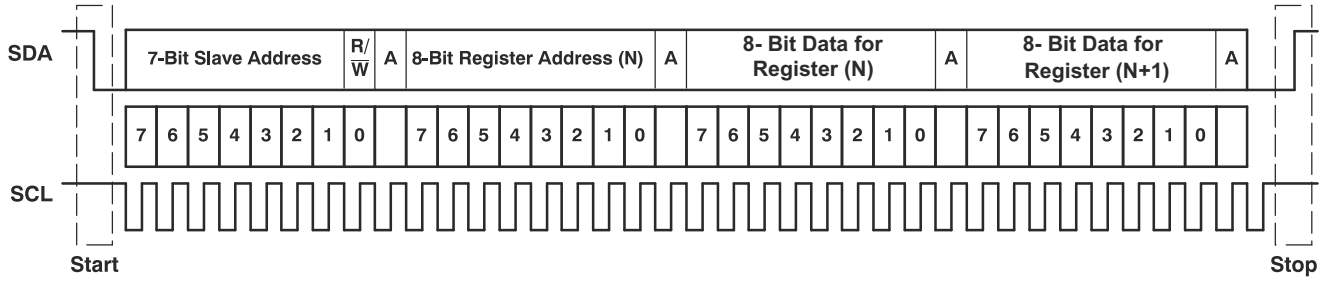


图 8-1. Typical I²C Sequence

There is no limit on the number of bytes that can be transmitted between start and stop conditions. When the last word transfers, the master generates a stop condition to release the bus. 图 8-1shows a generic data transfer sequence.

8.3.3 Single-Byte and Multiple-Byte Transfers

The serial control interface supports both single-byte and multiple-byte read/write operations for all registers. During multiple-byte read operations, the TAS2770 responds with data, a byte at a time, starting at the register assigned, as long as the master device continues to respond with acknowledges.

The TAS2770 supports sequential I²C addressing. For write transactions, if a register is issued followed by data for that register and all the remaining registers that follow, a sequential I²C write transaction has taken place. For I²C sequential write transactions, the register issued then serves as the starting point, and the amount of data subsequently transmitted, before a stop or start is transmitted, determines to how many registers are written.

8.3.4 Single-Byte Write

As shown in 图 8-2, a single-byte data-write transfer begins with the master device transmitting a start condition followed by the I²C device address and the read/write bit. The read/write bit determines the direction of the data transfer. For a write-data transfer, the read/write bit must be set to 0. After receiving the correct I²C device address and the read/write bit, the TAS2770 responds with an acknowledge bit. Next, the master transmits the

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register byte corresponding to the device internal memory address being accessed. After receiving the register byte, the device again responds with an acknowledge bit. Finally, the master device transmits a stop condition to complete the single-byte data-write transfer.

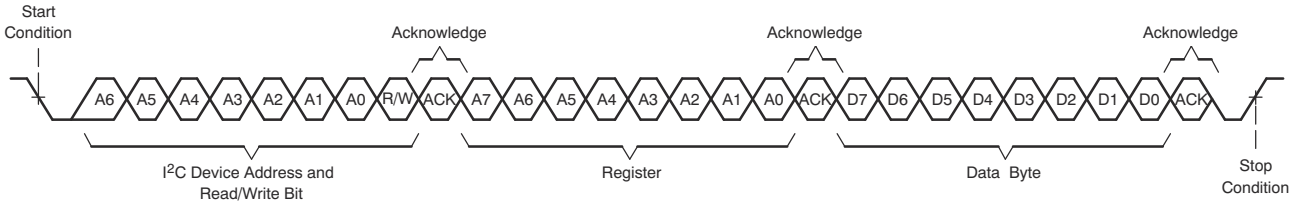


图 8-2. Single-Byte Write Transfer

8.3.5 Multiple-Byte Write and Incremental Multiple-Byte Write

A multiple-byte data write transfer is identical to a single-byte data write transfer except that multiple data bytes are transmitted by the master device to the TAS2770 as shown in 图 8-3. After receiving each data byte, the device responds with an acknowledge bit.

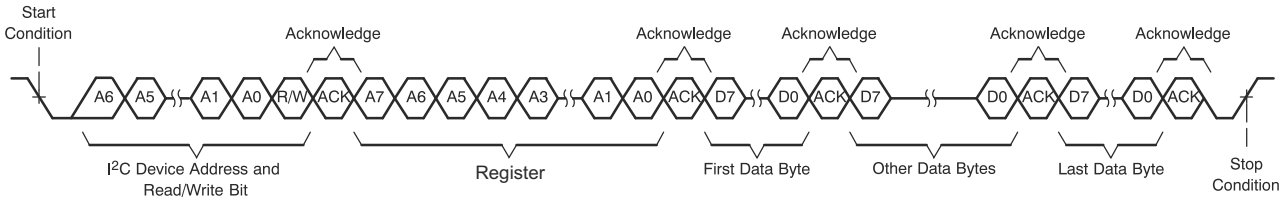


图 8-3. Multi-Byte Write Transfer

8.3.6 Single-Byte Read

As shown in 图 8-4, a single-byte data-read transfer begins with the master device transmitting a start condition followed by the I^{2}C device address and the read/write bit. For the data-read transfer, both a write followed by a read are actually done. Initially, a write is done to transfer the address byte of the internal memory address to be read. As a result, the read/write bit is set to a 0.

After receiving the TAS2770 address and the read/write bit, the device responds with an acknowledge bit. The master then sends the internal memory address byte, after which the device issues an acknowledge bit. The master device transmits another start condition followed by the TAS2770 address and the read/write bit again. This time, the read/write bit is set to 1, indicating a read transfer. Next, the TAS2770 transmits the data byte from the memory address being read. After receiving the data byte, the master device transmits a not-acknowledge followed by a stop condition to complete the single-byte data read transfer.

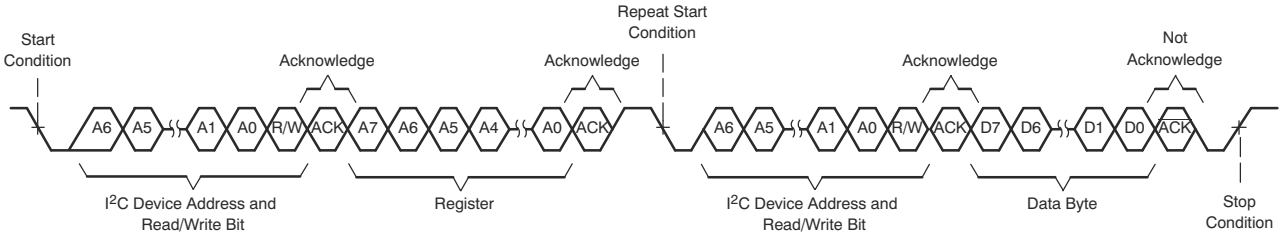


图 8-4. Single-Byte Read Transfer

8.3.7 Multiple-Byte Read

A multiple-byte data-read transfer is identical to a single-byte data-read transfer except that multiple data bytes are transmitted by the TAS2770 to the master device as shown in 图 8-5. With the exception of the last data byte, the master device responds with an acknowledge bit after receiving each data byte.

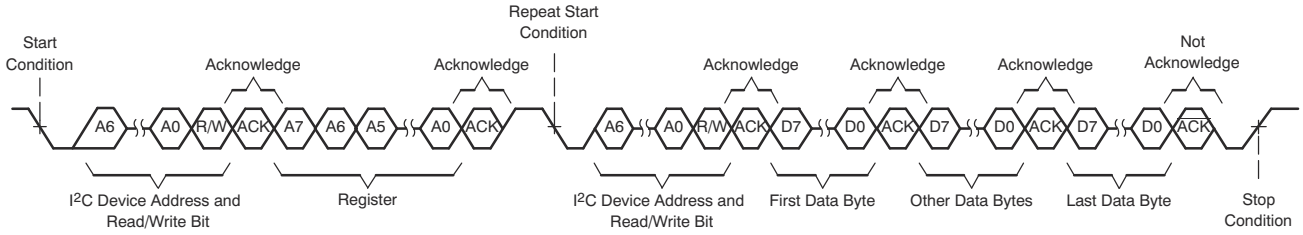


图 8-5. Multi-Byte Read Transfer

8.3.8 Register Organization

Device configuration and coefficients are stored using a page and book scheme. Each page contains 128 bytes and each book contains 256 pages. All device configuration registers are stored in book 0, page 0, which is the default setting at power up (and after a software reset). The book and page can be set by the *BOOK[7:0]* and *PAGE[7:0]* registers respectively.

8.4 Device Functional Modes

8.4.1 PDM Input

The TAS2770 provides one PDM input that can be used for low latency audio playback or sensor aggregation in TDM/I^{2}C mode. 图 8-6 below illustrates the double data rate nature of the PDM inputs. Each input has two interleaved PDM channels, one sampled by the rising edge and the other by the falling edge of the clock.

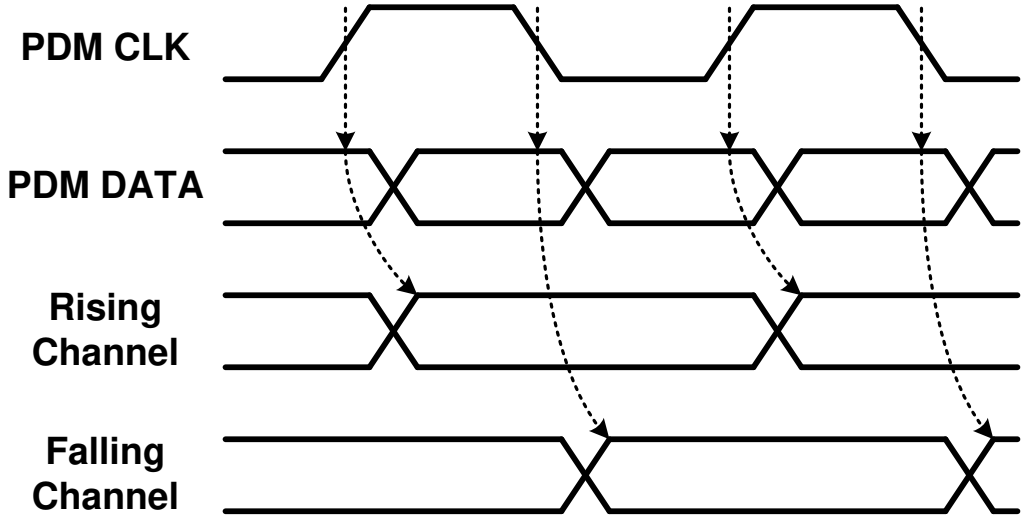


图 8-6. PDM Waveform

The PDM inputs are sampled by the PDMCK pin, which can be independently configured as either a PDM clock slave input or a PDM clock master output. The *PDM_EDGE[1:0]* and *PDM_SLV[1:0]* register bits select the sample clock edge and master/slave mode for each of the two PDM inputs. In master mode the PDMCK pin can disable the clocks (and drive a logic 0) by setting the *PDM_GATE[1:0]* register bits low. The *PDM_CLK[1:0]* register bits select which clock is used to sample each PDM input.

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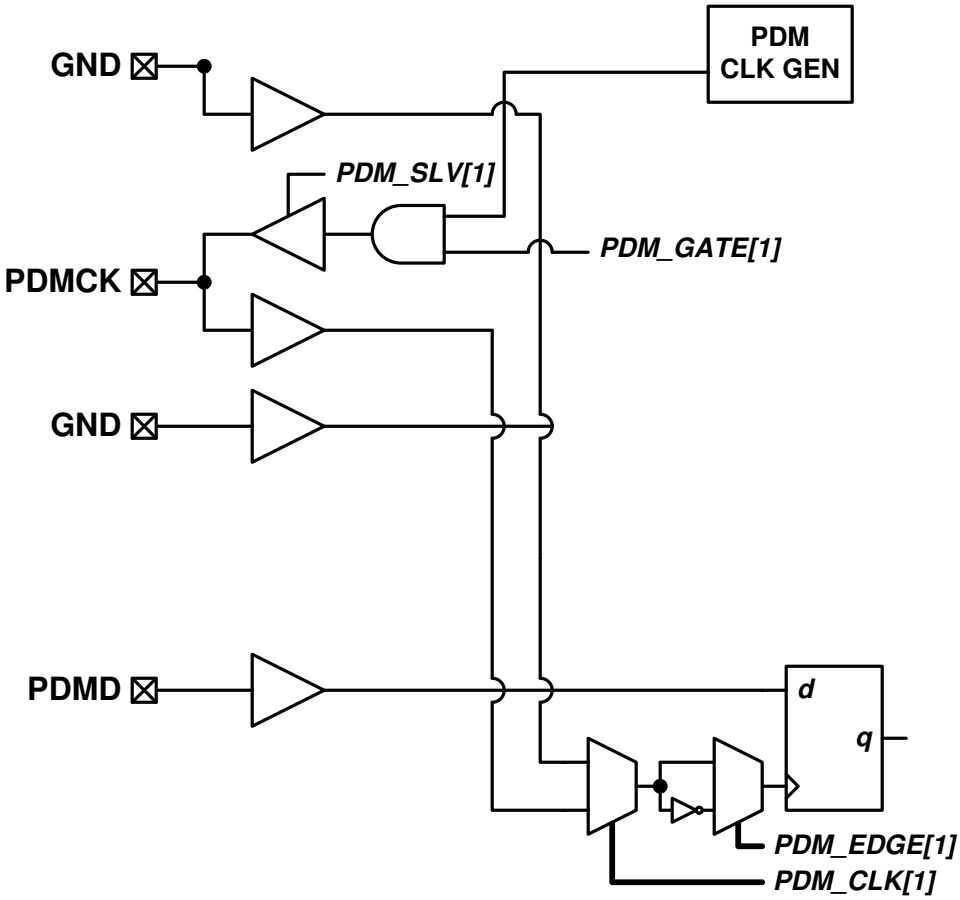


图 8-7. PDM Data and Clock Input Block Diagram

When configured as a clock slave, the PDM clock input does not require a specific phase relationship to the system clock (SBCLK in TDM/I^{2}C Mode), but must have an exact frequency relationship to the audio sample rate. This is equivalent to 64/32/16 (~3 MHz) or 128/64/32 (~6 MHz) times a single/double/quadruple speed sample rate. The PDM rate is set by the *PDM_RATE1[1:0]* register bits.

When the PDMCK pin is configured as a clock master, the TAS2770 will output a 50% duty cycle clock of frequency that is set by the *PDM_RATE1[1:0]* register bits (64/32/16 or 128/64/32 times a single/double/quadruple speed sample rate).

The *PDM_MAP* register bit selects which PDM pin is used for audio playback input and which is used for PDM sensor input. The PDM sensor input can be decimated (time aligned with the IV sense) and transmitted on the SDOUT pin when the device is in TDM/I^{2}C mode.

表 8-2. PDM Input Capture Edge

PDM Input Pin	Register Bit	Value	Capture Edge
PDMD	*PDM_EDGE[1]*	0	Rising (default)
		1	Falling

表 8-3. PDM Clock Slave

PDM Input Pin	Register Bit	Value	Master/Slave
PDMD	*PDM_SLV[1]*	0	Slave (default)
		1	Master

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表 8-4. PDM Clock Select

PDM Input Pin	Register Bit	Value	Clock Source
PDMD	*PDM_CLK[1]*	0	GND
		1	PDMCK (default)

表 8-5. PDM Master Mode Clock Gate

PDM Clock Pin	Register Bit	Value	Gating
PDMCK	*PDM_GATE[1]*	0	Gated Off (default)
		1	Active

表 8-6. PDM Input Sample Rate

PDM Input Pin	Register Bits	Value	Sample Rate
PDMD	*PDM_RATE 1[1:0]*	00	2.54 - 3.38 MHz (default)
		01	5.08 - 6.76 MHz
		10	Reserved
		11	Reserved

表 8-7. PDM Pin Mapping

PDM_MAP	Mapping
0	PDMD pin for sensor input (default)
1	PDMD pin for playback

8.4.2 TDM Port

The TAS2770 provides a flexible TDM serial audio port for use in TDM/I^{2}C Mode. The port can be configured to support a variety of formats including stereo I^{2}S, Left Justified and TDM. Mono audio playback is available via the SDIN pin. The SDOUT pin is used to transmit sample streams including speaker voltage and current sense, VBAT voltage, die temperature and channel gain.

The TDM serial audio port supports up to 8 32-bit time slots at 44.1/48 kHz, 4 32-bit time slots at a 88.2/96 kHz sample rate and 2 32-bit time slots at a 176.4/192 kHz sample rate. The device supports 2 time slots at 32 bits in width and 4 or 8 time slots at 16, 24 or 32 bits in width. Valid SBCLK to FSYNC ratios are 64, 96, 128, 192, and 256.. Note that the device will automatically detect the number of time slots and this does not need to be programmed.

By default, the TAS2770 will automatically detect the PCM playback sample rate. This can be disabled by setting the *AUTO_RATE* register bit high.

The *SAMP_RATE[2:0]* register bits set the PCM audio sample rate when *AUTO_RATE* = 1. The TAS2770 employs a robust clock fault detection engine that will automatically volume ramp down the playback path if FSYNC does not match the configured sample rate (if *AUTO_RATE* = 1) or the ratio of SBCLK to FSYNC is not supported (minimizing any audible artifacts). Once the clocks are detected to be valid in both frequency and ratio, the device will automatically volume ramp the playback path back to the configured volume and resume playback.

表 8-8. PCM Auto Sample Rate Detection

AUTO_RATE	Setting
0	Enabled (default)

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表 8-8. PCM Auto Sample Rate Detection (continued)

AUTO_RATE	Setting
1	Disabled

表 8-9. PCM Audio Sample Rates

SAMP_RATE[1:0]	Sample Rate
000	Reserved
001	Reserved
010	Reserved
011	44.1 kHz / 48 kHz (default)
100	88.2 kHz / 96 kHz
101	176.4 kHz / 192 kHz
110	Reserved
111	Reserved

图 8-8 and 图 8-9 below illustrates the receiver frame parameters required to configure the port for playback. A frame begins with the transition of FSYNC from either high to low or low to high (set by the *FRAME_START* register bit). FSYNC and SDIN are sampled by SBCLK using either the rising or falling edge (set by the *RX_EDGE* register bit). The *RX_OFFSET[4:0]* register bits define the number of SBCLK cycles from the transition of FSYNC until the beginning of time slot 0. This is typically set to a value of 0 for Left Justified format and 1 for an I^2S format.

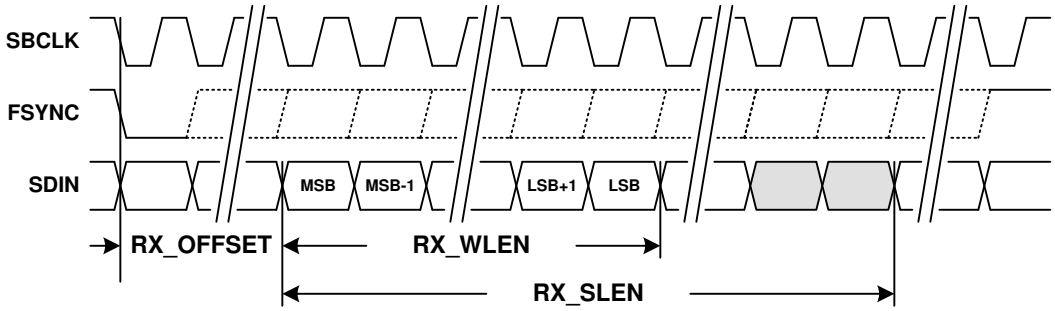


图 8-8. TDM RX Time Slot with Left Justification

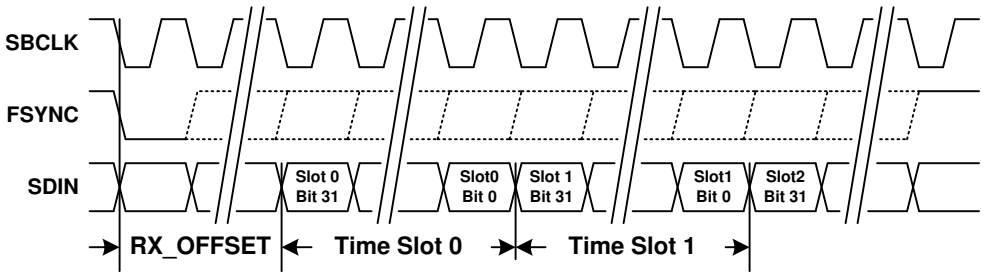


图 8-9. TDM RX Time Slots

表 8-10. TDM Start of Frame Polarity

FRAME_START	Polarity
0	Low to High on FSYNC

表 8-10. TDM Start of Frame Polarity (continued)

FRAME_START	Polarity
1	High to Low on FSYNC (default)

表 8-11. TDM RX Capture Polarity

RX_EDGE	FSYNC and SDIN Capture Edge
0	Rising edge of SBCLK (default)
1	Falling edge of SBCLK

表 8-12. TDM RX Start of Frame to Time Slot 0 Offset

RX_OFFSET[4:0]	SBCLK Cycles
0x00	0
0x01	1 (default)
0x02	2
...	...
0x1E	30
0x1F	31

The *RX_SLEN[1:0]* register bits set the length of the RX time slot. The length of the audio sample word within the time slot is configured by the *RX_WLEN[1:0]* register bits. The RX port will left justify the audio sample within the time slot by default, but this can be changed to right justification via the *RX_JUSTIFY* register bit. The TAS2770 supports mono and stereo down mix playback ([L+R]/2) via the left time slot, right time slot and time slot configuration register bits (*RX_SLOT_L[3:0]*, *RX_SLOT_R[3:0]* and *RX_SCFG[1:0]* respectively). By default the device will playback mono from the time slot equal to the I^2C base address offset (set by the MODE pin) for playback. The *RX_SCFG [1:0]* register bits can be used to override the playback source to the left time slot, right time slot or stereo down mix set by the *RX_SLOT_L[3:0]* and *RX_SLOT_R[3:0]* register bits.

If time slot selections places reception either partially or fully beyond the frame boundary, the receiver will return a null sample equivalent to a digitally muted sample.

表 8-13. TDM RX Time Slot Length

RX_SLEN[1:0]	Time Slot Length
00	16-bits
01	24-bits
10	32-bits (default)
11	reserved

表 8-14. TDM RX Sample Word Length

RX_WLEN[1:0]	Length
00	16-bits
01	20-bits
10	24-bits (default)
11	32-bits

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表 8-15. TDM RX Sample Justification

RX_JUSTIFY	Justification
0	Left (default)
1	Right

表 8-16. TDM RX Time Slot Select Configuration

RX_SCFG[1:0]	Config Origin
00	Mono with Time Slot equal to I²C Address Offset (default)
01	Mono Left Channel
10	Mono Right Channel
10	Stereo Down Mix [L+R]/2

表 8-17. TDM RX Left Channel Time Slot

RX_SLOT_L[3:0]	Time Slot
0x0	0 (default)
0x1	1
...	...
0xE	14
0xF	15

表 8-18. TDM RX Right Channel Time Slot

RX_SLOT_R[3:0]	Time Slot
0x0	0 (default)
0x1	1
...	...
0xE	14
0xF	15

The TDM port can transmit a number sample streams on the SDOUT pin including speaker voltage sense, speaker current sense, decimated PDM input, VBAT voltage, die temperature and channel gain. 图 8-10 below illustrates the alignment of time slots to the beginning of a frame and how a given sample stream is mapped to time slots. Either the rising or falling edge of SBCLK can be used to transmit data on the SDOUT pin, which can be configured by setting the *TX_EDGE* register bit. The *TX_OFFSET[2:0]* register bits define the number SBCLK cycles between the start of a frame and the beginning of time slot 0. This would typically be programmed to 0 for Left Justified format and 1 for I²S format. The TDM TX can either transmit logic 0 or Hi-Z depending on the setting of the *TX_FILL* register bit setting. An optional bus keeper will weakly hold the state of SDOUT when all devices driving are Hi-Z. Since only one bus keeper is required on SDOUT, this feature can be disabled via the *TX_KEEPER* register bit.

Each sample stream is composed of either one or two 8-bit time slots. Speaker voltage sense, speaker current sense and decimated PDM sample streams are 16-bit precision, so they will always utilize two TX time slots. The VBAT voltage stream is 12-bit precision, and can either be transmitted left justified in a 16-bit word (using two time slots) or can be truncated to 8-bits (the top 8 MSBs) and be transmitted in a single time slot. This is configured by setting *VBAT_SLEN* register bit. The Die temperature and gain are both 8-bit precision and are transmitted in a single time slot.

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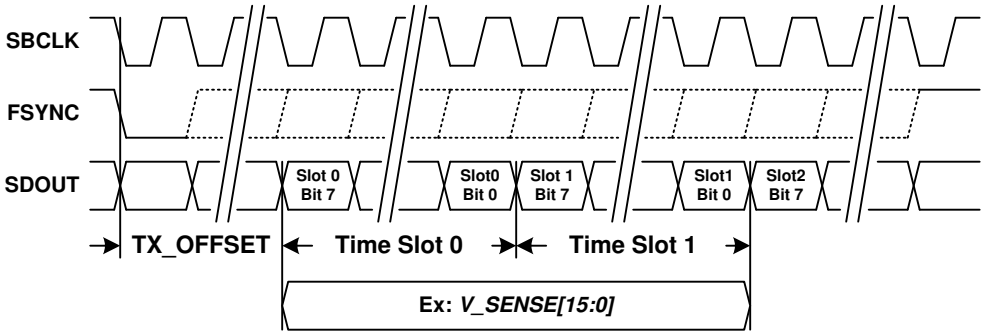


图 8-10. TDM Port TX Diagram

表 8-19. TDM TX Transmit Polarity

TX_EDGE	SDOUT Transmit Edge
0	Rising edge of SBCLK
1	Falling edge of SBCLK (default)

表 8-20. TDM TX Start of Frame to Time Slot 0 Offset

TX_OFFSET[2:0]	SBCLK Cycles
0x0	0
0x1	1 (default)
0x2	2
. . .	...
0x6	6
0x7	7

表 8-21. TDM TX Unused Bit Field Fill

TX_FILL	SDOUT Unused Bit Fields
0	Transmit 0
1	Transmit Hi-Z (default)

表 8-22. TDM TX SDOUT Bus Keeper Enable

TX_KEEPER	SDOUT Bus Keeper
0	Disable bus keeper
1	Enable bus keeper (default)

The time slot register for each sample stream defines where the MSB transmission begins. For instance, if *VSNS_SLOT[5:0]* is set to 2, the upper 8 MSBs will be transmitted in time slot 2 and the lower 8 LSBs will be transmitted in time slot 3. Each sample stream can be individually enabled or disabled. This is useful to manage limited TDM bandwidth since it may not be necessary to transmit all streams for all devices on the bus.

It is important to ensure that time slot assignments for actively transmitted sample streams do not conflict. For instance, if *VSNS_SLOT[5:0]* is set to 2 and *ISNS_SLOT[5:0]* is set to 3, the lower 8 LSBs of voltage sense will conflict with the upper 8 MSBs of current sense. This will produce unpredictable transmission results in the conflicting bit slots (i.e. the priority is not defined).

If time slot selections place transmission beyond the frame boundary, the transmitter will truncate transmission at the frame boundary.

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表 8-23. TDM Voltage Sense Time Slot

VSNS_SLOT[5:0]	Slot
0x00	0 (default)
0x01	1
0x02	2
. . .	...
0x3E	62
0x3F	63

表 8-24. TDM Voltage Sense Transmit Enable

VSNS_TX	State
0	Disabled (default)
1	Enabled

表 8-25. TDM Current Sense Time Slot

ISNS_SLOT[5:0]	Slot
0x00	0
0x01	1
0x02	2 (default)
. . .	...
0x3E	62
0x3F	63

表 8-26. TDM Current Sense Transmit Enable

ISNS_TX	State
0	Disabled (default)
1	Enabled

表 8-27. TDM Decimated PDM Input Time Slot

PDM_SLOT[5:0]	Slot
0x00	0
0x01	1
. . .	...
0x04	4 (default)
. . .	...
0x3E	62
0x3F	63

表 8-28. TDM Decimated PDM Input Transmit Enable

PDM_TX	State
0	Disabled (default)
1	Enabled

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表 8-29. TDM VBAT Time Slot

VBAT_SLOT[5:0]	Slot
0x00	0
0x01	1
. . .	...
0x06	6 (default)
. . .	...
0x3E	62
0x3F	63

表 8-30. TDM VBAT Time Slot Length

VBAT_SLEN	Slot Length
0	Truncate to 8-bits (default)
1	Left justify to 16-bits

表 8-31. TDM VBAT Transmit Enable

VBAT_TX	State
0	Disabled (default)
1	Enabled

表 8-32. TDM Temp Sensor Time Slot

TEMP_SLOT[5:0]	Slot
0x00	0
0x01	1
. . .	...
0x07	7 (default)
. . .	...
0x3E	62
0x3F	63

表 8-33. TDM Temp Sensor Transmit Enable

TEMP_TX	State
0	Disabled (default)
1	Enabled

表 8-34. TDM Limiter Gain Reduction Time Slot

GAIN_SLOT[5:0]	Slot
0x00	0
0x01	1
. . .	...
0x08	8 (default)
. . .	...

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表 8-34. TDM Limiter Gain Reduction Time Slot (continued)

GAIN_SLOT[5:0]	Slot
0x3E	62
0x3F	63

表 8-35. TDM Limiter Gain Reduction Transmit Enable

GAIN_TX	State
0	Disabled (default)
1	Enabled

8.4.3 Playback Signal Path

8.4.3.1 High Pass Filter

Excessive DC and low frequency content in audio playback signal can damage loudspeakers, so the TAS2770 employs a high-pass filter (HPF) to prevent this from occurring for the PCM playback path. No HPF is available in the PDM playback path. 表 8-36 below shows the -3 dB corner frequencies available for each sample rate set by register bits *HPF_FREQ[2:0]*. The filter can be bypassed by setting the *HPF_FREQ[2:0]* register to 3'b000. The HPF Bi-Quad filter coefficients can also be directly programmed via the TBD register bits.

表 8-36. HPF Filter Settings

HPF_FREQ[2:0]	-3 dB FREQUENCY (Hz)	
	44.1/88.2/176.4 kHz	48/96/192 kHz
000	bypass	bypass
001	1.8 (default)	2 (default)
010	46	50
011	92	100
100	184	200
101	368	400
110	735	800
111	Reserved	Reserved

8.4.3.2 Digital Volume Control and Amplifier Output Level

The gain from audio input to speaker terminals is controlled by setting the amplifier’s output level and digital volume control (DVC). A separate DVC is provided for PDM (available from the PDM input pins) and PCM (available from the TDM ports pins) playback paths.

Amplifier output level settings are presented in dBV (dB relative to 1 V_{rms}) with a full scale digital audio input (0 dBFS) and the digital volume control set to 0 dB. It should be noted that these levels may not be achievable because of analog clipping in the amplifier, so they should be used to convey gain only. 表 8-37 below shows analog gain settings that can be programmed via the *AMP_LEVEL[4:0]* register bits.

表 8-37. Amplifier Output Level Settings

AMP_LEVEL[4:0]	FULL SCALE OUTPUT	
	dBV	V_{PEAK} (V)
0x00	11.0	5.02
0x01	11.5	5.32

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表 8-37. Amplifier Output Level Settings (continued)

AMP_LEVEL[4:0]	FULL SCALE OUTPUT	
	dBV	V_{PEAK} (V)
0x02	12.0	5.63
0x03	12.5	5.96
0x04	13.0	6.32
0x05	13.5	6.69
0x06	14.0	7.09
0x07	14.5	7.51
0x08	15.0	7.95
0x09	15.5	8.42
0x0A	16.0	8.92
0x0B	16.5	9.45
0x0C	17.0	10.0
0x0D	17.5	10.6
0x0E	18.0	11.2
0x0F	18.5	11.9
0x10	19.0 (default)	12.6 (default)
0x11	19.5	13.4
0x12	20.0	14.1
0x13	20.5	14.98
0x14	21.0	15.87
0x15 – 0x1F	Reserved	Reserved

方程式 1 calculates the amplifiers output voltage.

$$V_{AMP} = Input + A_{dvc} + A_{AMP} \ \ dBV \quad (1)$$

where

- V_{AMP} is the amplifier output voltage in dBV
- Input is the digital input amplitude in dB with respect to 0 dBFS
- A_{dvc} is the digital volume control setting, 0 dB to -100 dB in 0.5 dB steps
- A_{AMP} is the amplifier output level setting in dBV

The digital volume control (DVC) is independently configurable for PCM and PDM streams from 0 dB to -100 dB in 0.5 dB steps by setting the *DVC_PCM[7:0]* and *PVC_PDM[7:0]* register bits respectively. Settings greater than 0xC8 are interpreted as mute. When a change in digital volume control occurs, the device ramps the volume to the new setting based on the *DVC_RATE[1:0]* register bits. If DVC_RATE[1:0] is set to 2'b11, volume ramping is disabled. This can be used to speed up startup, shutdown and digital volume changes when volume ramping is handled by the system master.

表 8-38. PCM Digital Volume Control

DVC_PCM[7:0]	Volume (dB)
0x00	0 (default)

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表 8-38. PCM Digital Volume Control (continued)

DVC_PCM[7:0]	Volume (dB)
0x01	-0.5
0x02	-1
...	...
0xC8	-100
0xC9 – 0xFF	Mute

表 8-39. PDM Digital Volume Control

DVC_PDM[7:0]	Volume (dB)
0x00	0 (default)
0x01	-0.5
0x02	-1
...	...
0xC8	-100
0xC9 – 0xFF	Mute

表 8-40. Digital Volume Ramp Rate

DVC_RAMP[1:0]	Ramp Rate
00	0.5 dB per 1 Sample (default)
01	0.5 dB per 4 Samples
10	0.5 dB per 8 Samples
11	Volume Ramping Disabled

The Class-D amplifier uses a closed-loop architecture, so the gain does not depend on VBAT. The approximate threshold for the onset of analog clipping is calculated in 方程式 2.

$$V_{PK(max,preclip)} = VBAT \times \left(\frac{R_L}{R_{FET(tot)} + R_{interconnect} + R_L} \right) V \quad (2)$$

where

- $V_{PK(max,preclip)}$ is the maximum peak unclipped output voltage in V
- VBAT is the power supply voltage
- R_L is the speaker load in Ω
- $R_{interconnect}$ is the additional resistance in the PCB (such as cabling and filters) in Ω
- $R_{FET(on)}$ is the power stage total on resistance (HS FET+LS FET+Sense Resistor+bonding+packaging) in Ω

The effective on-resistance for this device (including HS+LS FET, Sense Resistor and bonding and packaging leads) is approximately 510 mΩ at room temperature. 表 8-41 shows approximate maximum unclipped peak output voltages at room temperature (excluding interconnect resistances).

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表 8-41. Approximate Maximum Unclipped Peak Output Voltage at Room Temperature

SUPPLY VOLTAGE VBAT (V)	MAXIMUM UNCLIPPED PEAK VOLTAGE V_{PK} (V)	
	R_L = 4 Ω	R_L = 8 Ω
8.4	7.45	7.90
12.6	11.18	11.84

8.4.3.3 Audio Playback Selection

Audio playback can be sourced from either PCM (through the TDM) or PDM (through the PDMD PDM Inputs) input sources through the *PB_SRC* register bit. The *PB_PDM_SRC* register bit determines the source of the PDM source.

表 8-42. Audio Playback Source

PB_SRC	Source
0	PCM (default)
1	PDM

表 8-43. PDM Playback Source

PB_PDM_SRC	Source
0	PDM input pin defined by PDM_MAP register bit (default)
1	Reserved

8.4.3.4 Battery Tracking Limiter with Brown Out Prevention

The TAS2770 monitors battery voltage (VBAT) and the audio signal to automatically decrease gain when the audio signal peaks exceed a programmable threshold. This helps prevent clipping and extends playback time through end of charge battery conditions. The limiter threshold can be configured to track VBAT below a programmable inflection point with a programmable slope. A minimum threshold sets the limit of threshold reduction from VBAT tracking. Configurable attack rate, hold time and release rate are provided to shape the dynamic response of the limiter (through the *LIM_ATK_RT[2:0], LIM_HLD_TM[2:0] and LIM_RLS_RT[2:0]* register bits).

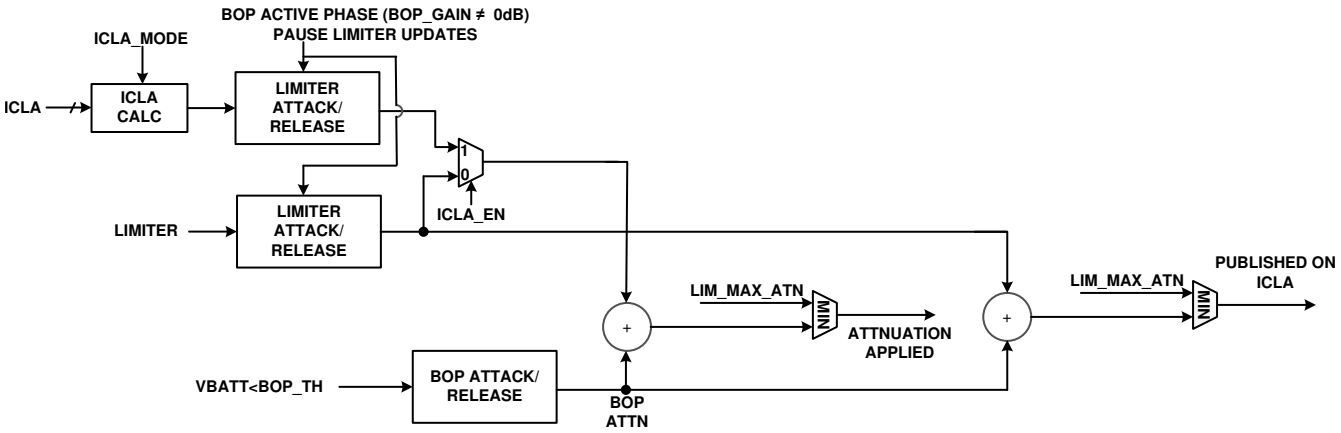


图 8-11. Limiter and Brown Out Prevention Interaction Diagram

A Brown Out Prevention (BOP) feature provides a priority input to the limiter to provide very fast response to transient dips in VBAT at end of charge conditions that can cause system level brown out. When VBAT dips below the BOP threshold, the limiter begins reducing gain with an attack latency of less than 10 µs and a

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configurable attack rate. When VBAT rises above the BOP threshold, the limiter will begin to release after the programmed hold time.

The limiter is enabled by setting the *LIM_EN* bit register bit high.

表 8-44. Battery Tracking Limiter Enable

LIM_EN	Value
0	Disabled (default)
1	Enabled

The limiter has configurable attack rate, hold time and release rate, which are available through the *LIM_ATK_RT[2:0]*, *LIM_HLD_TM[2:0]* and *LIM_RLS_RT[2:0]* register bits respectively. The limiter attack and release step size can be set by configuring the *LIM_ATK_ST[1:0]* and *LIM_RLS_ST[1:0]* register bits respectively.

表 8-45. Limiter Attack Rate

LIM_ATK_RT[2:0]	Attack Rate (µs)
0x0	5
0x1	10
0x2	20 (default)
0x3	40
0x4	80
0x5	160
0x6	320
0x7	640

表 8-46. Limiter Hold Time

LIM_HLD_TM[2:0]	Hold Time (ms)
0x0	0
0x1	10
0x2	25
0x3	50
0x4	100
0x5	250
0x6	500 (default)
0x7	1000

表 8-47. Limiter Release Rate

LIM_RLS_RT[2:0]	Release Time (ms)
0x0	10
0x1	50
0x2	100
0x3	250
0x4	500

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表 8-47. Limiter Release Rate (continued)

LIM_RLS_RT[2:0]	Release Time (ms)
0x5	750
0x6	1000 (default)
0x7	1500

表 8-48. Limiter Attack Step Size

LIM_ATK_ST[1:0]	Step Size (dB)
00	0.25
01	0.5 (default)
10	1
11	2

表 8-49. Limiter Release Step Size

LIM_RLS_ST[1:0]	Step Size (dB)
00	0.25
01	0.5 (default)
10	1
11	2

A maximum level of attenuation applied by the limiter and brown out prevention feature is configurable through the *LIM_MAX_ATN[4:0]* register bits. This attenuation limit is shared between the features. For instance, if the maximum attenuation is set to 6 dB and the limiter has reduced gain by 4 dB, the brown out prevention feature will only be able to reduce the gain further by another 2 dB. If the limiter or brown out prevention feature is attacking and it reaches the maximum attenuation, gain will not be reduced any further.

表 8-50. Limiter Max Attenuation

LIM_MAX_ATN[4:0]	Attenuation (dB)
0x00	1
0x01	1.5
. . .	...
0x10	9 (default)
. . .	...
0x1E	16
0x1F	16.5

The limiter begins reducing gain when the output signal level is greater than the limiter threshold. The limiter can be configured to track VBAT below a programmable inflection point with a minimum threshold value. 图 8-12 below shows the limiter configured to limit to a constant level regardless of VBAT level. To achieve this behavior, set the limiter maximum threshold to the desired level through the *LIM_TH_MAX[6:0]* register bits. Set the limiter inflection point (through the *LIM_INF_PT[6:0]* register bits) below the minimum allowable VBAT setting. The limiter minimum threshold register bits (*LIM_TH_MIN[6:0]*) do not impact limiter behavior in this use case.

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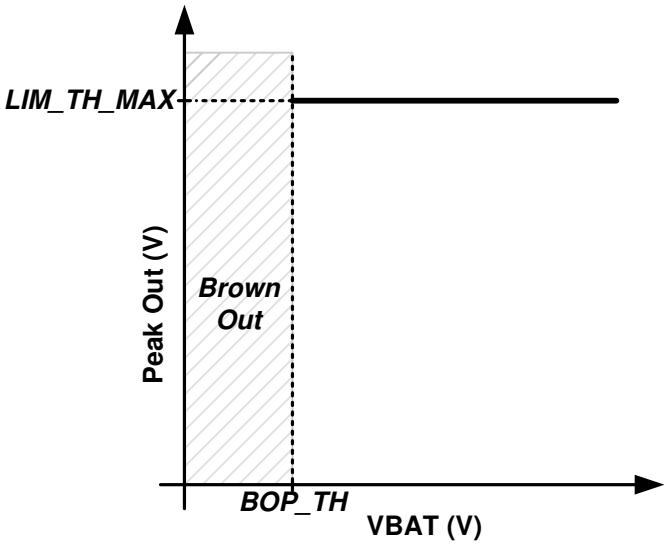


图 8-12. Limiter with Fixed Threshold

表 8-51. Limiter Maximum Threshold

LIM_TH_MAX[6:0]	Threshold (V)
0x00	2
0x01	2.1
...	...
0x6E	13 (default)
...	...
0x7E	14.6
0x7F	14.7

表 8-52. Limiter Minimum Threshold

LIM_TH_MIN[6:0]	Threshold (V)
0x00	2
0x01	2.1
...	...
0x1E	5 (default)
...	...
0x7E	14.6
0x7F	14.7

表 8-53. Limiter Inflection Point

LIM_INF_PT[6:0]	Inflection Point (V)
0x00	2
0x01	2.1
...	...
0x58	10.8 (default)

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表 8-53. Limiter Inflection Point (continued)

LIM_INF_PT[6:0]	Inflection Point (V)
...	...
0x7E	14.6
0x7F	14.7

图 8-13 shows how to configure the limiter to track VBAT below a threshold without a minimum threshold. Set the *LIM_TH_MAX[6:0]* register bits to the desired threshold and *LIM_INF_PT[6:0]* register bits to the desired inflection point where the limiter will begin reducing the threshold with VBAT. The *LIM_SLOPE[1:0]* register bits can be used to change the slope of the limiter tracking with VBAT. The default value of 1 V/V will reduce the threshold 1 V for every 1 V of drop in VBAT. More aggressive tracking slopes can be programmed if desired. Program the *LIM_TH_MIN[6:0]* below the minimum VBAT to prevent the limiter from having a minimum threshold reduction when tracking VBAT.

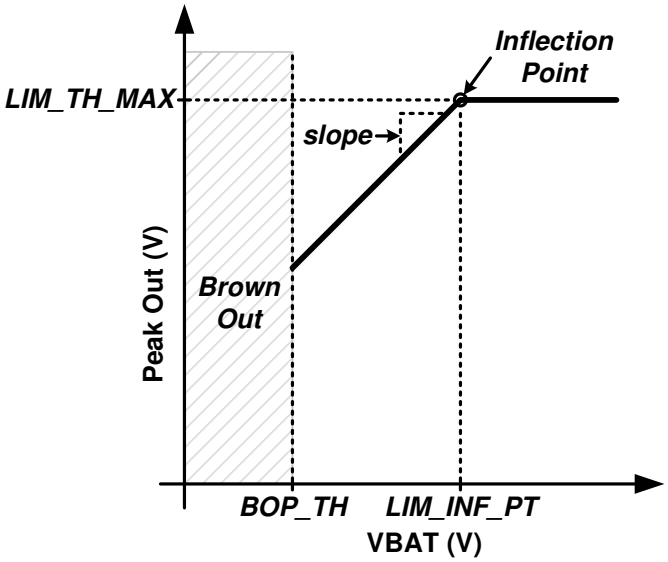


图 8-13. Limiter with Inflection Point

表 8-54. Limiter VBAT Tracking Slope

LIM_SLOPE[1:0]	Slope (V/V)
00	1 (default)
01	1.5
10	2
11	4

To achieve a limiter that tracks VBAT below a threshold, configure the limiter as explained in the previous example, except program the *LIM_TH_MIN[6:0]* register bits to the desired minimum threshold. This is shown in 图 8-14 below.

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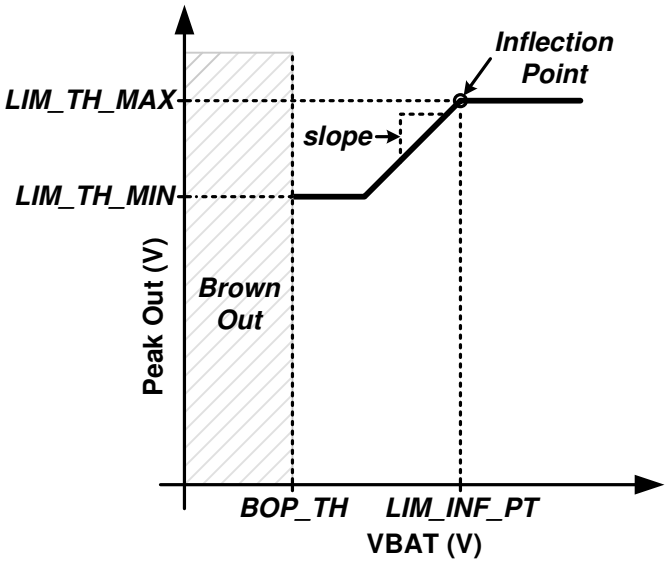


图 8-14. Limiter with Inflection Point and Minimum Threshold

The TAS2770 also employs a Brown Out Prevention (BOP) feature that serves as a low latency priority input to the limiter engine that begins attacking within 10 µs of VBAT dipping below the programmed BOP threshold. This feature can be enabled by setting the *BOP_EN* register bit high. It should be noted that the BOP feature is independent of the limiter and will function if enabled even if the limiter is disabled. The BOP threshold is configured by setting the threshold with register bits *BOP_TH[7:0]*.

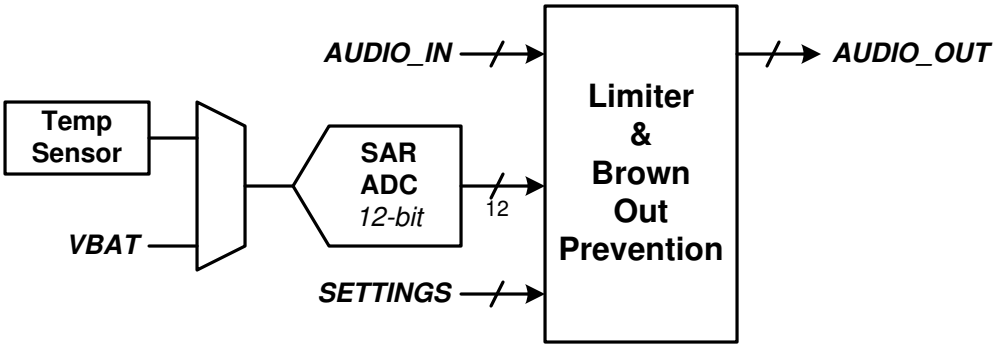


图 8-15. Limiter Block Diagram

表 8-55. Brown Out Prevention Enable

BOP_EN	Value
0	Disabled
1	Enabled (default)

表 8-56. Brown Out Prevention Threshold

BOP_TH[7:0]	Threshold (V)
0x00	4.5
0x01	4.525
0x02	4.55
. . .	...
0x14	5.0 (default)

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表 8-56. Brown Out Prevention Threshold (continued)

BOP_TH[7:0]	Threshold (V)
. . .	...
0xFE	10.85
0xFF	10.875

The BOP feature has a separate attack rate, attack step size and hold time from the battery tracking limiter (register bits *BOP_ATK_RT[2:0]*, *BOP_ATK_ST[1:0]* and *BOP_HLD_TM[2:0]* respectively). The BOP feature uses the *LIM_RLS_RT[2:0]* register setting to release after a brown out event.

表 8-57. Brown Out Prevention Attack Rate

BOP_ATK_RT[2:0]	Attack Rate (μs)
0x0	5
0x1	10
0x2	20 (default)
0x3	40
0x4	80
0x5	160
0x6	320
0x7	640

表 8-58. Brown Out Prevention Attack Step Size

BOP_ATK_ST[1:0]	Step Size (dB)
00	0.5
01	1 (default)
10	1.5
11	2

表 8-59. Brown Out Prevention Hold Time

BOP_HLD_TM[2:0]	Hold Time (ms)
0x0	0
0x1	10
0x2	25
0x3	50
0x4	100
0x5	250
0x6	500 (default)
0x7	1000

The TAS2770 can also shutdown the device when a brown out event occurs if the *BOP_SHUTDOWN* register bit is set high. For the device to continue playing audio again, the device must transition through a SW/HW shutdown state. Setting the *BOP_INF_HLD* high will cause the limiter to stay in the hold state (i.e. never release)

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after a cleared brown out event until either the device transitions through a mute or SW/HW shutdown state or the register bit *BOP_HLD_CLR* is written to a high value (which will cause the device to exit the hold state and begin releasing). This bit is self clearing and will always readback low. 图 8-16 below illustrates the entering and exiting from a brown out event.

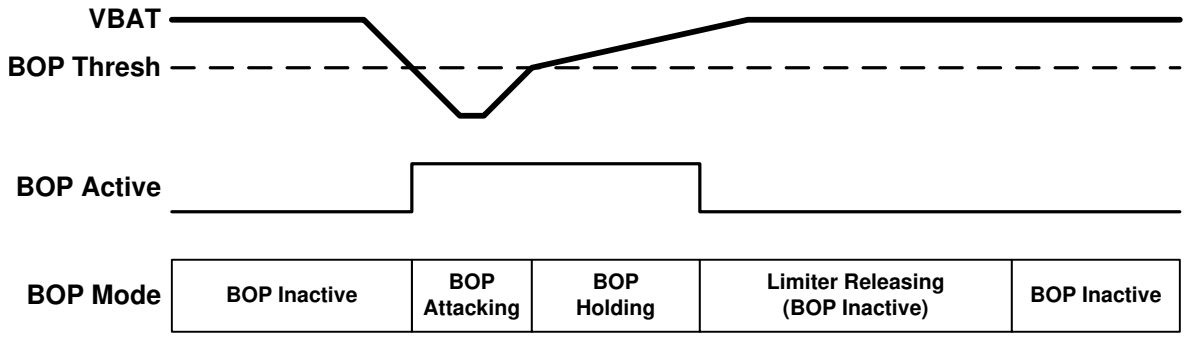


图 8-16. Brown Out Prevention Event

表 8-60. Shutdown on Brown Out Event

BOP_SHUTDOWN	Value
0	Don't Shutdown (default)
1	Shutdown

表 8-61. Infinite Hold on Brown Out Event

BOP_INF_HLD	Value
0	Use *BOP_HLD_TM* after Brown Out event (default)
1	Do not release until *BOP_HLD_CLR* is asserted high

表 8-62. BOP Infinite Hold Clear

BOP_HLD_CLR	Value
0	Don't clear (default)
1	Clear event (self clearing)

8.4.3.5 Inter Chip Limiter Alignment

8.4.3.5.1 TDM Mode

The TAS2770 supports alignment of limiter (including brown out prevention) dynamics across devices that share the same TDM bus. This ensures consistent gain between channels during limiting or brown out events since these dynamics are dependent on audio content, which can vary across channels. Each device can be configured to align to a specified number of other devices, which allows creation of groupings of devices that align only to each other.

Limiter activity is communicated through the limiter gain reduction parameter that can be optionally transmitted by each device on SDOUT in an 8-bit time slot. Gain reduction should be transmitted in adjacent time slots for all devices that are to be aligned beginning with the first slot that is specified by the *ICLA_SLOT[5:0]* register bits. The order of the devices is not important as long as they are adjacent. The time slot for limiter gain reduction is configured by the *GAIN_SLOT[5:0]* register bits and enabled by the *GAIN_TX* register bit.

The *ICLA_SEN[7:0]* register bits specify which time slots should be listened to for gain alignment. This allows any number of devices between two and eight to be grouped together. At least two of these bits should be enabled for alignment to take place. The *ICLA_USE_MAX* register bit determines whether alignment is based on the maximum or minimum gain reduction value from the group of enabled devices.

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To enable the inter chip limiter alignment feature, the *ICLA_EN* register bit should be asserted high and all devices should be configured with identical limiter and brown out prevention settings. Limiter gain reduction transmission should be enabled on all devices as described above.

表 8-63. Inter Chip Limiter Alignment

ICLA_EN	Value
0	Disabled (default)
1	Enabled

表 8-64. ICLA Alignment Configuration

ICLA_MODE	Value
00	Use the minimum gain reduction of the ICLA group including 0dB (default)
01	Use the maximum gain reduction of the ICLA group
10	Use the minimum gain reduction of the ICLA group that is non-0dB
11	Reserved

表 8-65. Inter Chip Limiter Alignment Starting Time Slot

ICLA_SLOT[5:0]	Starting Time Slot
0x00	Time Slot 0 (default)
0x01	Time Slot 1
0x02	Time Slot 2
...	...
0x3F	Time Slot 63

表 8-66. Inter Chip Limiter Alignment Time Slot Enable

Register Bit	Description	Bit Value	State
ICLA_SEN[0]	Time Slot = *ICLA_SLOT[5:0]*. When enabled, the limiter will include this time slot in the alignment group.	0	Disabled (default)
		1	Enabled
ICLA_SEN[1]	Time Slot = *ICLA_SLOT[5:0]* + 1. When enabled, the limiter will include this time slot in the alignment group.	0	Disabled (default)
		1	Enabled
ICLA_SEN[2]	Time Slot = *ICLA_SLOT[5:0]* + 2. When enabled, the limiter will include this time slot in the alignment group.	0	Disabled (default)
		1	Enabled
ICLA_SEN[3]	Time Slot = *ICLA_SLOT[5:0]* + 3. When enabled, the limiter will include this time slot in the alignment group.	0	Disabled (default)
		1	Enabled
ICLA_SEN[4]	Time Slot = *ICLA_SLOT[5:0]* + 4. When enabled, the limiter will include this time slot in the alignment group.	0	Disabled (default)
		1	Enabled
ICLA_SEN[5]	Time Slot = *ICLA_SLOT[5:0]* + 5. When enabled, the limiter will include this time slot in the alignment group.	0	Disabled (default)
		1	Enabled
ICLA_SEN[6]	Time Slot = *ICLA_SLOT[5:0]* + 6. When enabled, the limiter will include this time slot in the alignment group.	0	Disabled (default)
		1	Enabled

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表 8-66. Inter Chip Limiter Alignment Time Slot Enable (continued)

Register Bit	Description	Bit Value	State
ICLA_SEN[7]	Time Slot = *ICLA_SLOT[5:0]* + 7. When enabled, the limiter will include this time slot in the alignment group.	0	Disabled (default)
		1	Enabled

8.4.3.6 Class-D Settings

The TAS2770 Class-D amplifier supports spread spectrum PWM modulation, which can be enabled by setting the *AMP_SS* register bit high. This can help reduce EMI in some systems.

表 8-67. Low EMI Spread Spectrum Mode

AMP_SS	Spread Spectrum
0	Disabled
1	Enabled (default)

By default the Class-D amplifier's switching frequency is based on the device's trimmed internal oscillator. To synchronize switching to the audio sample rate, set the *CLASSD_SYNC* register bit high. When the Class-D is synchronized to the audio sample rate, the *RATE_RAMP* register bit must be set based whether the audio sample rate is based on a 44.1 kHz or 48 kHz frequency. For 44.1, 88.2 and 176.4 kHz, set this bit high. for 48, 96 and 192 kHz, set this bit low. This ensures that the internal ramp generator has the appropriate slope.

表 8-68. Class-D Synchronization Mode

CLASSD_SYNC	Synchronization Mode
0	Not synchronized to audio clocks (default)
1	Synchronized to audio clocks

表 8-69. Sample Rate for Class-D Synchronized Mode

RAMP_RATE	Playback Sample Rate
0	48, 96 and 192 kHz (default)
1	44.1, 88.2 and 174.6 kHz

8.4.4 SAR ADC

A 12-bit SAR ADC monitors VBAT voltage and die temperature. The results of these conversions are available through the register readback (*VBAT_CNV[11:0]* and *TMP_CNV[7:0]* registers respectively). VBAT voltage conversions are also used by the limiter and brown out prevention features.

The ADC runs at a fixed 667 kHz sample rate (1.5 µs per conversion) interleaved between VBAT voltage and die temperature measurements. This gives an effective sample rate of 333 kHz (3 µs per conversion) with a latency of 1 sample (1.5 µs). This gives a worst case measurement latency of 4.5 µs. Actual VBAT voltage is calculated by dividing the *VBAT_CNV[11:0]* register by 256. Actual die temperature is calculated by dividing the *TMP_CNV[11:0]* register by 16 and then subtracting 93.

表 8-70. ADC VBAT Voltage Conversion

VBAT_CNV[11:0]	VBAT Voltage (V)
0x000	0 V
0x001	0.0039 V
. . .	...
0xC9A	12.6016 V

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表 8-70. ADC VBAT Voltage Conversion (continued)

VBAT_CNV[11:0]	VBAT Voltage (V)
. . .	...
0xE00	14.0000 V

表 8-71. ADC Die Temperature Conversion

TMP_CNV[11:0]	Die Temperature (°C)
0x000	-93 °C
0x001	-92.9375 °C
. . .	...
0x760	25 °C
. . .	...
0xFFE	162.8750 °C
0xFFF	162.9375 °C

8.4.5 IV Sense

The TAS2770 provides speaker voltage and current sense for real time monitoring of loudspeaker behavior. The VSNS_P and VSNS_N pins should be connected after any ferrite bead filter (or directly to the OUT_P and OUT_N connections if no EMI filter is used). The V-Sense connections eliminate IR drop error due to packaging, PCB interconnect or ferrite bead filter resistance. It should be noted that any interconnect resistance after the V-Sense terminals will not be corrected for, so it is advised to connect the sense connections as close to the load as possible.

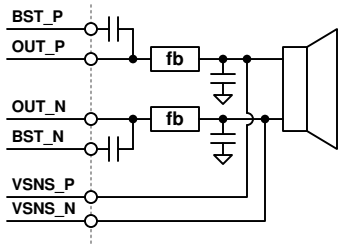


图 8-17. V-Sense Connections

I-Sense and V-Sense can be powered down by asserting the *ISNS_PD* and *VSNS_PD* register bits respectively. When powered down, the device will return null samples for the powered down block.

表 8-72. I-Sense Power Down

ISNS_PD	Setting
0	I-Sense is active (default)
1	I-Sense is powered down

表 8-73. V-Sense Power Down

VSNS_PD	Setting
0	V-Sense is active (default)
1	V-Sense is powered down

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8.4.6 Clocks and PLL

In TMD/I^{2}C Mode, the device operates from SBCLK. 表 8-74 and 表 8-75 below shows the valid SBCLK frequencies for each sample rate and SBCLK to FSYNC ratio (for 44.1 kHz and 48 kHz family frequencies respectively.

If the sample rate is properly configured through the *SAMP_RATE[1:0]* bits, no additional configuration is required as long as the SBCLK to FSYNC ratio is valid. The device will detect improper SBCLK frequencies and SBCLK to FSYNC ratios and volume ramp down the playback path to minimize audible artifacts.

表 8-74. Supported SBCLK Frequencies (48 kHz based sample rates)

Sample Rate (kHz)	SBCLK to FSYNC Ratio						
	64	96	128	192	256	384	512
48 kHz	3.072 MHz	4.608 MHz	6.144 MHz	9.216 MHz	12.288 MHz	18.432 MHz	24.576 MHz
96 kHz	6.144 MHz	9.216 MHz	12.288 MHz	18.432 MHz	24.576 MHz	-	-
192 kHz	12.288 MHz	18.432 MHz	24.576 MHz	-	-	-	-

表 8-75. Supported SBCLK Frequencies (44.1 kHz based sample rates)

Sample Rate (kHz)	SBCLK to FSYNC Ratio						
	64	96	128	192	256	384	512
44.1 kHz	2.8224 MHz	4.2336 MHz	5.6448 MHz	8.4672 MHz	11.2896 MHz	16.9344 MHz	22.5792 MHz
88.2 kHz	5.6448 MHz	8.4672 MHz	11.2896 MHz	16.9344 MHz	22.5792 MHz	-	-
176.4 kHz	11.2896 MHz	16.9344 MHz	22.5792 MHz	-	-	-	-

8.4.7 Operational Modes

8.4.7.1 Hardware Shutdown

The device enters Hardware Shutdown mode if the SDZ pin is asserted low. In Hardware Shutdown mode, the device consumes the minimum quiescent current from AVDD and VBAT supplies. All registers loose state in this mode and communication is disabled (through the I^{2}C).

If SDZ is asserted low while audio is playing, the device will ramp down volume on the audio, stop the Class-D switching, power down analog and digital blocks and finally put the device into Hardware Shutdown mode.

When SDZ is released, the device will sample the MODE pin and enter the selected operational mode (i.e. either TDM/I^{2}C).

8.4.7.2 Software Shutdown

Software Shutdown mode powers down all analog blocks required to playback audio, but does not cause the device to loose register state. Software Shutdown is enabled by asserting the *MODE[1:0]* register bits to 2'b10. If audio is playing when Software Shutdown is asserted, the Class-D will volume ramp down before shutting down. When deasserted, the Class-D will begin switching and volume ramp back to the programmed digital volume setting.

8.4.7.3 Mute

The TAS2770 will volume ramp down the Class-D amplifier to a mute state by setting the *MODE[1:0]* register bits to 2'b01. During mute the Class-D still switches, but transmits no audio content. If mute is deasserted, the device will volume ramp back to the programmed digital volume setting.

8.4.7.4 Active

In Active Mode the Class-D switches and plays back audio. Speaker voltage and current sensing are operational if enabled. PDM inputis also active if enabled. Set the *MODE[1:0]* register bits to 2'b00 to enter active mode.

8.4.7.5 Mode Control and Software Reset

The TAS2770 mode can be configured by writing the *MODE[1:0]* bits.

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表 8-76. Mode Control

MODE[1:0]	Setting
00	Active
01	Mute
10	Software Shutdown (default)
11	Reserved

A software reset can be accomplished by asserting the *SW_RESET* bit, which is self clearing. This will restore all registers to their default values.

表 8-77. Software Reset

SW_RESET	Setting
0	Don't reset (default)
1	Reset

8.4.8 Faults and Status

During the power-up sequence, the power-on-reset circuit (POR) monitoring the AVDD pin will hold the device in reset (including all configuration registers) until the supply is valid. The device will not exit hardware shutdown until AVDD is valid and the SDZ pin is released. Once SDZ is released, the digital core voltage regulator will power up, enabling detection of the operational mode. If AVDD dips below the POR threshold, the device will immediately be forced into a reset state.

The device also monitors the VBAT supply and holds the analog core in power down if the supply is below the UVLO threshold or above the OVLO threshold. If the TAS2770 is in active operation and a UVLO or OVLO fault occurs, the analog supplies will immediately power down to protect the device. These faults are latching and require a transition through HW/SW shutdown to clear the fault. The live and latched registers will report UVLO/OVLO faults.

The device transitions into software shutdown mode if it detects any faults with the TDM clocks such as:

- Invalid SBCLK to FSYNC ratio
- Invalid FSYNC frequency
- Halting of SBCLK or FSYNC clocks

Upon detection of a TDM clock error, the device transitions into software shutdown mode as quickly as possible to limit the possibility of audio artifacts. Once all TDM clock errors are resolved, the device volume ramps back to its previous playback state. During a TDM clock error, the IRQZ pin will assert low if the clock error interrupt mask register bit is set low (*INT_MASK[2]*). The clock fault is also available for readback in the live or latched fault status registers (*INT_LIVE[2]* and *INT_LTCH[2]*). Reading the latched fault status register (*INT_LTCH[7:0]*) clears the register.

The TAS2770 also monitors die temperature and Class-D load current and will enter software shutdown mode if either of these exceed safe values. As with the TDM clock error, the IRQZ pin will assert low for these faults if the appropriate fault interrupt mask register bit is set low (*INT_MASK[0]* for over temp and *INT_MASK[1]* for over current). The fault status can also be monitored in the live and latched fault registers as with the TDM clock error.

Die over temp and Class-D over current errors can either be latching (i.e. the device will enter software shutdown until a HW/SW shutdown sequence is applied) or they can be configured to automatically retry after a prescribed time. This behavior can be configured in the *OTE_RETRY* and OCE_RETRY register bits (for over temp and over current respectively). Even in latched mode, the Class-D will not attempt to retry after an over temp or over current error until the retry time period (1.5s) has elapsed. This prevents applying repeated stress to the device in a rapid fashion that could lead to device damage. If the device has been cycled through SW/HW shutdown, the device will only begin to operate after the retry time period.

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The status registers (and IRQZ pin if enabled through the status mask register) also indicates limiter behavior including when the limiter is activity, when VBAT is below the inflection point, when maximum attenuation has been applied, when the limiter is in infinite hold and when the limiter has muted the audio.

The IRQZ pin is an open drain output that asserts low during unmasked fault conditions and therefore must be pulled up with a resistor to IOVDD. An internal pull up resistor is provided in the TAS2770 and can be accessed by setting the *IRQZ_PU* register bit high. 图 8-18 below highlights the IRQZ pin circuit.

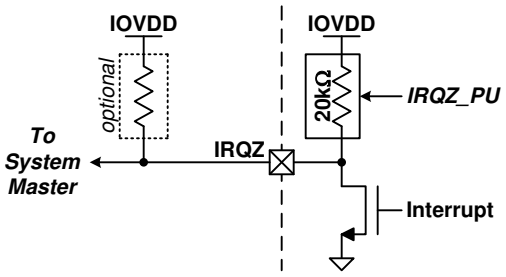


图 8-18. IRQZ Pin

表 8-78. Fault Interrupt Mask

INT_MASK[10:0] Bit	Interrupt	Default (1 = Mask)
0	Over Temp Error	0
1	Over Current Error	0
2	TDM Clock Error	1
3	Limiter Active	1
4	VBAT < Inf Point	1
5	Limiter Max Atten	1
6	Limiter Inf Hold	1
7	Limiter Mute	1
8	PDM Clock Error	1
9	VBAT Brown Out	1
10	VBAT UVLO	1
11	VBAT OVLO	1

表 8-79. IRQZ Internal Pull Up Enable

IRQZ_PU	State
0	Disabled (default)
1	Enabled

表 8-80. IRQZ Interrupt Configuration

IRQZ_PIN_CFG[1:0]	Value
00	IRQZ will assert on any unmasked live interrupts
01	IRQZ will assert on any unmasked latched interrupts (default)
10	Reserved

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表 8-80. IRQZ Interrupt Configuration (continued)

IRQZ_PIN_CFG[1:0]	Value
11	Reserved

8.4.9 Power Sequencing Requirements

AVDD and IOVDD pins should be connected to the same 1.8 V supply domain. There are no other power sequencing requirements for order of rate of ramping up or down.

8.4.10 Digital Input Pull Downs

Each digital input and IO has an optional weak pull down to prevent the pin from floating. Pull downs are not enabled during HW shutdown.

表 8-81. Digital Input Pull Down Enables

Register Bit	Description	Bit Value	State
DIN_PD[0]	Weak pull down for PDMCK.	0	Disabled
		1	Enabled (default)
DIN_PD[2]	Weak pull down for PDMD.	0	Disabled
		1	Enabled (default)
DIN_PD[5]	Weak pull down for FSYNC.	0	Disabled
		1	Enabled (default)
DIN_PD[6]	Weak pull down for SDIN.	0	Disabled
		1	Enabled (default)
DIN_PD[7]	Weak pull down for SDOUT.	0	Disabled
		1	Enabled (default)

8.5 Register Maps

8.5.1 Register Summary Table Book=0x00 Page=0x00

Addr	Register	Description	Section
0x00	PAGE	Device Page	节 8.5.2.1
0x01	SW_RESET	Software Reset	节 8.5.2.2
0x02	PWR_CTL	Power Control	节 8.5.2.3
0x03	PB_CFG0	Playback Configuration 0	节 8.5.2.4
0x04	PB_CFG1	Playback Configuration 1	节 8.5.2.5
0x05	PB_CFG2	Playback Configuration 2	节 8.5.2.6
0x06	PB_CFG3	Playback Configuration 3	节 8.5.2.7
0x07	MISC_CFG	Misc Configuration	节 8.5.2.8
0x08	PDM_CFG0	PDM Input Register 0	节 8.5.2.9
0x09	PDM_CFG1	PDM Configuration 1	节 8.5.2.10
0x0A	TDM_CFG0	TDM Configuration 0	节 8.5.2.11
0x0B	TDM_CFG1	TDM Configuration 1	节 8.5.2.12
0x0C	TDM_CFG2	TDM Configuration 2	节 8.5.2.13
0x0D	TDM_CFG3	TDM Configuration 3	节 8.5.2.14
0x0E	TDM_CFG4	TDM Configuration 4	节 8.5.2.15
0x0F	TDM_CFG5	TDM Configuration 5	节 8.5.2.16
0x10	TDM_CFG6	TDM Configuration 6	节 8.5.2.17
0x11	TDM_CFG7	TDM Configuration 7	节 8.5.2.18

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0x12	TDM_CFG8	TDM Configuration 8	节 8.5.2.19
0x13	TDM_CFG9	TDM Configuration 9	节 8.5.2.20
0x14	TDM_CFG10	TDM Configuration 10	节 8.5.2.21
0x15	LIM_CFG0	Limiter Configuration 0	节 8.5.2.22
0x16	LIM_CFG1	Limiter Configuration 1	节 8.5.2.23
0x17	LIM_CFG2	Limiter Configuration 2	节 8.5.2.24
0x18	LIM_CFG3	Limiter Configuration 3	节 8.5.2.25
0x19	LIM_CFG4	Limiter Configuration 4	节 8.5.2.26
0x1A	LIM_CFG5	Limiter Configuration 5	节 8.5.2.27
0x1B	BOP_CFG0	Brown Out Prevention 0	节 8.5.2.28
0x1C	BOP_CFG1	Brown Out Prevention 1	节 8.5.2.29
0x1D	BOP_CFG2	Brown Out Prevention 2	节 8.5.2.30
0x1E	ICLA_CFG0	Inter Chip Limiter Alignment 0	节 8.5.2.31
0x1F	ICLA_CFG1	Inter Chip Limiter Alignment 1	节 8.5.2.32
0x20	INT_MASK0	Interrupt Mask 0	节 8.5.2.33
0x21	INT_MASK1	Interrupt Mask 1	节 8.5.2.34
0x22	INT_LIVE0	Live Interrupt Readback 0	节 8.5.2.35
0x23	INT_LIVE1	Live Interrupt Readback 1	节 8.5.2.36
0x24	INT_LTCH0	Latched Interrupt Readback 0	节 8.5.2.37
0x25	INT_LTCH1	Latched Interrupt Readback 1	节 8.5.2.38
0x27	VBAT_MSB	SAR ADC Conversion 0	节 8.5.2.40
0x28	VBAT_LSB	SAR ADC Conversion 1	节 8.5.2.41
0x29	TEMP_MSB	SAR ADC Conversion 2	节 8.5.2.42
0x2A	TEMP_LSB	SAR ADC Conversion 2	节 8.5.2.43
0x30	INT_CFG	Interrupt Configuration	节 8.5.2.44
0x31	DIN_PD	Digital Input Pin Pull Down	节 8.5.2.45
0x32	MISC_IRQ	Misc Configuration	节 8.5.2.46
0x3C	CLOCK_CFG	Clock Configuration	节 8.5.2.47
0x77	TDM_DET	TDM Clock detection monitor	节 8.5.2.48
0x7D	REV_ID	Revision and PG ID	节 8.5.2.49
0x7E	I2C_CKSUM	I2C Checksum	节 8.5.2.50
0x7F	BOOK	Device Book	节 8.5.2.51

8.5.2 Register Maps

8.5.2.1 PAGE (book=0x00 page=0x00 address=0x00) [reset=0h]

The device's memory map is divided into pages and books. This register sets the page.

图 8-19. PAGE Register Address: 0x00

7	6	5	4	3	2	1	0
PAGE[7:0]							
RW-0h							

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-82. Device Page Field Descriptions

Bit	Field	Type	Reset	Description
7-0	PAGE[7:0]	RW	0h	Sets the device page. 00h = Page 0 01h = Page 1 ... FFh = Page 255

8.5.2.2 SW_RESET (book=0x00 page=0x00 address=0x01) [reset=0h]

Asserting Software Reset will place all register values in their default POR (Power on Reset) state.

图 8-20. SW_RESET Register Address: 0x01

7	6	5	4	3	2	1	0
Reserved							SW_RESET
RW-0h							RW-0h

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-83. Software Reset Field Descriptions

Bit	Field	Type	Reset	Description
7-1	Reserved	RW	0h	Reserved
0	SW_RESET	RW	0h	Software reset. Bit is self clearing. 0b = Don't reset 1b = Reset

8.5.2.3 PWR_CTL (book=0x00 page=0x00 address=0x02) [reset=Eh]

Sets device's mode of operation and power down of IV sense blocks.

图 8-21. PWR_CTL Register Address: 0x02

7	6	5	4	3	2	1	0
Reserved		Reserved	Reserved	ISNS_PD	VSNS_PD	MODE[1:0]	
RW-0h		RW-0h	RW-0h	RW-1h	RW-1h	RW-2h	

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-84. Power Control Field Descriptions

Bit	Field	Type	Reset	Description
7-6	Reserved	RW	0h	Reserved
5	Reserved	RW	0h	Reserved
4	Reserved	RW	0h	Reserved
3	ISNS_PD	RW	1h	Current sense power down. 0b = Current sense active 1b = Current sense is powered down
2	VSNS_PD	RW	1h	Voltage sense power down. 0b = voltage sense is active 1b = Voltage sense is powered down
1-0	MODE[1:0]	RW	2h	Device operational mode. 00b = Active 01b = Mute 10b = Software Shutdown 11b = Reserved

8.5.2.4 PB_CFG0 (book=0x00 page=0x00 address=0x03) [reset=10h]

Sets playback source, including PDM input and amplifier output level setting.

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图 8-22. PB_CFG0 Register Address: 0x03

7	6	5	4	3	2	1	0
PDM_MAP	PB_PDM_SRC	PB_SRC	AMP_LEVEL[4:0]				
RW-0h	RW-0h	RW-0h	RW-10h				

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-85. Playback Configuration 0 Field Descriptions

Bit	Field	Type	Reset	Description
7	PDM_MAP	RW	0h	PDM Pin Mapping 0b = PDMD1 for sensor input. 1b = PDMD1 for playback.
6	PB_PDM_SRC	RW	0h	PDM playback source. 0b = PDM input pin defined by PDM_MAP. 1b = Reserved.
5	PB_SRC	RW	0h	Playback source. 0b = PCM 1b = PDM
4-0	AMP_LEVEL[4:0]	RW	10h	Amplifier output level setting. 00h = 11.0 dBV (5.02 Vpk) 01h = 11.5 dBV (5.32 Vpk) 02h = 12.0 dBV (5.63 Vpk) 03h = 12.5 dBV (5.96 Vpk) 04h = 13.0 dBV (6.32 Vpk) 05h = 13.5 dBV (6.69 Vpk) 06h = 14.0 dBV (7.09 Vpk) 07h = 14.5 dBV (7.51 Vpk) 08h = 15.0 dBV (7.95 Vpk) 09h = 15.5 dBV (8.42 Vpk) 0Ah = 16.0 dBV (8.92 Vpk) 0Bh = 16.5 dBV (9.45 Vpk) 0Ch = 17.0 dBV (10.01 Vpk) 0Dh = 17.5 dBV (10.61 Vpk) 0Eh = 18.0 dBV (11.23 Vpk) 0Fh = 18.5 dBV (11.90 Vpk) 10h = 19.0 dBV (12.60 Vpk) 11h = 19.5 dBV (13.35 Vpk) 12h = 20.0 dBV (14.14 Vpk) 13h = 20.5 dBV (14.98 Vpk) 14h = 21.0 dBV (15.87 Vpk) 15h - 1Fh = Reserved

8.5.2.5 PB_CFG1 (book=0x00 page=0x00 address=0x04) [reset=1h]

Sets playback high pass filter corner (PCM playback only).

图 8-23. PB_CFG1 Register Address: 0x04

7	6	5	4	3	2	1	0
Reserved	Reserved	Reserved	Reserved	Reserved	HPF_FREQ[2:0]		
RW-0h	RW-0h	RW-0h	RW-0h	RW-0h	RW-1h		

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-86. Playback Configuration 1 Field Descriptions

Bit	Field	Type	Reset	Description
7	Reserved	RW	0h	Reserved
6	Reserved	RW	0h	Reserved
5	Reserved	RW	0h	Reserved
4	Reserved	RW	0h	Reserved

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表 8-86. Playback Configuration 1 Field Descriptions (continued)

Bit	Field	Type	Reset	Description
3	Reserved	RW	0h	Reserved
2-0	HPF_FREQ[2:0]	RW	1h	High Pass Filter Corner Frequency. 000b = Bypass 001b = 2 Hz 010b = 50 Hz 011b = 100 Hz 100b = 200 Hz 101b = 400 Hz 110b = 800 Hz 111b = Reserved

8.5.2.6 PB_CFG2 (book=0x00 page=0x00 address=0x05) [reset=0h]

Sets playback volume for PCM playback path.

图 8-24. PB_CFG2 Register Address: 0x05

7	6	5	4	3	2	1	0
DVC_PCM[7:0]							
RW-0h							

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-87. Playback Configuration 2 Field Descriptions

Bit	Field	Type	Reset	Description
7-0	DVC_PCM[7:0]	RW	0h	PCM digital volume control. 00h = 0 dB 01h = -0.5 dB 02h = -1 dB .... C7h = -99.5 dB C8h = -100dB C9h - FFh = Mute

8.5.2.7 PB_CFG3 (book=0x00 page=0x00 address=0x06) [reset=0h]

Sets playback volume for PDM playback path.

图 8-25. PB_CFG3 Register Address: 0x06

7	6	5	4	3	2	1	0
DVC_PDM[7:0]							
RW-0h							

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-88. Playback Configuration 3 Field Descriptions

Bit	Field	Type	Reset	Description
7-0	DVC_PDM[7:0]	RW	0h	PDM digital volume control. 00h = 0 dB 01h = -0.5 dB 02h = -1 dB .... C7h = -99.5 dB C8h = -100dB C9h - FFh = Mute

8.5.2.8 MISC_CFG (book=0x00 page=0x00 address=0x07) [reset=6h]

Sets DVC Ramp Rate, IRQZ pull up, amp spread spectrum and I-Sense current range.

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7	6	5	4	3	2	1	0
DVC_RAMP_RATE[1:0]		Reserved		IRQZ_PU	AMP_SS	Reserved	
RW-0h		RW-0h		RW-0h	RW-1h	RW-2h	

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-89. Misc Configuration Field Descriptions

Bit	Field	Type	Reset	Description
7-6	DVC_RAMP_RATE[1:0]	RW	0h	Digital volume control ramp rate. 00b = 0.5 dB per 1 sample 01b = 0.5 dB per 4 samples 10b = 0.5 dB per 8 samples 11b = Volume ramping disabled
5-4	Reserved	RW	0h	Reserved
3	IRQZ_PU	RW	0h	IRQZ internal pull up enable. 0b = Disabled 1b = Enabled
2	AMP_SS	RW	1h	Low EMI spread spectrum enable. 0b = Disabled 1b = Enabled
1-0	Reserved	RW	2h	Reserved

8.5.2.9 PDM_CFG0 (book=0x00 page=0x00 address=0x08) [reset=0h]

Sets Class-D sync mode and PDM sample rates.

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

图 8-26. PDM_CFG0 Register Address: 0x08

7	6	5	4	3	2	1	0
Reserved	CLASSD_SYNC	Reserved		PDM_RATE1[1:0]		Reserved	
RW-0h	RW-0h	RW-0h		RW-0h		RW-0h	

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-90. PDM Input Register 0 Field Descriptions

Bit	Field	Type	Reset	Description
7	Reserved	RW	0h	Reserved
6	CLASSD_SYNC	RW	0h	Class-D synchronization mode. 0b = Not synchronized to audio clocks 1b = Synchronized to audio clocks
5-4	Reserved	RW	0h	Reserved
3-2	PDM_RATE1[1:0]	RW	0h	PDMD1 input sample rate. 00b = 2.54 - 3.38 MHz 01b = 5.08 - 6.76 MHz 10b = Reserved 11b = Reserved
1-0	Reserved	RW	0h	Reserved

8.5.2.10 PDM_CFG1 (book=0x00 page=0x00 address=0x09) [reset=8h]

Sets PDM capture edge, master/slave, clock source and gating.

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

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图 8-27. PDM_CFG1 Register Address: 0x09

7	6	5	4	3	2	1	0
PDM_EDGE1	Reserved	PDM_SLV1	Reserved	PDM_CLK1	Reserved	PDM_GATE1	Reserved
RW-0h	RW-0h	RW-0h	RW-0h	RW-1h	RW-0h	RW-0h	RW-0h

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-91. PDM Configuration 1 Field Descriptions

Bit	Field	Type	Reset	Description
7	PDM_EDGE1	RW	0h	PDMD1 input capture edge. 0b = Rising 1b = Falling
6	Reserved	RW	0h	Reserved
5	PDM_SLV1	RW	0h	PDMD1 input master or slave. 0b = Slave 1b = Master
4	Reserved	RW	0h	Reserved
3	PDM_CLK1	RW	1h	PDMD1 clock select. 0b = GND 1b = PDMCK1
2	Reserved	RW	0h	Reserved
1	PDM_GATE1	RW	0h	PDMD1 clock gate. 0b = Gated Off 1b = Active
0	Reserved	RW	0h	Reserved

8.5.2.11 TDM_CFG0 (book=0x00 page=0x00 address=0x0A) [reset=7h]

Sets the TDM frame start, TDM sample rate, TDM auto rate detection and whether rate is based on 44.1 kHz or 48 kHz frequency.

图 8-28. TDM_CFG0 Register Address: 0x0A

7	6	5	4	3	2	1	0
Reserved		RATE_RAMP	AUTO_RATE	SAMP_RATE[2:0]			FRAME_START
RW-0h		RW-0h	RW-0h	RW-3h			RW-1h

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-92. TDM Configuration 0 Field Descriptions

Bit	Field	Type	Reset	Description
7-6	Reserved	RW	0h	Reserved
5	RATE_RAMP	RW	0h	Sample rate based on 44.1kHz or 48kHz when CLASSD_SYNC=1. 0b = 48kHz 1b = 44.1kHz
4	AUTO_RATE	RW	0h	Auto detection of TDM sample rate. 0b = Enabled 1b = Disabled
3-1	SAMP_RATE[2:0]	RW	3h	Sample rate of the TDM bus. 000b = Reserved 001b = Reserved 010b = Reserved 011b = 44.1/48 kHz 100b = 88.2/96 kHz 101b = 176.4/192 kHz 110b = Reserved 111b = Reserved

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表 8-92. TDM Configuration 0 Field Descriptions (continued)

Bit	Field	Type	Reset	Description
0	FRAME_START	RW	1h	TDM frame start polarity. 0b = Low to High on FSYNC 1b = High to Low on FSYNC

8.5.2.12 TDM_CFG1 (book=0x00 page=0x00 address=0x0B) [reset=2h]

Sets TDM RX justification, offset and capture edge.

图 8-29. TDM_CFG1 Register Address: 0x0B

7	6	5	4	3	2	1	0
Reserved	RX_JUSTIFY	RX_OFFSET[4:0]					RX_EDGE
RW-0h	RW-0h	RW-1h					RW-0h

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-93. TDM Configuration 1 Field Descriptions

Bit	Field	Type	Reset	Description
7	Reserved	RW	0h	Reserved
6	RX_JUSTIFY	RW	0h	TDM RX sample justification within the time slot. 0b = Left 1b = Right
5-1	RX_OFFSET[4:0]	RW	1h	TDM RX start of frame to time slot 0 offset (SBCLK cycles).
0	RX_EDGE	RW	0h	TDM RX capture clock polarity. 0b = Rising edge of SBCLK 1b = Falling edge of SBCLK

8.5.2.13 TDM_CFG2 (book=0x00 page=0x00 address=0x0C) [reset=Ah]

Sets TDM RX time slot select, word length and time slot length.

图 8-30. TDM_CFG2 Register Address: 0x0C

7	6	5	4	3	2	1	0
Reserved		RX_SCFG[1:0]		RX_WLEN[1:0]		RX_SLEN[1:0]	
RW-0h		RW-0h		RW-2h		RW-2h	

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-94. TDM Configuration 2 Field Descriptions

Bit	Field	Type	Reset	Description
7-6	Reserved	RW	0h	Reserved
5-4	RX_SCFG[1:0]	RW	0h	TDM RX time slot select config. 00b = Mono with time slot equal to I2C address offset 01b = Mono left channel 10b = Mono right channel 11b = Stereo downmix (L+R)/2
3-2	RX_WLEN[1:0]	RW	2h	TDM RX word length. 00b = 16-bits 01b = 20-bits 10b = 24-bits 11b = 32-bits
1-0	RX_SLEN[1:0]	RW	2h	TDM RX time slot length. 00b = 16-bits 01b = 24-bits 10b = 32-bits 11b = Reserved

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8.5.2.14 TDM_CFG3 (book=0x00 page=0x00 address=0x0D) [reset=10h]

Sets TDM RX left and right time slots.

图 8-31. TDM_CFG3 Register Address: 0x0D

7	6	5	4	3	2	1	0
RX_SLOT_R[3:0]				RX_SLOT_L[3:0]			
RW-1h				RW-0h			

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-95. TDM Configuration 3 Field Descriptions

Bit	Field	Type	Reset	Description
7-4	RX_SLOT_R[3:0]	RW	1h	TDM RX Right Channel Time Slot.
3-0	RX_SLOT_L[3:0]	RW	0h	TDM RX Left Channel Time Slot.

8.5.2.15 TDM_CFG4 (book=0x00 page=0x00 address=0x0E) [reset=13h]

Sets TDM TX bus keeper, fill, offset and transmit edge.

图 8-32. TDM_CFG4 Register Address: 0x0E

7	6	5	4	3	2	1	0
TX_LSB_CFG	TX_KEEPER_CFG	TX_KEEPER	TX_FILL	TX_OFFSET[2:0]			TX_EDGE
RW-0h	RW-0h	RW-0h	RW-1h	RW-1h			RW-1h

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-96. TDM Configuration 4 Field Descriptions

Bit	Field	Type	Reset	Description
7	TX_LSB_CFG	RW	0h	TDM TX SDOUT LSB data option 0b = TX SDOUT LSB is driven for full-cycle (provided TX_KEEPER is '0') 1b = TX SDOUT LSB is driven for half-cycle
6	TX_KEEPER_CFG	RW	0h	TDM TX SDOUT bus keeper configuration. 0b = Bus keeper is enabled only for 1 LSB bit cycle & SDOUT LSB driven for half cycle (provided TX_KEEPER is '1') 1b = Bus keeper is always enabled & SDOUT LSB driven for half cycle (provided TX_KEEPER is '1')
5	TX_KEEPER	RW	0h	TDM TX SDOUT bus keeper enable. 0b = Disable bus keeper 1b = Enable bus keeper
4	TX_FILL	RW	1h	TDM TX SDOUT unused bitfield fill. 0b = Transmit 0 1b = Transmit Hi-Z
3-1	TX_OFFSET[2:0]	RW	1h	TDM TX start of frame to time slot 0 offset.
0	TX_EDGE	RW	1h	TDM TX launch clock polarity. 0b = Rising edge of SBCLK 1b = Falling edge of SBCLK

8.5.2.16 TDM_CFG5 (book=0x00 page=0x00 address=0x0F) [reset=2h]

Sets TDM TX V-Sense time slot and enable.

图 8-33. TDM_CFG5 Register Address: 0x0F

7	6	5	4	3	2	1	0
Reserved	VSNS_TX	VSNS_SLOT[5:0]					

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图 8-33. TDM_CFG5 Register Address: 0x0F (continued)

RW-0h	RW-0h	RW-2h

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-97. TDM Configuration 5 Field Descriptions

Bit	Field	Type	Reset	Description
7	Reserved	RW	0h	Reserved
6	VSNS_TX	RW	0h	TDM TX voltage sense transmit enable. 0b = Disabled 1b = Enabled
5-0	VSNS_SLOT[5:0]	RW	2h	TDM TX voltage sense time slot. It is recommended to maintain the following order: ISNS_SLOT<VSNS_SLOT<PDM_SLOT<VBAT_SLOT<TEMP_SLOT<GAIN_SLOT

8.5.2.17 TDM_CFG6 (book=0x00 page=0x00 address=0x10) [reset=0h]

Sets TDM TX I-Sense time slot and enable.

图 8-34. TDM_CFG6 Register Address: 0x10

7	6	5	4	3	2	1	0
Reserved	ISNS_TX	ISNS_SLOT[5:0]					
RW-0h	RW-0h	RW-0h					

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-98. TDM Configuration 6 Field Descriptions

Bit	Field	Type	Reset	Description
7	Reserved	RW	0h	Reserved
6	ISNS_TX	RW	0h	TDM TX current sense transmit enable. 0b = Disabled 1b = Enabled
5-0	ISNS_SLOT[5:0]	RW	0h	TDM TX current sense time slot. It is recommended to maintain the following order: ISNS_SLOT<VSNS_SLOT<PDM_SLOT<VBAT_SLOT<TEMP_SLOT<GAIN_SLOT

8.5.2.18 TDM_CFG7 (book=0x00 page=0x00 address=0x11) [reset=4h]

Sets TDM TX time slot and transmit enable for decimated PDM.

图 8-35. TDM_CFG7 Register Address: 0x11

7	6	5	4	3	2	1	0
Reserved	PDM_TX	PDM_SLOT[5:0]					
RW-0h	RW-0h	RW-4h					

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-99. TDM Configuration 7 Field Descriptions

Bit	Field	Type	Reset	Description
7	Reserved	RW	0h	Reserved
6	PDM_TX	RW	0h	TDM TX decimated PDM transmit enable. 0b = Disabled 1b = Enabled
5-0	PDM_SLOT[5:0]	RW	4h	TDM TX decimated PDM time slot.

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8.5.2.19 TDM_CFG8 (book=0x00 page=0x00 address=0x12) [reset=6h]

Sets TDM TX VBAT time slot and enable.

图 8-36. TDM_CFG8 Register Address: 0x12

7	6	5	4	3	2	1	0
VBAT_SLEN	VBAT_TX	VBAT_SLOT[5:0]					
RW-0h	RW-0h	RW-6h					

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-100. TDM Configuration 8 Field Descriptions

Bit	Field	Type	Reset	Description
7	VBAT_SLEN	RW	0h	TDM TX VBAT time slot length. 0b = Truncate to 8-bits 1b = Left justify to 16-bits
6	VBAT_TX	RW	0h	TDM TX VBAT transmit enable. 0b = Disabled 1b = Enabled
5-0	VBAT_SLOT[5:0]	RW	6h	TDM TX VBAT time slot.

8.5.2.20 TDM_CFG9 (book=0x00 page=0x00 address=0x13) [reset=7h]

Sets TDM TX temp time slot and enable.

图 8-37. TDM_CFG9 Register Address: 0x13

7	6	5	4	3	2	1	0
Reserved	TEMP_TX	TEMP_SLOT[5:0]					
RW-0h	RW-0h	RW-7h					

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-101. TDM Configuration 9 Field Descriptions

Bit	Field	Type	Reset	Description
7	Reserved	RW	0h	Reserved
6	TEMP_TX	RW	0h	TDM TX temp sensor transmit enable. 0b = Disabled 1b = Enabled
5-0	TEMP_SLOT[5:0]	RW	7h	TDM TX temp sensor time slot.

8.5.2.21 TDM_CFG10 (book=0x00 page=0x00 address=0x14) [reset=8h]

Sets TDM TX limiter gain reduction time slot and enable.

图 8-38. TDM_CFG10 Register Address: 0x14

7	6	5	4	3	2	1	0
Reserved	GAIN_TX	GAIN_SLOT[5:0]					
RW-0h	RW-0h	RW-8h					

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-102. TDM Configuration 10 Field Descriptions

Bit	Field	Type	Reset	Description
7	Reserved	RW	0h	Reserved

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表 8-102. TDM Configuration 10 Field Descriptions (continued)

Bit	Field	Type	Reset	Description
6	GAIN_TX	RW	0h	TDM TX limiter gain reduction transmit enable. 0b = Disabled 1b = Enabled
5-0	GAIN_SLOT[5:0]	RW	8h	TDM TX limiter gain reduction time slot.

8.5.2.22 LIM_CFG0 (book=0x00 page=0x00 address=0x15) [reset=14h]

Sets Limiter attack step size, attack rate and enable.

图 8-39. LIM_CFG0 Register Address: 0x15

7	6	5	4	3	2	1	0
Reserved		LIM_ATK_ST[1:0]		LIM_ATK_RT[2:0]			LIM_EN
RW-0h		RW-1h		RW-2h			RW-0h

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-103. Limiter Configuration 0 Field Descriptions

Bit	Field	Type	Reset	Description
7-6	Reserved	RW	0h	Reserved
5-4	LIM_ATK_ST[1:0]	RW	1h	Limiter/ICLA attack step size. 00b = 0.25 dB 01b = 0.5 dB 10b = 1 dB 11b = 2 dB
3-1	LIM_ATK_RT[2:0]	RW	2h	Limiter/ICLA attack rate. 000b = 5 us/step 001b = 10 us/step 010b = 20 us/step 011b = 40 us/step 100b = 80 us/step 101b = 160 us/step 110b = 320 us/step 111b = 640 us/step
0	LIM_EN	RW	0h	Limiter enable. 0b = Disabled 1b = Enabled

8.5.2.23 LIM_CFG1 (book=0x00 page=0x00 address=0x16) [reset=76h]

Sets limiter release step size, release rate and hold time.

图 8-40. LIM_CFG1 Register Address: 0x16

7	6	5	4	3	2	1	0
LIM_RLS_ST[1:0]		LIM_RLS_RT[2:0]			LIM_HLD_TM[2:0]		
RW-1h		RW-6h			RW-6h		

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-104. Limiter Configuration 1 Field Descriptions

Bit	Field	Type	Reset	Description
7-6	LIM_RLS_ST[1:0]	RW	1h	Limiter/BOP/ICLA release step size. 00b = 0.25 dB 01b = 0.5 dB 10b = 1 dB 11b = 2 dB

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表 8-104. Limiter Configuration 1 Field Descriptions (continued)

Bit	Field	Type	Reset	Description
5-3	LIM_RLS_RT[2:0]	RW	6h	Limiter/BOP/ICLA release rate. 000b = 10 ms/step 001b = 50 ms/step 010b = 100 ms/step 011b = 250 ms/step 100b = 500 ms/step 101b = 750 ms/step 110b = 1000 ms/step 111b = 1500 ms/step
2-0	LIM_HLD_TM[2:0]	RW	6h	Limiter hold time. 000b = 0 ms 001b = 10 ms 010b = 25 ms 011b = 50 ms 100b = 100 ms 101b = 250 ms 110b = 500 ms 111b = 1000 ms

8.5.2.24 LIM_CFG2 (book=0x00 page=0x00 address=0x17) [reset=10h]

Sets limiter VBAT tracking slope and max attenuatio.

图 8-41. LIM_CFG2 Register Address: 0x17

7	6	5	4	3	2	1	0
Reserved			LIM_MAX_ATN[4:0]				
RW-0h			RW-10h				

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-105. Limiter Configuration 2 Field Descriptions

Bit	Field	Type	Reset	Description
7-5	Reserved	RW	0h	Reserved
4-0	LIM_MAX_ATN[4:0]	RW	10h	Limiter max attenuation. 00h = 1 dB 01h = 1.5 dB ... 10h = 9 dB ... 1Eh = 16 dB 1Fh = 16.5 dB

8.5.2.25 LIM_CFG3 (book=0x00 page=0x00 address=0x18) [reset=6Eh]

Sets Limiter max threshold.

图 8-42. LIM_CFG3 Register Address: 0x18

7	6	5	4	3	2	1	0
Reserved	LIM_TH_MAX[6:0]						
RW-0h	RW-6Eh						

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-106. Limiter Configuration 3 Field Descriptions

Bit	Field	Type	Reset	Description
7	Reserved	RW	0h	Reserved

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表 8-106. Limiter Configuration 3 Field Descriptions (continued)

Bit	Field	Type	Reset	Description
6-0	LIM_TH_MAX[6:0]	RW	6Eh	Limiter max threshold. 00h = 2 V 01h = 2.1 V ... 6Eh = 13 V ... 7Eh = 14.6 V 7Fh = 14.7 V

8.5.2.26 LIM_CFG4 (book=0x00 page=0x00 address=0x19) [reset=1Eh]

Sets limiter min threshold.

图 8-43. LIM_CFG4 Register Address: 0x19

7	6	5	4	3	2	1	0
Reserved	LIM_TH_MIN[6:0]						
RW-0h	RW-1Eh						

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-107. Limiter Configuration 4 Field Descriptions

Bit	Field	Type	Reset	Description
7	Reserved	RW	0h	Reserved
6-0	LIM_TH_MIN[6:0]	RW	1Eh	Limiter min threshold. 00h = 2 V 01h = 2.1 V ... 1Eh = 5 V ... 7Eh = 14.6 V 7Fh = 14.7 V

8.5.2.27 LIM_CFG5 (book=0x00 page=0x00 address=0x1A) [reset=58h]

Sets limiter inflection point.

图 8-44. LIM_CFG5 Register Address: 0x1A

7	6	5	4	3	2	1	0
Reserved	LIM_INF_PT[6:0]						
RW-0h	RW-58h						

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-108. Limiter Configuration 5 Field Descriptions

Bit	Field	Type	Reset	Description
7	Reserved	RW	0h	Reserved
6-0	LIM_INF_PT[6:0]	RW	58h	Limiter inflection point. 00h = 2 V 01h = 2.1 V ... 58h = 10.8 V ... 7Eh = 14.6 V 7Fh = 14.7 V

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8.5.2.28 BOP_CFG0 (book=0x00 page=0x00 address=0x1B) [reset=1h]

Sets BOP infinite hold clear, infinite hold enable, mute on brown out and enable.

图 8-45. BOP_CFG0 Register Address: 0x1B

7	6	5	4	3	2	1	0
Reserved	EN_BO_RECOVERY_HYSTERSIS	LIM_SLOPE[1:0]		BOP_HLD_CLR	BOP_INF_HLD	BOP_MUTE	BOP_EN
RW-0h	RW-0h	RW-0h		RW-0h	RW-0h	RW-0h	RW-1h

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-109. Brown Out Prevention 0 Field Descriptions

Bit	Field	Type	Reset	Description
7	Reserved	RW	0h	Reserved
6	EN_BO_RECOVERY_HYSTERSIS	RW	0h	
5-4	LIM_SLOPE[1:0]	RW	0h	Limiter VBAT tracking slope. 00b = 1 V/V 01b = 1.5 V/V 10b = 2 V/V 11b = 4 V/V
3	BOP_HLD_CLR	RW	0h	BOP infinite hold clear (self clearing). 0b = Don't clear 1b = Clear
2	BOP_INF_HLD	RW	0h	Infinite hold on brown out event. 0b = Use BOP_HLD_TM after brown out event 1b = Don't release until BOP_HLD_CLR is asserted high
1	BOP_MUTE	RW	0h	Mute on brown out event. 0b = Don't mute 1b = Mute followed by device shutdown
0	BOP_EN	RW	1h	Brown out prevention enable. 0b = Disabled 1b = Enabled

8.5.2.29 BOP_CFG1 (book=0x00 page=0x00 address=0x1C) [reset=14h]

BOP threshold.

图 8-46. BOP_CFG1 Register Address: 0x1C

7	6	5	4	3	2	1	0
BOP_TH[7:0]							
RW-14h							

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-110. Brown Out Prevention 1 Field Descriptions

Bit	Field	Type	Reset	Description
7-0	BOP_TH[7:0]	RW	14h	Brown out prevention threshold. 00h = 4.5 V 01h = 4.525 V ... 14h = 5.0 V ... FEh = 10.85 V FFh = 10.875 V

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8.5.2.30 BOP_CFG2 (book=0x00 page=0x00 address=0x1D) [reset=4Eh]

BOP attack rate, attack step size and hold time.

图 8-47. BOP_CFG2 Register Address: 0x1D

7	6	5	4	3	2	1	0
BOP_ATK_RT[2:0]			BOP_ATK_ST[1:0]		BOP_HLD_TM[2:0]		
RW-2h			RW-1h		RW-6h		

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-111. Brown Out Prevention 2 Field Descriptions

Bit	Field	Type	Reset	Description
7-5	BOP_ATK_RT[2:0]	RW	2h	Brown out prevention attack rate. 000b = 5 us/step 001b = 10 us/step 010b = 20 us/step 011b = 40 us/step 100b = 80 us/step 101b = 160 us/step 110b = 320 us/step 111b = 640 us/step
4-3	BOP_ATK_ST[1:0]	RW	1h	Brown out prevention attack step size. 00b = 0.5 dB 01b = 1 dB 10b = 1.5 dB 11b = 2 dB
2-0	BOP_HLD_TM[2:0]	RW	6h	Brown out prevention hold time. 000b = 0 ms 001b = 10 ms 010b = 25 ms 011b = 50 ms 100b = 100 ms 101b = 250 ms 110b = 500 ms 111b = 1000 ms

8.5.2.31 ICLA_CFG0 (book=0x00 page=0x00 address=0x1E) [reset=0h]

ICLA starting time slot and enable.

图 8-48. ICLA_CFG0 Register Address: 0x1E

7	6	5	4	3	2	1	0
ICLA_USE_MAX	ICLA_SLOT[5:0]						ICLA_EN
RW-0h	RW-0h						RW-0h

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-112. Inter Chip Limiter Alignment 0 Field Descriptions

Bit	Field	Type	Reset	Description
7	ICLA_USE_MAX	RW	0h	Inter chip limiter alignment min/max config 0b = Use the maximum of the ICLA group gain reduction 1b = Use the minimum of the ICLA group gain reduction
6-1	ICLA_SLOT[5:0]	RW	0h	Inter chip limiter alignment starting time slot.
0	ICLA_EN	RW	0h	Inter chip limiter alignment enable. 0b = Disabled 1b = Enabled

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8.5.2.32 ICLA_CFG1 (book=0x00 page=0x00 address=0x1F) [reset=0h]

ICLA time slot enables.

图 8-49. ICLA_CFG1 Register Address: 0x1F

7	6	5	4	3	2	1	0
ICLA_SEN[7]	ICLA_SEN[6]	ICLA_SEN[5]	ICLA_SEN[4]	ICLA_SEN[3]	ICLA_SEN[2]	ICLA_SEN[1]	ICLA_SEN[0]
RW-0h	RW-0h	RW-0h	RW-0h	RW-0h	RW-0h	RW-0h	RW-0h

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-113. Inter Chip Limiter Alignment 1 Field Descriptions

Bit	Field	Type	Reset	Description
7	ICLA_SEN[7]	RW	0h	Time slot equals ICLA_SLOT[5:0]+7. When enabled, the limiter will include this time slot in the alignment group. 0b = Disabled 1b = Enabled
6	ICLA_SEN[6]	RW	0h	Time slot equals ICLA_SLOT[5:0]+6. When enabled, the limiter will include this time slot in the alignment group. 0b = Disabled 1b = Enabled
5	ICLA_SEN[5]	RW	0h	Time slot equals ICLA_SLOT[5:0]+5. When enabled, the limiter will include this time slot in the alignment group. 0b = Disabled 1b = Enabled
4	ICLA_SEN[4]	RW	0h	Time slot equals ICLA_SLOT[5:0]+4. When enabled, the limiter will include this time slot in the alignment group. 0b = Disabled 1b = Enabled
3	ICLA_SEN[3]	RW	0h	Time slot equals ICLA_SLOT[5:0]+3. When enabled, the limiter will include this time slot in the alignment group. 0b = Disabled 1b = Enabled
2	ICLA_SEN[2]	RW	0h	Time slot equals ICLA_SLOT[5:0]+2. When enabled, the limiter will include this time slot in the alignment group. 0b = Disabled 1b = Enabled
1	ICLA_SEN[1]	RW	0h	Time slot equals ICLA_SLOT[5:0]+1. When enabled, the limiter will include this time slot in the alignment group. 0b = Disabled 1b = Enabled
0	ICLA_SEN[0]	RW	0h	Time slot equals ICLA_SLOT[5:0]. When enabled, the limiter will include this time slot in the alignment group. 0b = Disabled 1b = Enabled

8.5.2.33 INT_MASK0 (book=0x00 page=0x00 address=0x20) [reset=FCh]

Interrupt masks.

图 8-50. INT_MASK0 Register Address: 0x20

7	6	5	4	3	2	1	0
INT_MASK[7]	INT_MASK[6]	INT_MASK[5]	INT_MASK[4]	INT_MASK[3]	INT_MASK[2]	INT_MASK[1]	INT_MASK[0]
RW-1h	RW-1h	RW-1h	RW-1h	RW-1h	RW-1h	RW-0h	RW-0h

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

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表 8-114. Interrupt Mask 0 Field Descriptions

Bit	Field	Type	Reset	Description
7	INT_MASK[7]	RW	1h	Limiter mute mask. 0b = Don't Mask 1b = Mask
6	INT_MASK[6]	RW	1h	Limiter infinite hold mask. 0b = Don't Mask 1b = Mask
5	INT_MASK[5]	RW	1h	Limiter max attenuation mask. 0b = Don't Mask 1b = Mask
4	INT_MASK[4]	RW	1h	VBAT <N521 Inflection Point mask. 0b = Don't Mask 1b = Mask
3	INT_MASK[3]	RW	1h	Limiter active mask. 0b = Don't Mask 1b = Mask
2	INT_MASK[2]	RW	1h	TDM clock error mask. 0b = Don't Mask 1b = Mask
1	INT_MASK[1]	RW	0h	Over current error mask. 0b = Don't Mask 1b = Mask
0	INT_MASK[0]	RW	0h	Over temp error mask. 0b = Don't Mask 1b = Mask

8.5.2.34 INT_MASK1 (book=0x00 page=0x00 address=0x21) [reset=B1h]

Interrupt masks.

图 8-51. INT_MASK1 Register Address: 0x21

7	6	5	4	3	2	1	0
INT_MASK[14]	Reserved	Reserved	Reserved	INT_MASK[11]	INT_MASK[10]	INT_MASK[9]	INT_MASK[8]
RW-1h	RW-0h	RW-1h	RW-1h	RW-0h	RW-0h	RW-0h	RW-1h

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-115. Interrupt Mask 1 Field Descriptions

Bit	Field	Type	Reset	Description
7	INT_MASK[14]	RW	1h	PDM audio data invalid mask. 0b = Don't Mask 1b = Mask
6	Reserved	RW	0h	Reserved
5	Reserved	RW	1h	Reserved
4	Reserved	RW	1h	Reserved
3	INT_MASK[11]	RW	0h	VBAT OVLO mask. 0b = Don't Mask 1b = Mask
2	INT_MASK[10]	RW	0h	VBAT UVLO mask. 0b = Don't Mask 1b = Mask
1	INT_MASK[9]	RW	0h	VBAT Brown out mask 0b = Don't Mask 1b = Mask

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表 8-115. Interrupt Mask 1 Field Descriptions (continued)

Bit	Field	Type	Reset	Description
0	INT_MASK[8]	RW	1h	PDM clock error mask. 0b = Don't Mask 1b = Mask

8.5.2.35 INT_LIVE0 (book=0x00 page=0x00 address=0x22) [reset=0h]

Live interrupt readback.

图 8-52. INT_LIVE0 Register Address: 0x22

7	6	5	4	3	2	1	0
INT_LIVE[7]	INT_LIVE[6]	INT_LIVE[5]	INT_LIVE[4]	INT_LIVE[3]	INT_LIVE[2]	INT_LIVE[1]	INT_LIVE[0]
R-0h	R-0h	R-0h	R-0h	R-0h	R-0h	R-0h	R-0h

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-116. Live Interrupt Readback 0 Field Descriptions

Bit	Field	Type	Reset	Description
7	INT_LIVE[7]	R	0h	Interrupt due to limiter mute. 0b = No interrupt 1b = Interrupt
6	INT_LIVE[6]	R	0h	Interrupt due to limiter infinite hold. 0b = No interrupt 1b = Interrupt
5	INT_LIVE[5]	R	0h	Interrupt due to limiter max attenuation. 0b = No interrupt 1b = Interrupt
4	INT_LIVE[4]	R	0h	Interrupt due to VBAT below limiter inflection point. 0b = No interrupt 1b = Interrupt
3	INT_LIVE[3]	R	0h	Interrupt due to limiter active. 0b = No interrupt 1b = Interrupt
2	INT_LIVE[2]	R	0h	Interrupt due to TDM clock error. 0b = No interrupt 1b = Interrupt
1	INT_LIVE[1]	R	0h	Interrupt due to over current error. 0b = No interrupt 1b = Interrupt
0	INT_LIVE[0]	R	0h	Interrupt due to over temp error. 0b = No interrupt 1b = Interrupt

8.5.2.36 INT_LIVE1 (book=0x00 page=0x00 address=0x23) [reset=0h]

Live interrupt readback.

图 8-53. INT_LIVE1 Register Address: 0x23

7	6	5	4	3	2	1	0
INT_LIVE[15]	Reserved	Reserved	Reserved	INT_LIVE[11]	INT_LIVE[10]	INT_LIVE[9]	INT_LIVE[8]
R-0h	R-0h	R-0h	R-0h	R-0h	R-0h	R-0h	R-0h

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

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表 8-117. Live Interrupt Readback 1 Field Descriptions

Bit	Field	Type	Reset	Description
7	INT_LIVE[15]	R	0h	Interrupt due to PDM audio data invalid 0b = No interrupt 1b = Interrupt
6	Reserved	R	0h	Reserved
5	Reserved	R	0h	Reserved
4	Reserved	R	0h	Reserved
3	INT_LIVE[11]	R	0h	Interrupt due to VBAT OVLO flag. 0b = No interrupt 1b = Interrupt
2	INT_LIVE[10]	R	0h	Interrupt due to VBAT UVLO flag. 0b = No interrupt 1b = Interrupt
1	INT_LIVE[9]	R	0h	Interrupt due to VBAT brown out flag. 0b = No interrupt 1b = Interrupt
0	INT_LIVE[8]	R	0h	Interrupt due to PDM clock error. 0b = No interrupt 1b = Interrupt

8.5.2.37 INT_LTCH0 (book=0x00 page=0x00 address=0x24) [reset=0h]

Latched interrupt readback.

图 8-54. INT_LTCH0 Register Address: 0x24

7	6	5	4	3	2	1	0
INT_LTCH[7]	INT_LTCH[6]	INT_LTCH[5]	INT_LTCH[4]	INT_LTCH[3]	INT_LTCH[2]	INT_LTCH[1]	INT_LTCH[0]
R-0h	R-0h	R-0h	R-0h	R-0h	R-0h	R-0h	R-0h

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-118. Latched Interrupt Readback 0 Field Descriptions

Bit	Field	Type	Reset	Description
7	INT_LTCH[7]	R	0h	Interrupt due to limiter mute (read to clear). 0b = No interrupt 1b = Interrupt
6	INT_LTCH[6]	R	0h	Interrupt due to limiter infinite hold (read to clear). 0b = No interrupt 1b = Interrupt
5	INT_LTCH[5]	R	0h	Interrupt due to limiter max attenuation (read to clear). 0b = No interrupt 1b = Interrupt
4	INT_LTCH[4]	R	0h	Interrupt due to VBAT < limiter inflection point (read to clear). 0b = No interrupt 1b = Interrupt
3	INT_LTCH[3]	R	0h	Interrupt due to limiter active (read to clear). 0b = No interrupt 1b = Interrupt
2	INT_LTCH[2]	R	0h	Interrupt due to TDM clock error (read to clear). 0b = No interrupt 1b = Interrupt
1	INT_LTCH[1]	R	0h	Interrupt due to over current error (read to clear). 0b = No interrupt 1b = Interrupt

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表 8-118. Latched Interrupt Readback 0 Field Descriptions (continued)

Bit	Field	Type	Reset	Description
0	INT_LTCH[0]	R	0h	Interrupt due to over temp error (read to clear). 0b = No interrupt 1b = Interrupt

8.5.2.38 INT_LTCH1 (book=0x00 page=0x00 address=0x25) [reset=0h]

Latched interrupt readback.

图 8-55. INT_LTCH1 Register Address: 0x25

7	6	5	4	3	2	1	0
INT_LTCH[15]	Reserved	Reserved	Reserved	INT_LTCH[11]	INT_LTCH[10]	INT_LTCH[9]	INT_LTCH[8]
R-0h	R-0h	R-0h	R-0h	R-0h	R-0h	R-0h	R-0h

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-119. Latched Interrupt Readback 1 Field Descriptions

Bit	Field	Type	Reset	Description
7	INT_LTCH[15]	R	0h	Interrupt due to PDM audio data invalid. (read to clear). 0b = No interrupt 1b = Interrupt
6	Reserved	R	0h	Reserved
5	Reserved	R	0h	Reserved
4	Reserved	R	0h	Reserved
3	INT_LTCH[11]	R	0h	Interrupt due to VBAT OVLO flag (read to clear). 0b = No interrupt 1b = Interrupt
2	INT_LTCH[10]	R	0h	Interrupt due to VBAT UVLO flag (read to clear). 0b = No interrupt 1b = Interrupt
1	INT_LTCH[9]	R	0h	Interrupt due to VBAT brown out flag (read to clear). 0b = No interrupt 1b = Interrupt
0	INT_LTCH[8]	R	0h	Interrupt due to PDM clock error (read to clear). 0b = No interrupt 1b = Interrupt

8.5.2.39 INT_LTCH2 (book=0x00 page=0x00 address=0x26) [reset=0h]

表 8-120. INT_LTCH2 Register Address: 0x26

7	6	5	4	3	2	1	0
INT_LTCH[23]	INT_LTCH[22]	INT_LTCH[21]	INT_LTCH[20]	INT_LTCH[19]	INT_LTCH[18]	INT_LTCH[17]	INT_LTCH[16]
R-0h	R-0h	R-0h	R-0h	R-0h	R-0h	R-0h	R-0h

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-121. INT_LTCH2 Field Descriptions

Bit	Field	Type	Reset	Description
7	INT_LTCH[23]	R	0h	Interrupt due to clock halt flag (read to clear) 0b = No interrupt 1b = Interrupt
6	INT_LTCH[22]	R	0h	Interrupt due to DMA Request to DSP lost flag (read to clear) 0b = No interrupt 1b = Interrupt

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表 8-121. INT_LTCH2 Field Descriptions (continued)

Bit	Field	Type	Reset	Description
5	INT_LTCH[21]	R	0h	Interrupt due to Auto Trim converged status (read to clear) 0b = No interrupt 1b = Interrupt
4	INT_LTCH[20]	R	0h	Interrupt due to Class D Clamp status flag (read to clear) 0b = No interrupt 1b = Interrupt
3	INT_LTCH[19]	R	0h	Interrupt due to HIGH SIDE OC flag (read to clear). 0b = No interrupt 1b = Interrupt
2	INT_LTCH[18]	R	0h	Interrupt due to LOW SIDE OC flag (read to clear). 0b = No interrupt 1b = Interrupt
1	INT_LTCH[17]	R	1h	Interrupt due to LDO 5 V PG flag (read to clear). 0b = No interrupt 1b = Interrupt
0	INT_LTCH[16]	R	0h	Interrupt due to LDO 5 V OL (read to clear). 0b = No interrupt 1b = Interrupt

8.5.2.40 VBAT_MSB (book=0x00 page=0x00 address=0x27) [reset=0h]

MSBs of SAR ADC VBAT conversion.

图 8-56. VBAT_MSB Register Address: 0x27

7	6	5	4	3	2	1	0
VBAT_CNV[11:4]							
R-0h							

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-122. SAR ADC Conversion 0 Field Descriptions

Bit	Field	Type	Reset	Description
7--4	VBAT_CNV[11:0]	R	0h	Returns SAR ADC VBAT conversion MSBs.

8.5.2.41 VBAT_LSB (book=0x00 page=0x00 address=0x28) [reset=0h]

LSBs of SAR ADC VBAT conversion.

图 8-57. VBAT_LSB Register Address: 0x28

7	6	5	4	3	2	1	0
VBAT_CNV[3:0]				Reserved			
R-0h				R-0h			

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-123. SAR ADC Conversion 1 Field Descriptions

Bit	Field	Type	Reset	Description
7-4	VBAT_CNV[3:0]	R	0h	Returns SAR ADC VBAT conversion LSBs.
3-0	Reserved	R	0h	Reserved

8.5.2.42 TEMP_MSB (book=0x00 page=0x00 address=0x29) [reset=0h]

SARD ADC Temp conversion.

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图 8-58. TEMP_MSB Register Address: 0x29

7	6	5	4	3	2	1	0
TMP_CNV[11:4]							
R-0h							

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-124. SAR ADC Conversion 2 Field Descriptions

Bit	Field	Type	Reset	Description
7--4	TMP_CNV[11:0]	R	0h	Returns SAR ADC temp sensor conversion.

8.5.2.43 TEMP_LSB (book=0x00 page=0x00 address=0x2A) [reset=0h]

SARD ADC Temp conversion.

图 8-59. TEMP_LSB Register Address: 0x2A

7	6	5	4	3	2	1	0
TMP_CNV[3:0]				Reserved			
-0h				R-0h			

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-125. SAR ADC Conversion 2 Field Descriptions

Bit	Field	Type	Reset	Description
7-4	TMP_CNV[3:0]		0h	Returns SAR ADC temp sensor conversion.
3-0	Reserved	R	0h	Reserved

8.5.2.44 INT_CFG (book=0x00 page=0x00 address=0x30) [reset=5h]

Sets whether latched or live interrupts will trigger IRQZ pin.

图 8-60. INT_CFG Register Address: 0x30

7	6	5	4	3	2	1	0
Reserved						IRQZ_PIN_CFG[1:0]	
RW-0h						RW-1h	

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-126. Interrupt Configuration Field Descriptions

Bit	Field	Type	Reset	Description
7-2	Reserved	RW	0h	Reserved
1-0	IRQZ_PIN_CFG[1:0]	RW	1h	IRQZ interrupt configuration. 00b = IRQZ will assert on any unmasked live interrupts 01b = IRQZ will assert on any unmasked latched interrupts 10b = IRQZ will assert for 2ms one time on any unmasked live interrupt event 11b = IRQZ will assert for 2ms every 4ms on any unmasked latched interrupts

8.5.2.45 DIN_PD (book=0x00 page=0x00 address=0x31) [reset=0h]

Sets enables of input pin weak pull down.

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

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图 8-61. DIN_PD Register Address: 0x31

7	6	5	4	3	2	1	0
DIN_PD[7]	DIN_PD[6]	DIN_PD[5]	DIN_PD[4]	Reserved	DIN_PD[2]	Reserved	DIN_PD[0]
RW-0h	RW-0h	RW-0h	RW-0h	RW-0h	RW-0h	RW-0h	RW-0h

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-127. Digital Input Pin Pull Down Field Descriptions

Bit	Field	Type	Reset	Description
7	DIN_PD[7]	RW	0h	Weak pull down for SDOUT 0b = Disabled 1b = Enabled
6	DIN_PD[6]	RW	0h	Weak pull down for SDIN. 0b = Disabled 1b = Enabled
5	DIN_PD[5]	RW	0h	Weak pull down for FSYNC. 0b = Disabled 1b = Enabled
4	DIN_PD[4]	RW	0h	Weak pull down for SBCLK. 0b = Disabled 1b = Enabled
3	Reserved	RW	0h	Reserved
2	DIN_PD[2]	RW	0h	Weak pull down for PDMD1. 0b = Disabled 1b = Enabled
0	Reserved	RW	0h	Reserved
0	DIN_PD[0]	RW	0h	Weak pull down for PDMCK1. 0b = Disabled 1b = Enabled

8.5.2.46 MISC_IRQ (book=0x00 page=0x00 address=0x32) [reset=81h]

Set IRQZ pin active state

图 8-62. MISC_IRQ Register Address: 0x32

7	6	5	4	3	2	1	0
IRQZ_POL	Reserved			Reserved	Reserved	Reserved	IRQZ_VAL
RW-1h	RW-0h			RW-0h	RW-0h	RW-0h	R-1h

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-128. Misc Configuration Field Descriptions

Bit	Field	Type	Reset	Description
7	IRQZ_POL	RW	1h	IRQZ pin polarity for interrupt. 0b = Active high (IRQ) 1b = Active low (IRQZ)
6-4	Reserved	RW	0h	Reserved
3	Reserved	RW	0h	Reserved
2	Reserved	RW	0h	Reserved
1	Reserved	RW	0h	Reserved
0	IRQZ_VAL	R	1h	IRQZ bit bang in read value. Default is 1b'1 if there are no interupts/errors 0b = IRQZ Input Buffer Value=0 1b = IRQZ Input Buffer Value=1

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8.5.2.47 CLOCK_CFG (book=0x00 page=0x00 address=0x3C) [reset=Dh]

Can override audio configure and set the clocking ratio

图 8-63. CLOCK_CFG Register Address: 0x3C

7	6	5	4	3	2	1	0
Reserved	Reserved	SBCLK_FS_RATIO[3:0]				AUTO_CLK[1:0]	
RW-0h	RW-0h	RW-3h				RW-1h	

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-129. Clock Configuration Field Descriptions

Bit	Field	Type	Reset	Description
7	Reserved	RW	0h	Reserved
6	Reserved	RW	0h	Reserved
5-2	SBCLK_FS_RATIO[3:0]	RW	3h	Program manually SBCLK to FS ratio when auto clock detection is disabled 00h = 16 01h = 24 02h = 32 03h = 48 04h = 64 05h = 96 06h = 128 07h = 192 08h = 256 09h = 384 0Ah = 512
1-0	AUTO_CLK[1:0]	RW	1h	Clocking automatic configuraiton 00b = Auto configure clock dividers based on SBCLK to FSYNC ratio 01b = Manually configure clock dividers by programming SBCLK_FS_RATIO

8.5.2.48 TDM_DET (book=0x00 page=0x00 address=0x77) [reset=7Fh]

Readback of internal auto-rate detection.

图 8-64. TDM_DET Register Address: 0x77

7	6	5	4	3	2	1	0
Reserved	FS_RATIO[3:0]				FS_RATE_V[2:0]		
R-0h	R-Fh				R-7h		

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-130. TDM Clock detection monitor Field Descriptions

Bit	Field	Type	Reset	Description
7	Reserved	R	0h	Reserved

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表 8-130. TDM Clock detection monitor Field Descriptions (continued)

Bit	Field	Type	Reset	Description
6-3	FS_RATIO[3:0]	R	Fh	Detected SBCLK to FSYNC ratio. 00h = 16 01h = 24 02h = 32 03h = 48 04h = 64 05h = 96 06h = 128 07h = 192 08h = 256 09h = 384 0Ah = 512 0Bh-0Eh = Reserved 0F = Invalid ratio
2-0	FS_RATE_V[2:0]	R	7h	Detected sample rate of TDM bus. 000b = Reserved 001b = Reserved 010b = Reserved 011b = 44.1/48 KHz 100b = 88.2/96 kHz 101b = 176.4/192 kHz 110b = Reserved 111b = Error condition

8.5.2.49 REV_ID (book=0x00 page=0x00 address=0x7D) [reset=20h]

Returns REV and PG ID.

图 8-65. REV_ID Register Address: 0x7D

7	6	5	4	3	2	1	0
REV_ID[3:0]				PG_ID[3:0]			
R-1h (TAS2770 QFN Rev A) R-2h (TAS2770 QFN Rev B) R- 4h (TAS2770 WCSP Rev B) R- 5h (TAS2770 WCSP Rev C)				R-0h			

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-131. Revision and PG ID Field Descriptions

Bit	Field	Type	Reset	Description
7-4	REV_ID[3:0]	R	(see above table)	Returns the revision ID.
3-0	PG_ID[3:0]	R	0h	Returns the PG ID.

8.5.2.50 I2C_CKSUM (book=0x00 page=0x00 address=0x7E) [reset=0h]

Returns I2C checksum.

图 8-66. I2C_CKSUM Register Address: 0x7E

7	6	5	4	3	2	1	0
I2C_CKSUM[7:0]							
RW-0h							

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

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表 8-132. I2C Checksum Field Descriptions

Bit	Field	Type	Reset	Description
7-0	I2C_CKSUM[7:0]	RW	0h	Returns I2C checksum. Writing to this register will reset the checksum to the written value. This register is updated on writes to other registers on all books and pages.

8.5.2.51 BOOK (book=0x00 page=0x00 address=0x7F) [reset=0h]

Device's memory map is divided into pages and books. This register sets the book.

图 8-67. BOOK Register Address: 0x7F

7	6	5	4	3	2	1	0
BOOK[7:0]							
RW-0h							

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 8-133. Device Book Field Descriptions

Bit	Field	Type	Reset	Description
7-0	BOOK[7:0]	RW	0h	Sets the device book. 00h = Book 0 01h = Book 1 ... FFh = Book 255

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9 Application and Implementation

备注

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI’s customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

The TAS2770 is a digital input Class-D audio power amplifier with integrated I/V sense. I2S audio data is supplied by host processor. It also accepts I/V data in I2S format. I^{2}C bus is used for configuration and control.

9.2 Typical Application

图 9-1 below shows a typical configuration of the TAS2770.

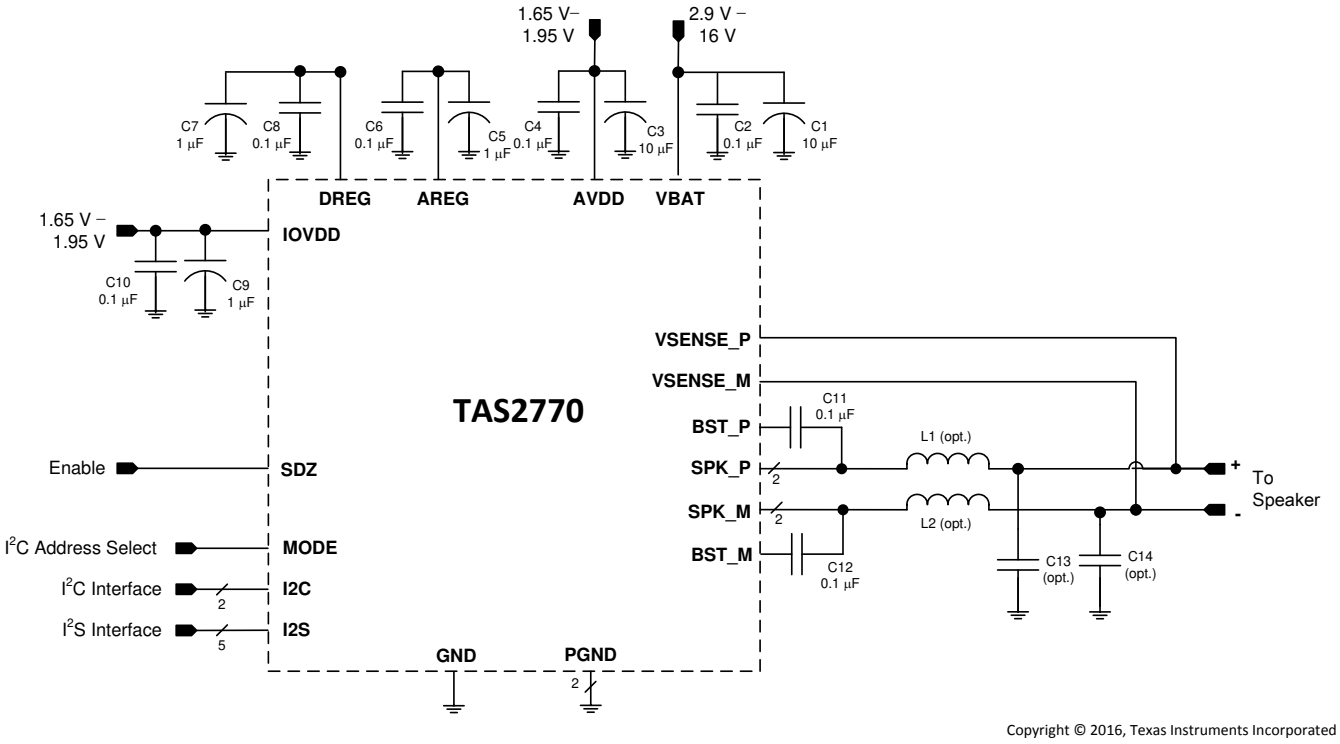


图 9-1. TAS2770 Typical Application

表 9-1. Recommended External Components

COMPONENT	DESCRIPTION	SPECIFICATION	MIN	TYP	MAX	UNIT	NOTES
C1	VBAT Decoupling Capacitor	Capacitance	10	22		µF	
		Rated Voltage	25			V	
C2	VBAT Decoupling Capacitor	Capacitance	0.1			µF	
		Rated Voltage	25			V	

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表 9-1. Recommended External Components (continued)

COMPONENT	DESCRIPTION	SPECIFICATION	MIN	TYP	MAX	UNIT	NOTES
C3	AVDD Decoupling Capacitor	Capacitance	1	10		µF	
		Rated Voltage	10			V	
C4	AVDD Decoupling Capacitor	Capacitance	0.1			µF	
		Rated Voltage	10			V	
C5	AREG Decoupling Capacitor	Capacitance	0.68	1	1.5	µF	
		Rated Voltage	10			V	
C6	AREG Decoupling Capacitor	Capacitance		0.1		µF	C5 + C6 < 1.5µF
		Rated Voltage	10			V	
C7	DREG Decoupling Capacitor	Capacitance	0.68	1	1.5	µF	
		Rated Voltage	10			V	
C8	DREG Decoupling Capacitor	Capacitance		0.1		µF	C7 + C8 < 1.5µF
		Rated Voltage	10			V	
C9	IOVDD Decoupling Capacitor	Capacitance	1			µF	
		Rated Voltage	10			V	
C10	IOVDD Decoupling Capacitor	Capacitance	0.1			µF	
		Rated Voltage	10			V	
C11	Class-D Positive Boostrap Capacitor	Capacitance		0.1	0.12	µF	
		Rated Voltage	25			V	
C12	Class-D Negative Boostrap Capacitor	Capacitance		0.1	0.12	µF	
		Rated Voltage	25			V	
C13, C14	EMI Filter Capacitors (optional). Optional inductors L1 and L2 must be connected when the EMI Filter capacitors are placed	Capacitance		1		nF	
		Rated Voltage	25			V	

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表 9-1. Recommended External Components (continued)

COMPONENT	DESCRIPTION	SPECIFICATION	MIN	TYP	MAX	UNIT	NOTES
L1, L2	EMI Filter Inductors (optional). SPK_P pin must be directly connected to VSENSE_P when the inductors are used. Optional capacitors C13 and C14 must be connected when the EMI filter inductors are placed	Impedance at 100MHz		120		Ω	
		DC Resistance			0.095	Ω	
		DC Current		4	6	A	
		Size		0402		EIA	

9.2.1 Design Requirements

表 9-2 shows the design parameters.

表 9-2. Recommended Component Selection

PARAMETER	EXAMPLE VALUE
Amplifier power supply (VBAT)	4.5 V to 16 V
EVM power supply	4.5 V to 16 V
IO power supply (IOVDD)	1.65 V to 1.95 V
Output Power	18.3 W
USB, USB class-audio	Micro-USB B

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9.2.2 Detailed Design Procedure

9.2.2.1 Overview

The TAS2770 is a flexible and easy-to-use Class D amplifier. Therefore, the design process is straightforward.

Before beginning the design, gather the following information regarding the audio system:

- VBAT rail planned for the design
- Speaker or load impedance
- Audio sample rate
- Maximum output power requirement

9.2.2.2 Select Input Capacitance

Select the bulk capacitors at the VBAT inputs for proper voltage margin and adequate capacitance to support the power requirements. The TAS2770 has very good PSRR, so the capacitor is more about limiting the ripple and droop for the rest of system than preserving good audio performance. The amount of bulk decoupling can be reduced as long as the droop and ripple is acceptable. One capacitor should be placed near the VBAT pin. VBATY capacitors should be a low ESR type because they are being used in a high-speed switching application.

9.2.2.3 Select Decoupling Capacitors

Good quality decoupling capacitors should be added at each of the VBAT input to provide good reliability, good audio performance, and to meet regulatory requirements. X5R or better ratings should be used in this application. Consider temperature, ripple current, and voltage overshoots when selecting decoupling capacitors.

Also, the decoupling capacitors should be located near the VBAT and GND connections to the device to minimize series inductances.

9.2.2.4 Select Bootstrap Capacitors

Each of the outputs require bootstrap capacitors to provide gate drive for the high-side output FETs. For this design, use 0.1-µF, 25-V capacitors of X5R quality or better.

9.2.3 Application Curves

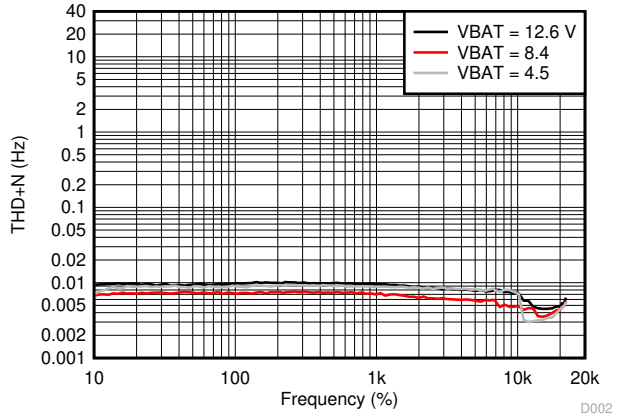


图 9-2. THD+N vs Frequency

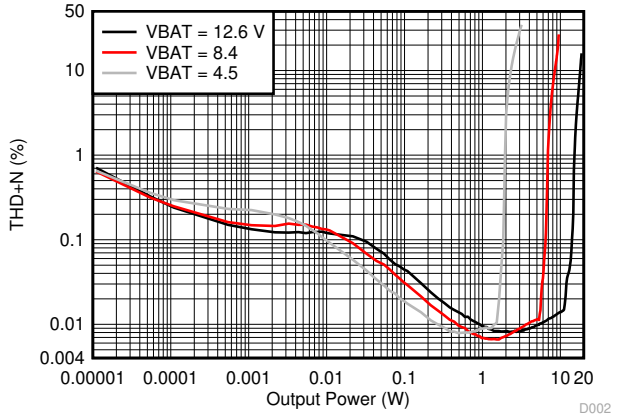


图 9-3. THD+N vs Output Power (W)

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9.3 Initialization Set Up

9.3.1 Initial Device Configuration - Auto Rate

The following I2C sequence is an example of initializing four TAS5770LC0 devices. The devices will be configured to use the TDM auto-rate detection feature. This sequence contains a 1 ms delay required after a software or hardware reset as illustrated in 节 10.

备注

For TAS2770 the device I2C address needs to be changed. See 表 8-1.

```
w 62 00 00 # Page-0
w 62 7f 00 # Book-0
w 62 01 01 # Software Reset
w 64 00 00 # Page-0
w 64 7f 00 # Book-0
w 64 01 01 # Software Reset
w 66 00 00 # Page-0
w 66 7f 00 # Book-0
w 66 01 01 # Software Reset
w 68 00 00 # Page-0
w 68 7f 00 # Book-0
w 68 01 01 # Software Reset
d 1 # 1mS Delay
###### Configure Channel 1
w 62 3c 11 # sbclk to fs ratio = 64
w 62 0e 33 # TX bus keeper, Hi-Z, offset 1, TX on Falling edge
w 62 0f 42 # TDM TX voltage sense transmit enable with slot 2,
w 62 10 40 # TDM TX current sense transmit enable with slot 0
w 62 03 14 # 21 dB gain
w 62 02 00 # power up audio playback with I,V enabled
###### Configure Channel 2
w 64 3c 11 # sbclk to fs ratio = 64
w 64 0e 13 # TX bus keeper, Hi-Z, offset 1, TX on Falling edge
w 64 0f 46 # TDM TX voltage sense transmit enable with slot 6,
w 64 10 44 # TDM TX current sense transmit enable with slot 4
w 64 03 14 # 21 dB gain
w 64 02 00 # power up audio playback with I,V enabled
###### Configure Channel 3
w 66 3c 11 # sbclk to fs ratio = 64
w 66 0e 13 # TX bus keeper, Hi-Z, offset 1, TX on Falling edge
w 66 0f 4A # TDM TX voltage sense transmit enable with slot 10,
w 66 10 48 # TDM TX current sense transmit enable with slot 8
w 66 03 14 # 21 dB gain
w 66 02 00 # power up audio playback with I,V enabled
###### Configure Channel 4
w 68 3c 11 # sbclk to fs ratio = 64
w 68 0e 13 # TX bus keeper, Hi-Z, offset 1, TX on Falling edge
w 68 0f 4E # TDM TX voltage sense transmit enable with slot 14,
w 68 10 4C # TDM TX current sense transmit enable with slot 12
w 68 03 14 # 21 dB gain
w 68 02 00 # power up audio playback with I,V enabled
```

9.3.2 Initial Device Configuration - 48 kHz

The following I2C sequence is an example of initializing a TAS5770LC0 device into 48 kHz sampling rate. This sequence contains a 1 ms delay required after a software or hardware reset as illustrated in 节 10.

备注

For TAS2770 the device I2C address needs to be changed. See 表 8-1.

```
w 62 00 00 # Page-0
w 62 7f 00 # Book-0
w 62 01 01 # Software Reset
d 1 # 1mS Delay
###### Configure Channel 1
w 62 3c 21 # sbclk to fs ratio = 256 / 8 TDM Slots
```

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```
w 62 0a 17 # 48KHz, Auto TDM off, Frame start High to Low
w 62 0b 03 # Offset = 1, Sync on BCLK falling edge
w 62 0c 0a # TDM slot by address, Word = 24 bit, Frame = 32 bit
w 62 0d 20 # Right Ch = TDM slot 2, Left Ch = TDM slot 0
w 62 0e 33 # TX bus keeper, Hi-Z, offset 1, TX on Falling edge
w 62 0f 42 # TDM TX voltage sense transmit enable with slot 2,
w 62 10 40 # TDM TX current sense transmit enable with slot 0
w 62 03 14 # 21 dB gain
w 62 02 00 # power up audio playback with I,V enabled
```

9.3.3 Initial Device Configuration - 44.1 kHz

The following I2C sequence is an example of initializing a TAS5770LC0 device into 48 kHz sampling rate. This sequence contains a 1 ms delay required after a software or hardware reset as illustrated in 节 10.

备注

For TAS2770 the device I2C address needs to be changed. See 表 8-1.

```
w 62 00 00 # Page-0
w 62 7f 00 # Book-0
w 62 01 01 # Software Reset
d 1 # 1mS Delay
###### Configure Channel 1
w 62 3c 21 # sbclk to fs ratio = 256 / 8 TDM Slots
w 62 0a 37 # 44.1KHz, Auto TDM off, Frame start High to Low
w 62 0b 03 # Offset = 1, Sync on BCLK falling edge
w 62 0c 0a # TDM slot by address, Word = 24 bit, Frame = 32 bit
w 62 0d 20 # Right Ch = TDM slot 2, Left Ch = TDM slot 0
w 62 0e 33 # TX bus keeper, Hi-Z, offset 1, TX on Falling edge
w 62 0f 42 # TDM TX voltage sense transmit enable with slot 2,
w 62 10 40 # TDM TX current sense transmit enable with slot 0
w 62 03 14 # 21 dB gain
w 62 02 00 # power up audio playback with I,V enabled
```

9.3.4 Sample Rate Change - 48 kHz to 44.1kHz

The following I2C sequence is an example of changing the sampling rate from 48 kHz to 44.1 kHz .

```
w 62 07 80 #Set DVC Ramp Rate to 0.5 dB / 8 samples
w 62 02 01 #Mute
d 1
w 62 02 02 #Software shutdown
w 62 0a 37 #44.1KHz, Auto TDM off, Frame start High to Low
### change source sample rate now
w 62 02 01 #Take device out of low-power shutdown
d 1
w 62 02 00 #Un-mute
```

9.3.5 Sample Rate Change - 44.1 kHz to 48 kHz

The following I2C sequence is an example of changing the sampling rate from 44.1 kHz to 48 kHz .

```
w 62 07 80 #Set DVC Ramp Rate to 0.5 dB / 8 samples
w 62 02 01 #Mute
d 1
w 62 02 02 #Software shutdown
w 62 0a 17 #44.1KHz, Auto TDM off, Frame start High to Low
### change source sample rate now
w 62 02 01 #Take device out of low-power shutdown
d 1
w 62 02 00 #Un-mute
```


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9.3.6 Device Mute

The following I2C sequence will mute one device at address 62 using a digital volume ramp rate of 0.5 dB per 8 samples.

备注

For TAS2770 the device I2C address is 82

```
w 62 07 80 #Set DVC Ramp Rate to 0.5 dB / 8 samples
w 62 02 01 #Mute
```

9.3.7 Device Un-Mute

The following I2C sequence will un-mute one device at address 62 using a digital volume ramp rate of 0.5 dB per 8 samples.

备注

For TAS2770 the device I2C address is 82

```
w 62 07 80 #Set DVC Ramp Rate to 0.5 dB / 8 samples
w 62 02 00 #Un-Mute
```

9.3.8 Device Sleep

The following I2C sequence will mute the device and put it into low power mode for one device at address 62 using a digital volume ramp rate of 0.5 dB per 8 samples.

备注

For TAS2770 the device I2C address is 82

```
w 62 07 80 #Set DVC Ramp Rate to 0.5 dB / 8 samples
w 62 02 01 #Mute
d 1 # 1mS Delay
w 62 02 02 #Software shutdown
```

9.3.9 Device Wake

The following I2C sequence will wake the device from low power mode (sleep) and un-mute one device at address 62 using a digital volume ramp rate of 0.5 dB per 8 samples.

备注

For TAS2770 the device I2C address is 82

```
w 62 07 80 #Set DVC Ramp Rate to 0.5 dB / 8 samples
w 62 02 01 #Take device out of low-power shutdown
d 1 # 1mS Delay
w 62 02 00 #Un-mute TAS2770
```

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10 Power Supply Recommendations

The power sequence between the supply rails can be applied in any order as long as SDZ pin is held low. Generally VBAT would be applied before IOVDD and AVDD in most system applications. Once all supplies are stable the SDZ pin can be set high to initialize the part. After a hardware or software reset additional commands to the device should be delayed for 1 mS to allow the OTP to load.

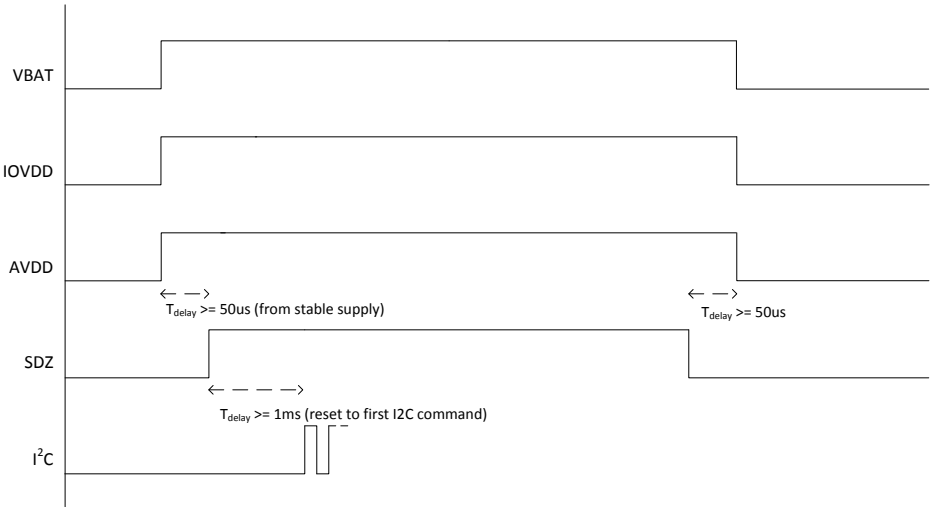


图 10-1. Power Supply Sequence for Power-Up and Power-Down

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11 Layout

11.1 Layout Guidelines

Pay special attention to the power stage power supply layout.

- Use 4.7 µf for decoupling of VBAT supply.
- Keep the current circulating loops containing the supply decoupling capacitors, the H-bridges in the device and the connections to the speakers as tight as possible to reduce emissions.
- Use ground planes to provide the lowest impedance for power and signal current between the device and the decoupling capacitors. The area directly under the device should be treated as a central ground area for the device, and all device grounds must be connected directly to that area.
- Use a via pattern to connect the area directly under the device to the ground planes in copper layers below the surface. This connection helps to dissipate heat from the device.
- Avoid interrupting the ground plane with circular traces around the device. Interruption disconnects the copper and interrupt flow of heat and current. Radial copper traces are better to use if necessary.

11.2 Layout Example

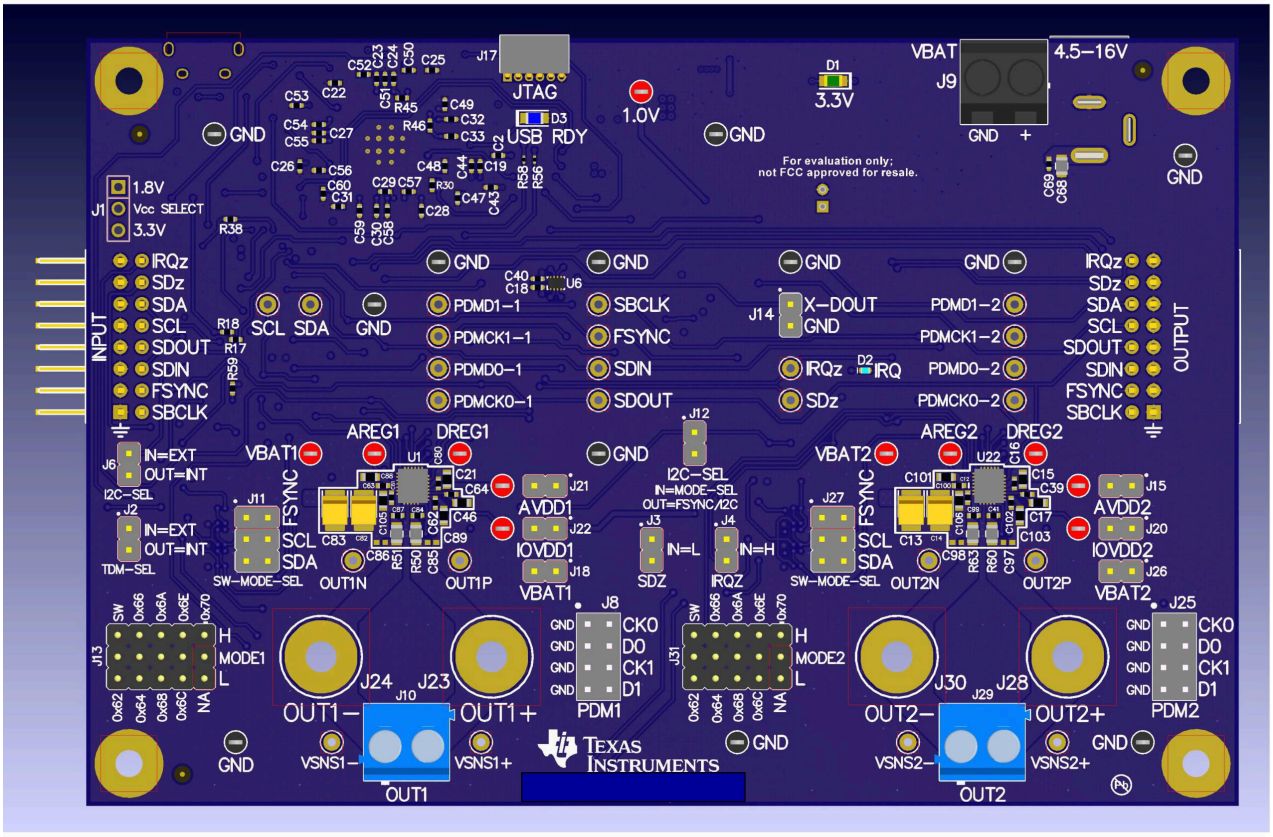


图 11-1. Stereo EVM Layout Diagram

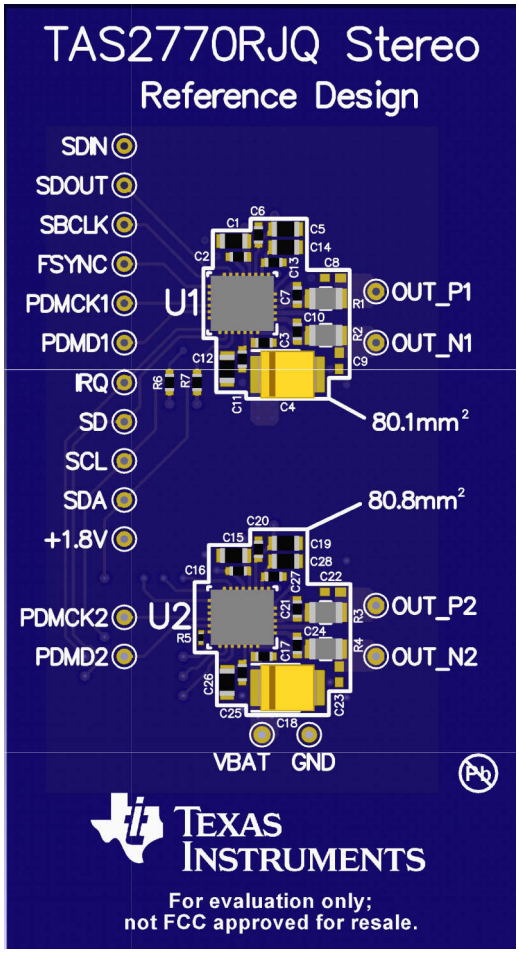


图 11-2. Stereo EVM Layout Reference Design - 01

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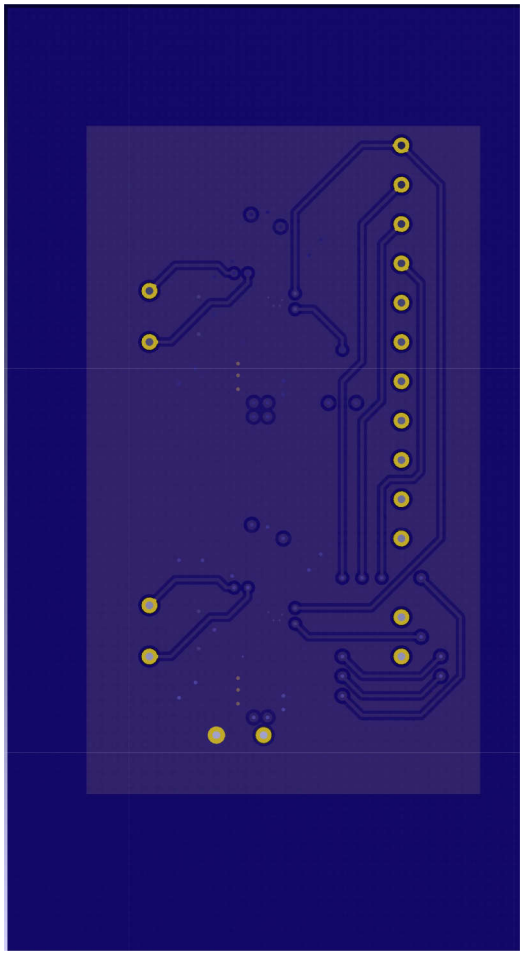


图 11-3. Stereo EVM Layout Reference Design - 02

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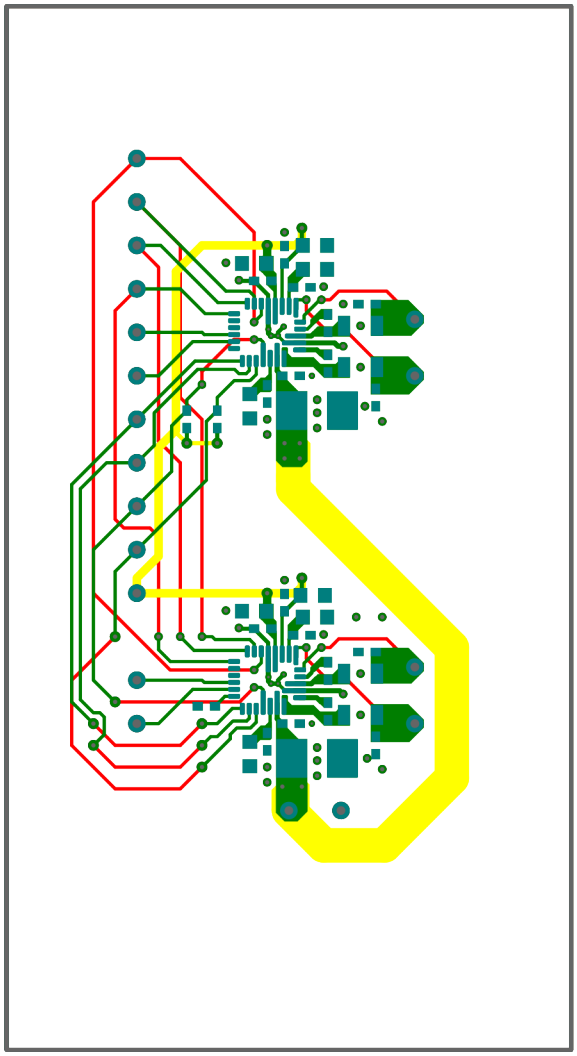


图 11-4. Layout Reference – TAS2770RJQ

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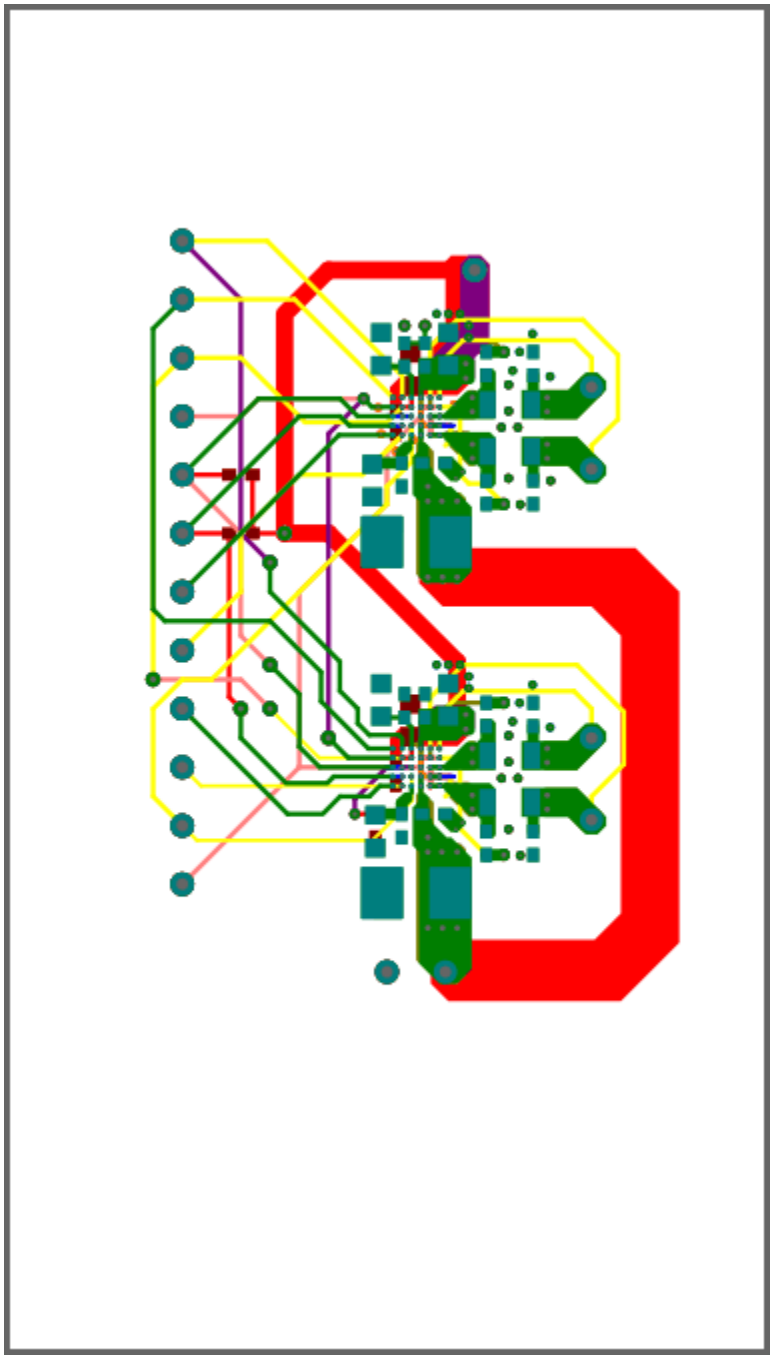


图 11-5. Layout Reference – TAS2770YFF

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12 Device and Documentation Support

12.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

12.2 Community Resources

12.3 Trademarks

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13 Mechanical, Packaging, and Orderable Information

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PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TAS2770RJQR	Active	Production	VQFN-HR (RJQ) | 26	3000 | LARGE T&R	Yes	Call TI | Sn	Level-2-260C-1 YEAR	-40 to 85	2770
TAS2770RJQR.A	Active	Production	VQFN-HR (RJQ) | 26	3000 | LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 85	2770
TAS2770RJQRG4	Active	Production	VQFN-HR (RJQ) | 26	3000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	2770
TAS2770RJQRG4.A	Active	Production	VQFN-HR (RJQ) | 26	3000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	2770
TAS2770RJQT	Active	Production	VQFN-HR (RJQ) | 26	250 | SMALL T&R	Yes	Call TI | Sn	Level-2-260C-1 YEAR	-40 to 85	2770
TAS2770RJQT.A	Active	Production	VQFN-HR (RJQ) | 26	250 | SMALL T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 85	2770
TAS2770YFFR	Active	Production	DSBGA (YFF) | 30	3000 | LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 85	2770
TAS2770YFFR.A	Active	Production	DSBGA (YFF) | 30	3000 | LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 85	2770
TAS2770YFFT	Active	Production	DSBGA (YFF) | 30	250 | SMALL T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 85	2770
TAS2770YFFT.A	Active	Production	DSBGA (YFF) | 30	250 | SMALL T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 85	2770
TAS5770LC0YFFR	Active	Production	DSBGA (YFF) | 30	3000 | LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 85	TAS5770LC0
TAS5770LC0YFFR.A	Active	Production	DSBGA (YFF) | 30	3000 | LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 85	TAS5770LC0

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

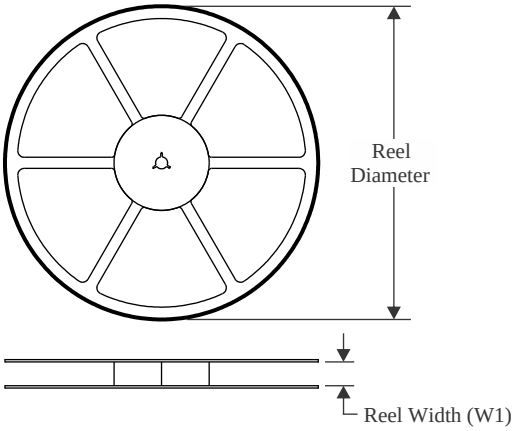
Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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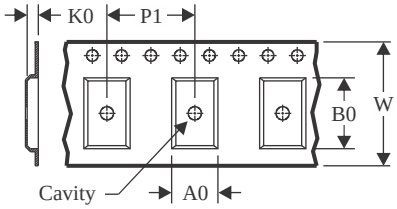
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TAPE AND REEL INFORMATION

REEL DIMENSIONS

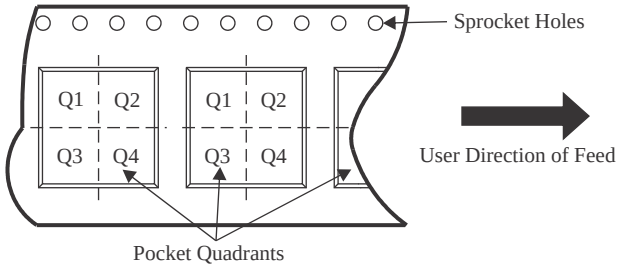


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

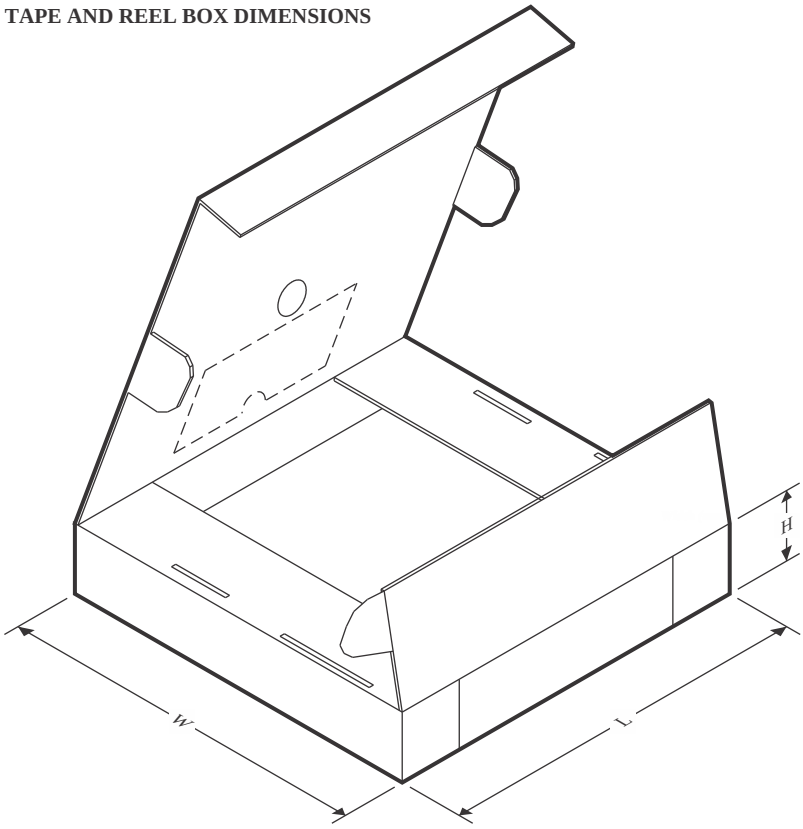
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TAS2770RJQT	VQFN-HR	RJQ	26	250	180.0	12.4	3.8	4.3	1.5	8.0	12.0	Q2
TAS2770YFFR	DSBGA	YFF	30	3000	180.0	8.4	2.13	2.66	0.69	4.0	8.0	Q1
TAS2770YFFT	DSBGA	YFF	30	250	180.0	8.4	2.13	2.66	0.69	4.0	8.0	Q1
TAS5770LC0YFFR	DSBGA	YFF	30	3000	180.0	8.4	2.13	2.66	0.69	4.0	8.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

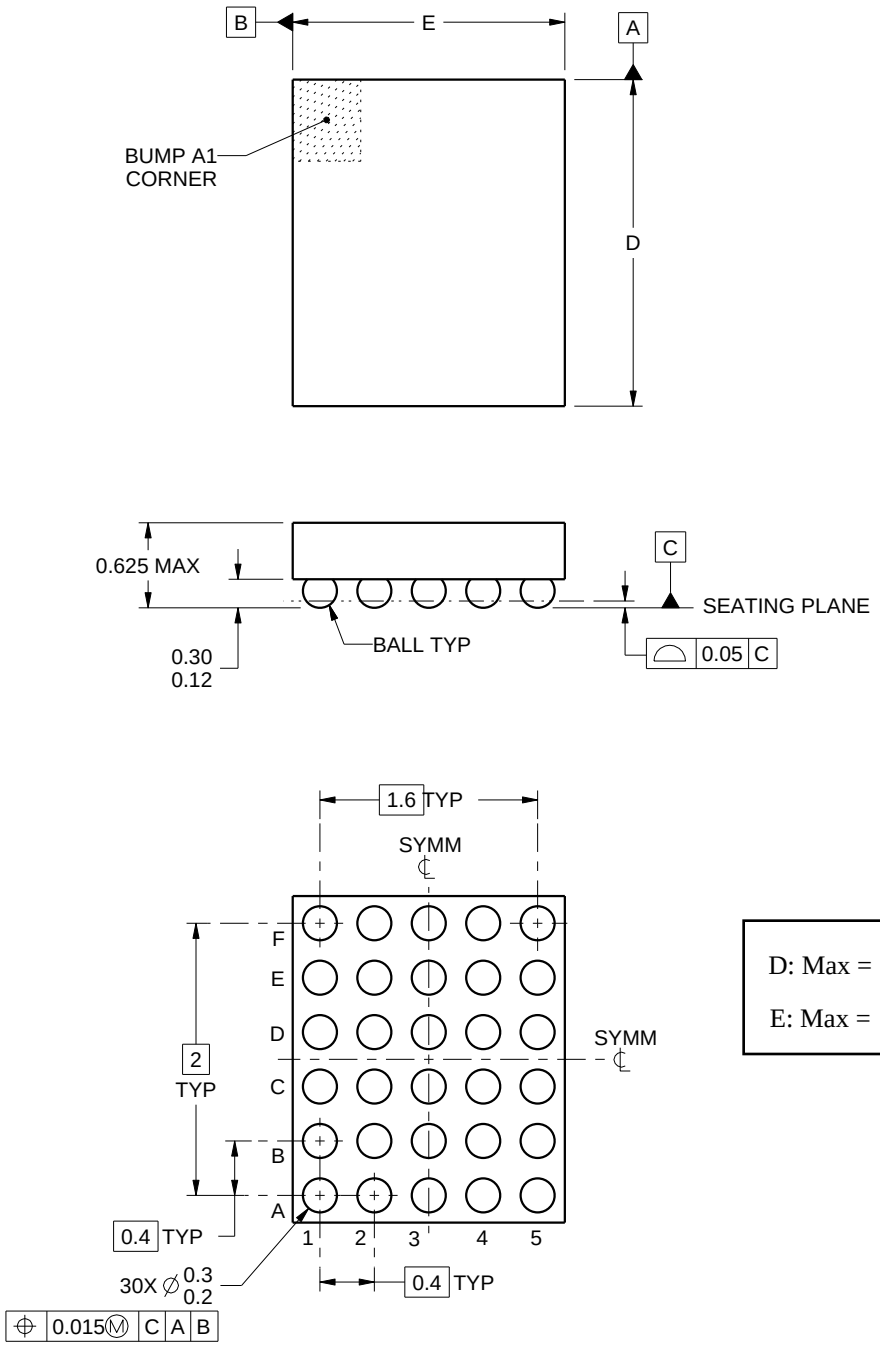
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TAS2770RJQT	VQFN-HR	RJQ	26	250	341.0	185.0	80.0
TAS2770YFFR	DSBGA	YFF	30	3000	182.0	182.0	20.0
TAS2770YFFT	DSBGA	YFF	30	250	182.0	182.0	20.0
TAS5770LC0YFFR	DSBGA	YFF	30	3000	182.0	182.0	20.0

PACKAGE OUTLINE

YFF0030

DSBGA - 0.625 mm max height

DIE SIZE BALL GRID ARRAY



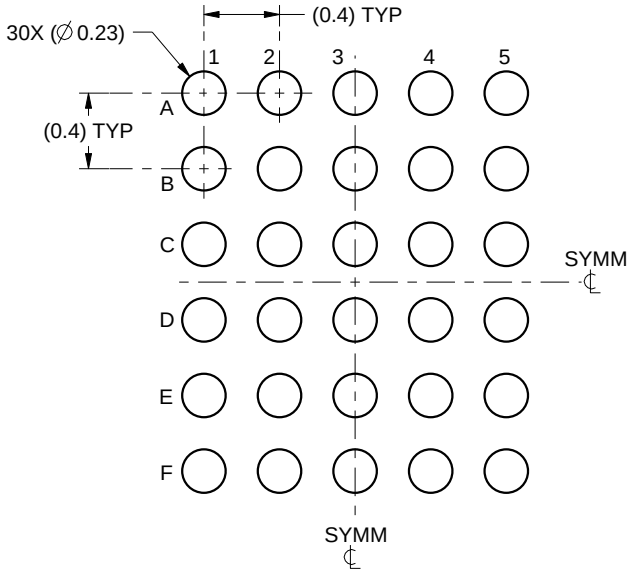
D: Max = 2.549 mm, Min =2.489 mm

E: Max = 2.038 mm, Min =1.977 mm

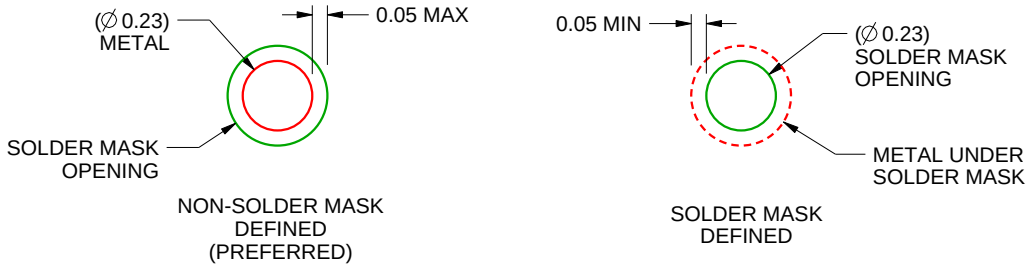
4219433/A 03/2016

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.



LAND PATTERN EXAMPLE
SCALE:25X

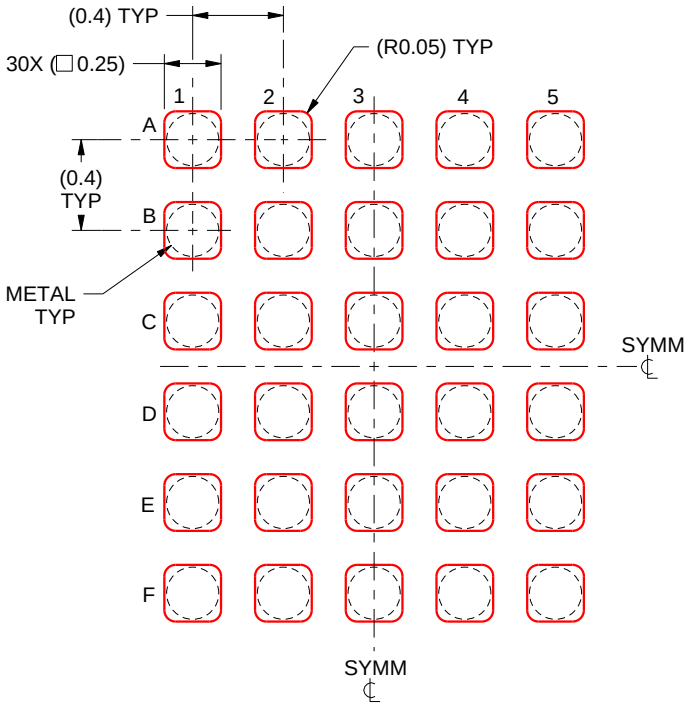


SOLDER MASK DETAILS
NOT TO SCALE

4219433/A 03/2016

NOTES: (continued)

3. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints.
For more information, see Texas Instruments literature number SNVA009 (www.ti.com/lit/snva009).



SOLDER PASTE EXAMPLE
BASED ON 0.1 mm THICK STENCIL
SCALE:30X

4219433/A 03/2016

NOTES: (continued)

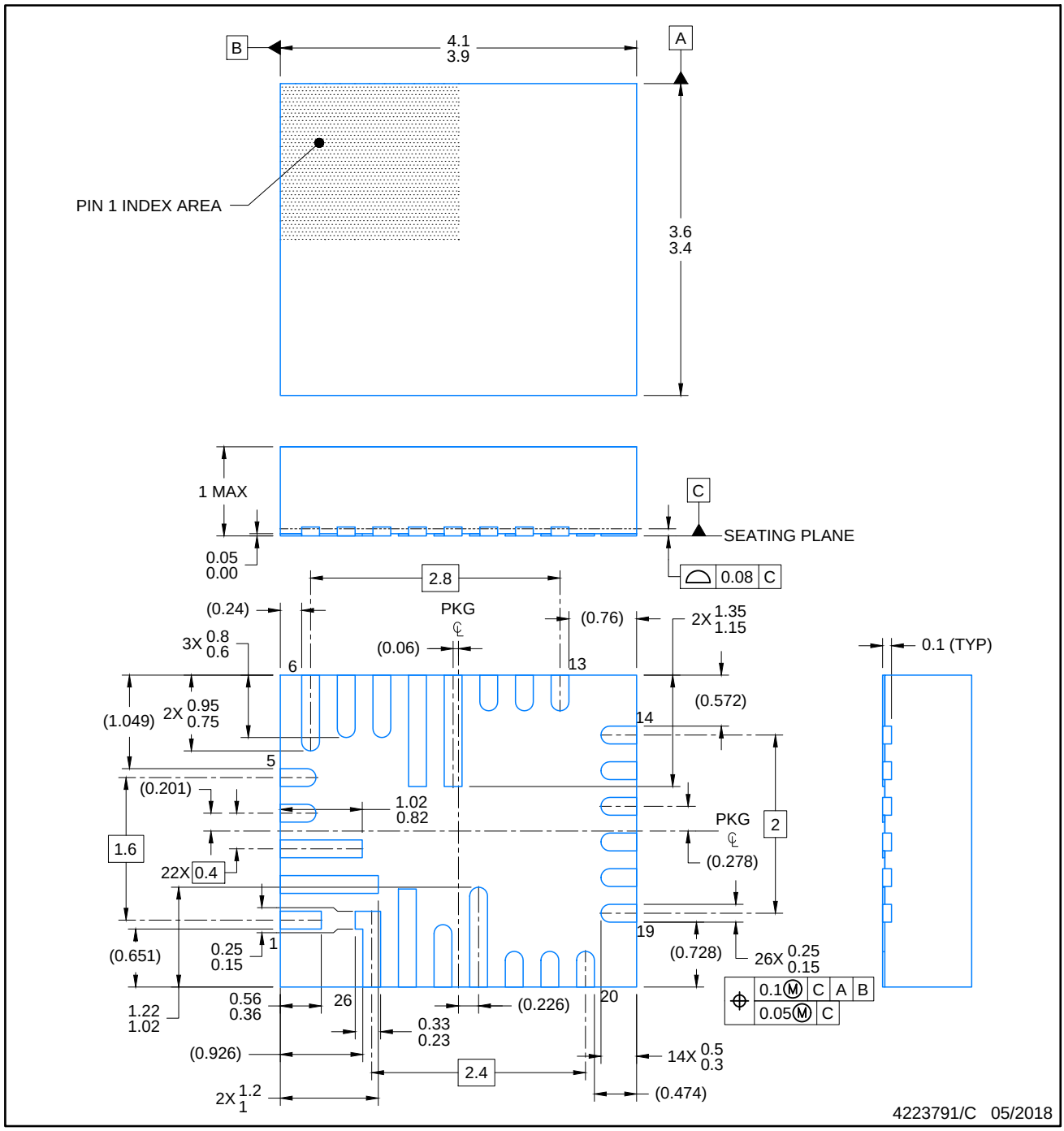
4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.

PACKAGE OUTLINE

RJQ0026A

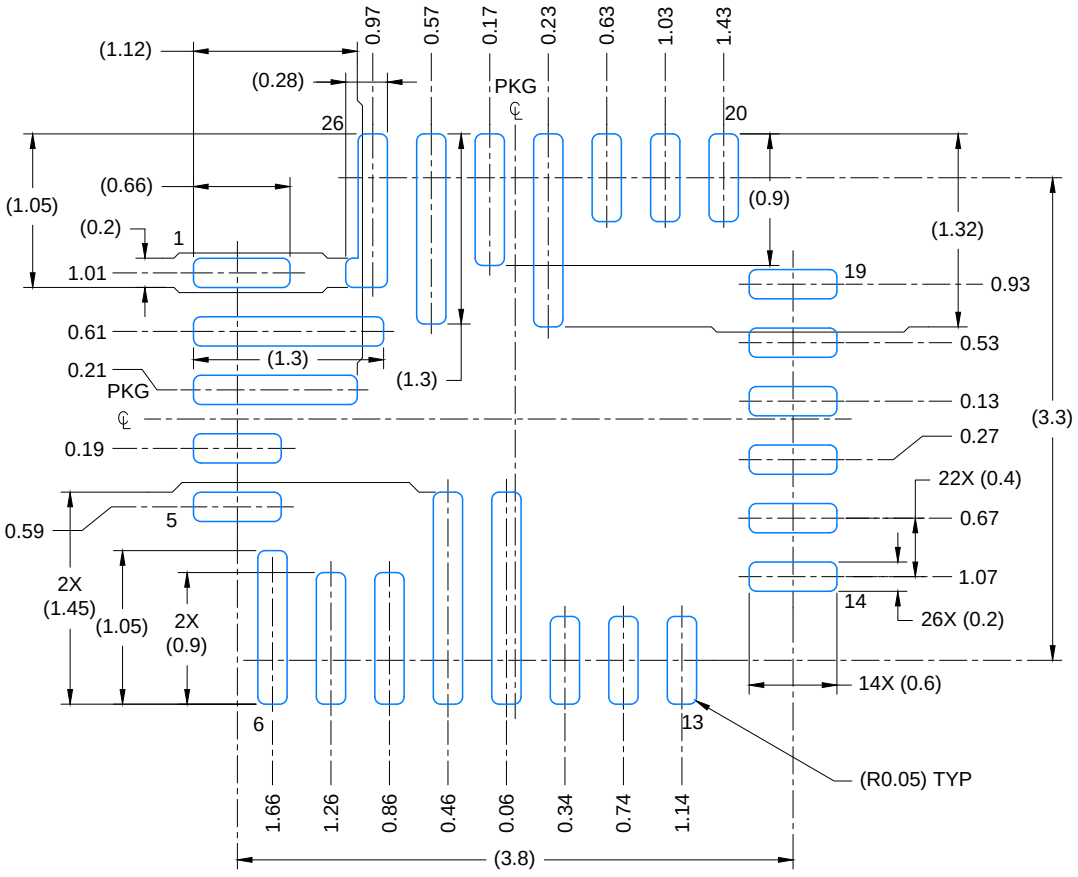
VQFN-HR - 1 mm max height

PLASTIC QUAD FLATPACK- NO LEAD

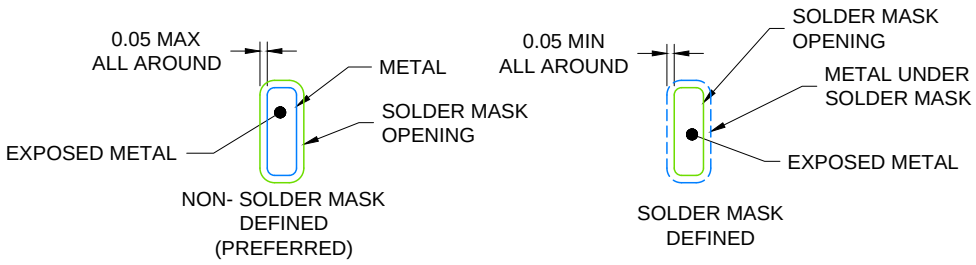


NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 20X

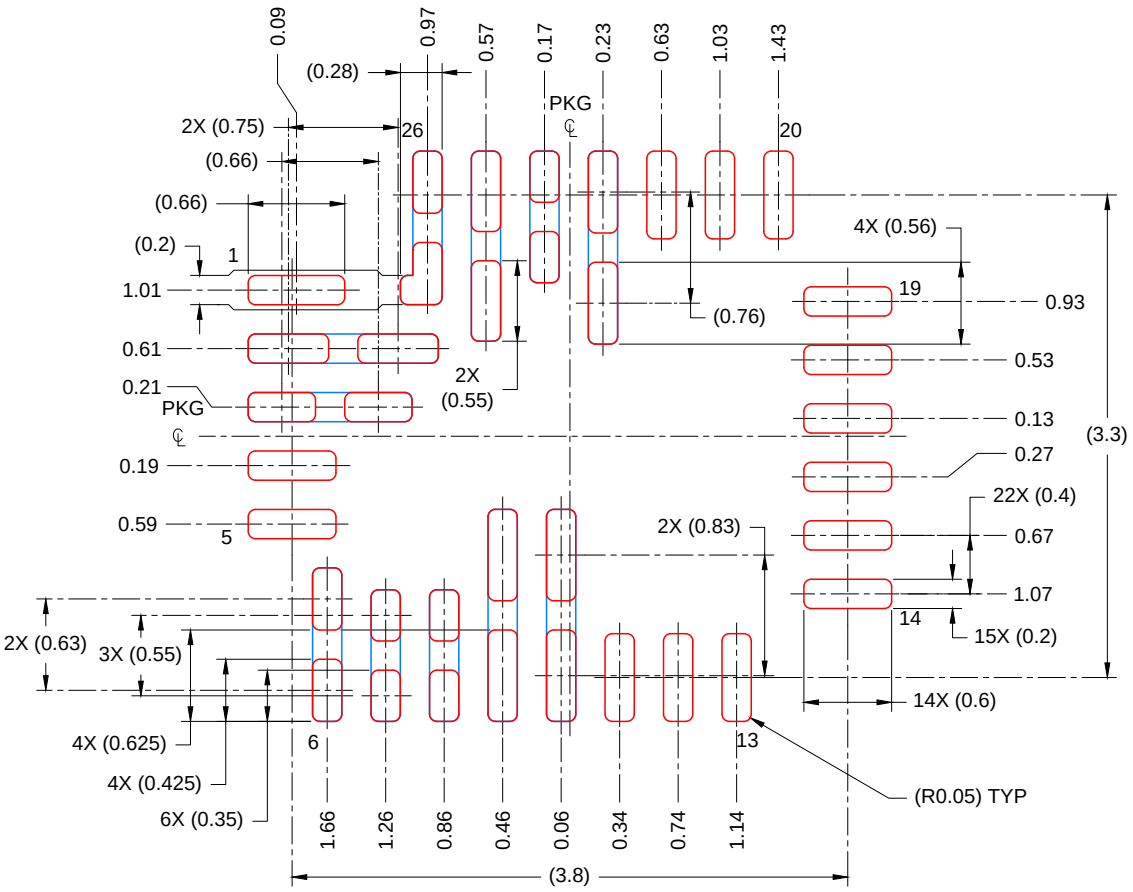


SOLDER MASK DETAILS

4223791/C 05/2018

NOTES: (continued)

3. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271) .
4. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOLDER PASTE EXAMPLE
BASED ON 0.1mm THICK STENCIL

EXPOSED PAD
84% PRINTED COVERAGE BY AREA
SCALE: 20X

4223791/C 05/2018

NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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最后更新日期：2025 年 10 月